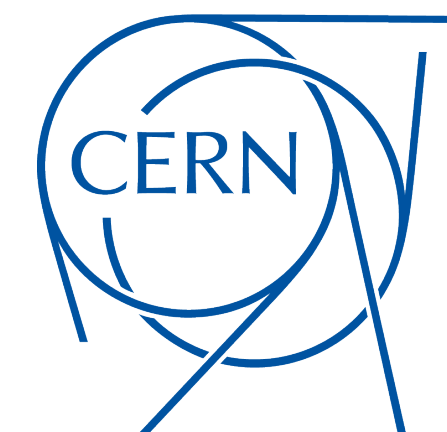


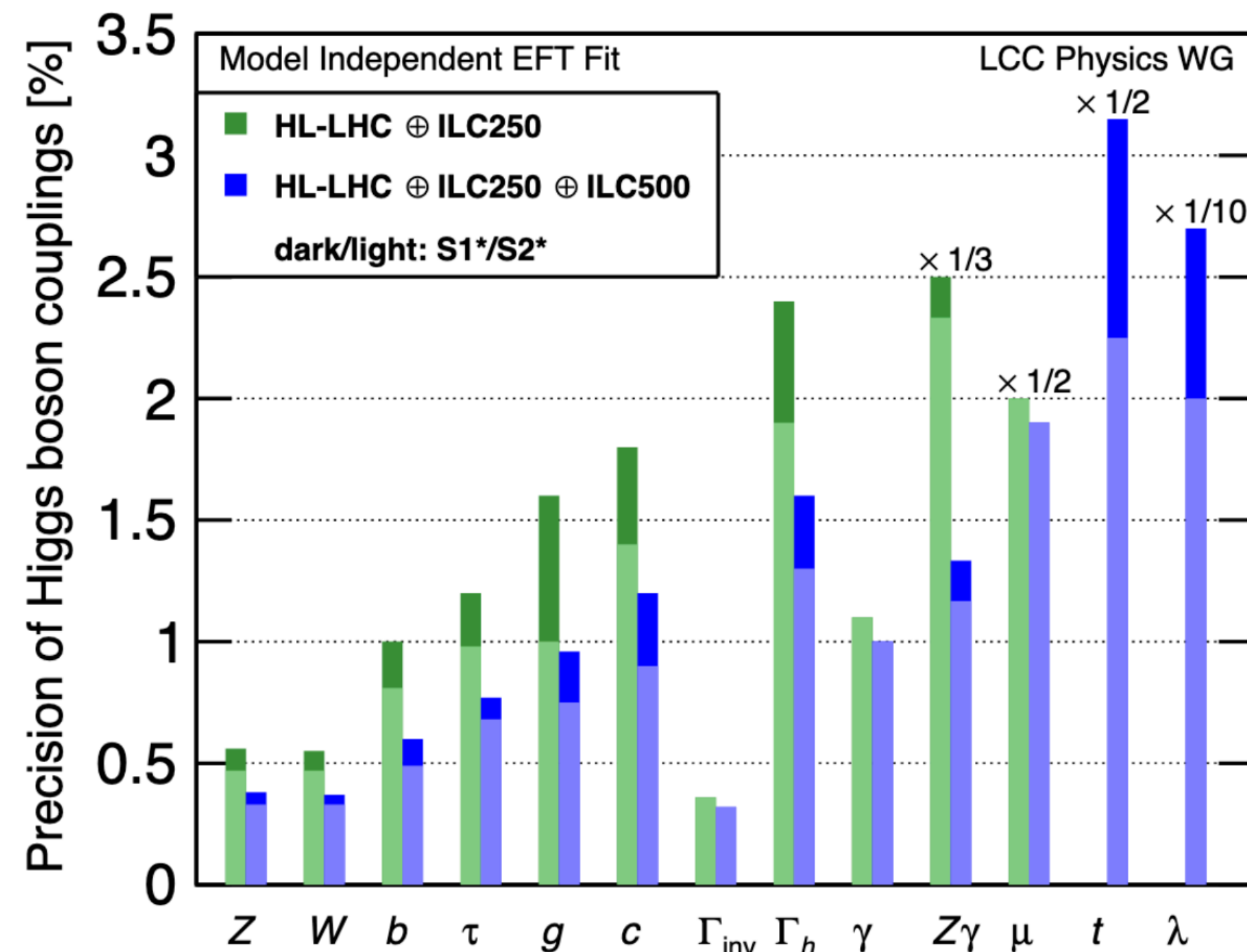
# Recent results with radiation-tolerant TowerJazz 180 nm MALTA Sensors

Vienna Conference of Instrumentation 2022

Philip Allport (UOB), Ignacio Asensi Tortajada (CERN), Marlon Barbero (CPPM), Pierre Barrillon (CPPM), Dumitru-Vlad Berlea (DESY), Christian Bospin (Bonn), Daniela Bortoletto (Oxford), Patrick Breugnon (CPPM), Edoardo Charbon (EPFL), Florian Dacks (CERN), Valerio Dao (CERN), Yavuz Degerli (CEA), Jochen Christian Dingfelder (Bonn), Dominik Dobrijevic (CERN, Zagreb), Leyre Flores Sanz de Acedo (CERN), Andrea Gabrielli (CERN), Giuliano Gustavino (CERN), Amr Habib (CPPM), Tomas Hemperek (CPPM), **Matt LeBlanc (CERN)**, Magdalena Munker (CERN), Patrick Pangaud (CPPM), Heinz Pernegger (CERN), Francesco Piro (EPFL, CERN), Petra Riedler (CERN), Heidi Sandaker (Oslo), Abhishek Sharma (CERN), Water Snoeys (CERN), Tomislav Suligoj (Zagreb), Milou van Rijnbach (CERN, Oslo), Tianyang Wang (Bonn), Julian Weick (CERN, Darmstadt), Norbert Wermes (Bonn), Steven Worm (DESY), Abdelhak Zoubir (Darmstadt)

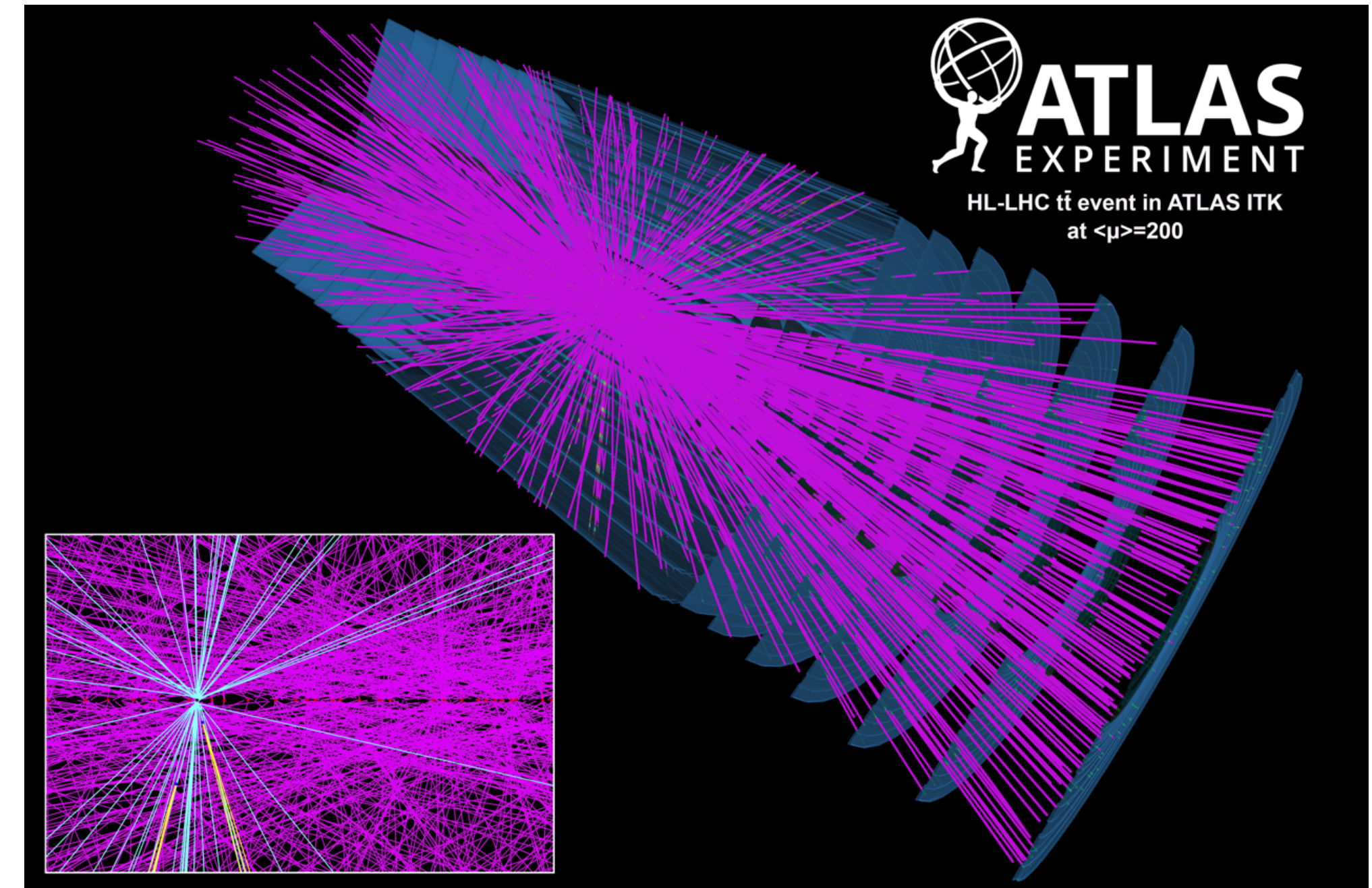


# FUTURE PHYSICS GOALS AND EXPERIMENTAL CONDITIONS WILL CHALLENGE US!



**Goal: measure major Higgs couplings with ~1% precision!**

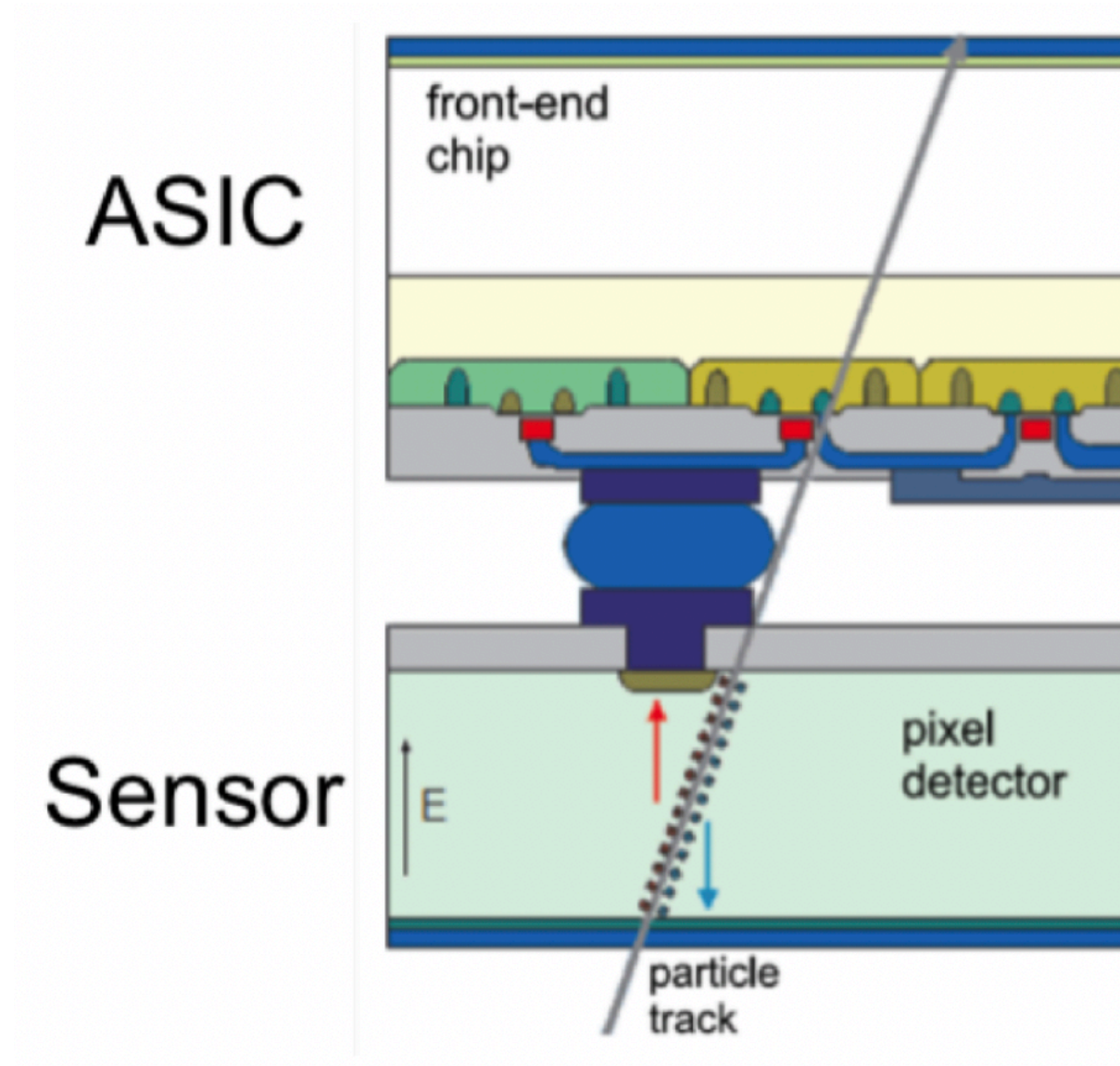
*b vs. c discrimination, high luminosities, ...*



- High radiation doses,
- Low material budget (reduced services / cooling)
- Fast readout
- Large surface area (13 m<sup>2</sup>, 7x current)
- High granularity (200 MHz/cm<sup>2</sup> hit rate)
- Affordability?

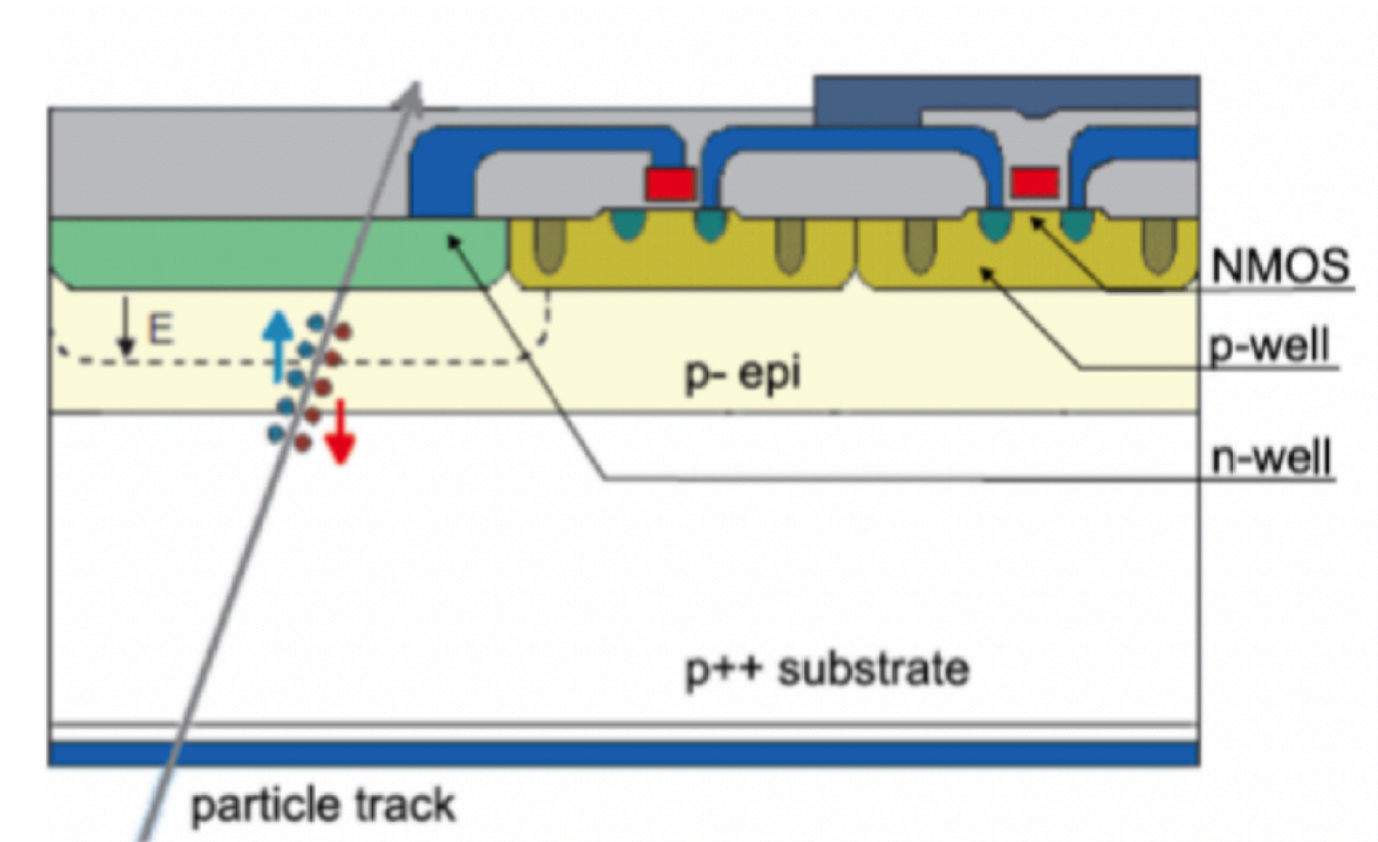
# MAPS

- Monolithic Active Pixel Sensors (MAPS) present an attractive solution to many experimental challenges.
  - Integration of readout electronics and sensor in a single silicon die eliminates expensive bump-bonding step.
  - Small sensor capacitance ( $< \text{fF}$ )
    - reduced power consumption
    - reduced services
- Radiation tolerances unproven, **ATLAS ITk outer layer taken as benchmark:**
  - $1\text{E}+15$   $1 \text{ MeV } n_{\text{eq}}/\text{cm}^2$  Non-Ionising Energy Loss (NIEL)
  - $\sim 100$  Mrad Total Ionizing Dose (TID)
- LHC bunch-crossing rate requires **timing response  $< 25 \text{ ns}$ .**
  - Smaller window for future colliders.



## Hybrid sensors

- Current state-of-the-art.
- Expensive bump-bonding.
- Well-understood radiation tolerance



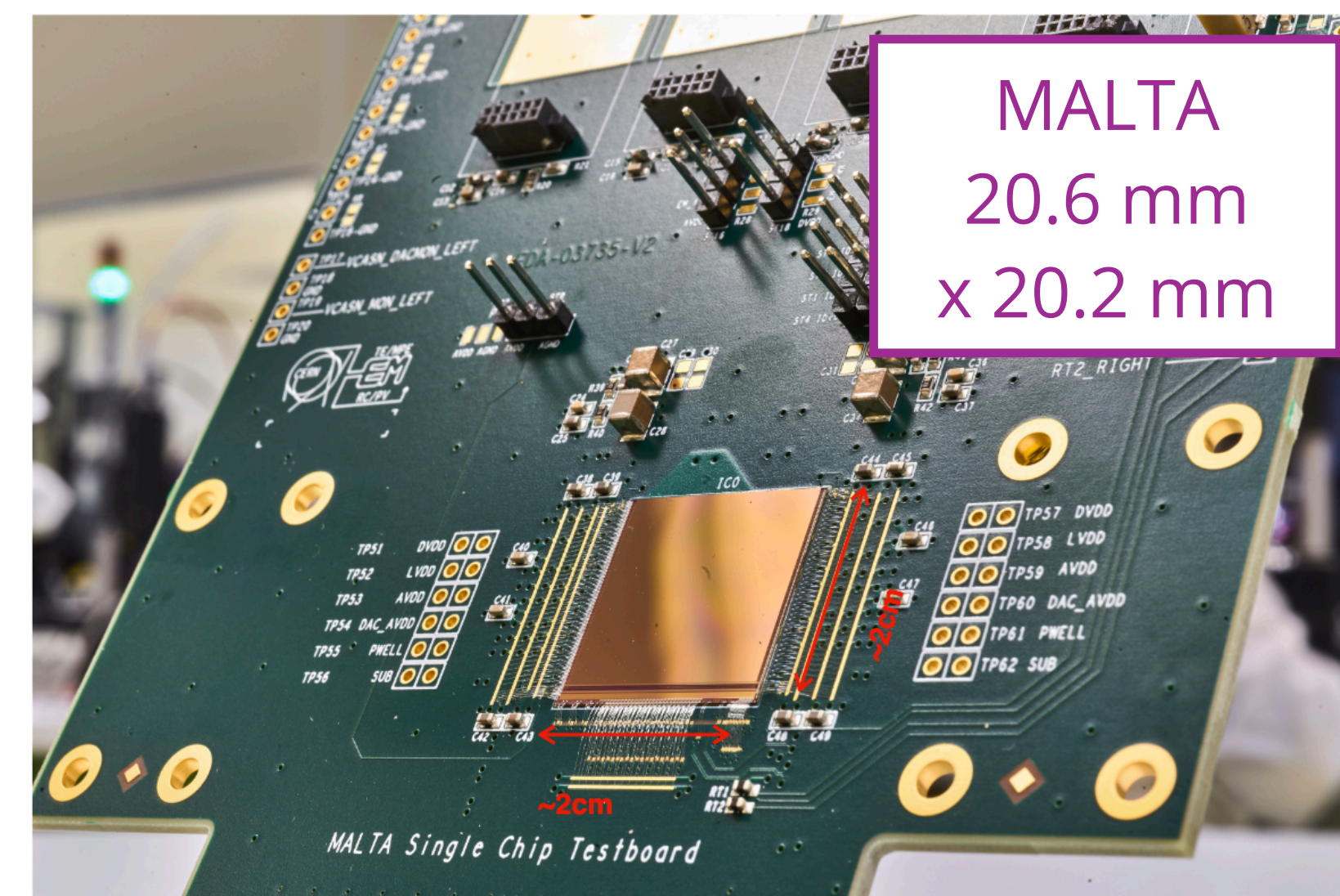
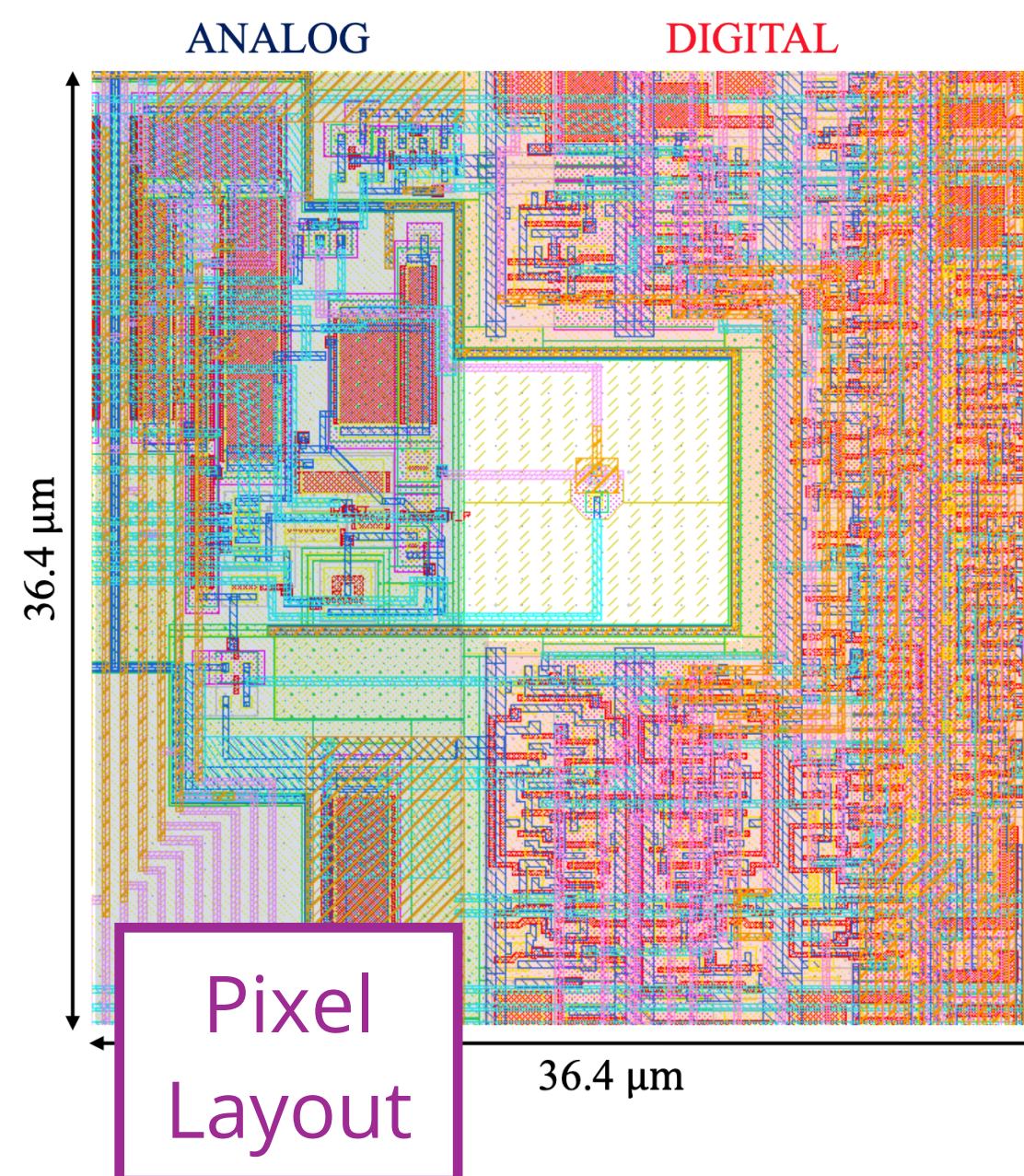
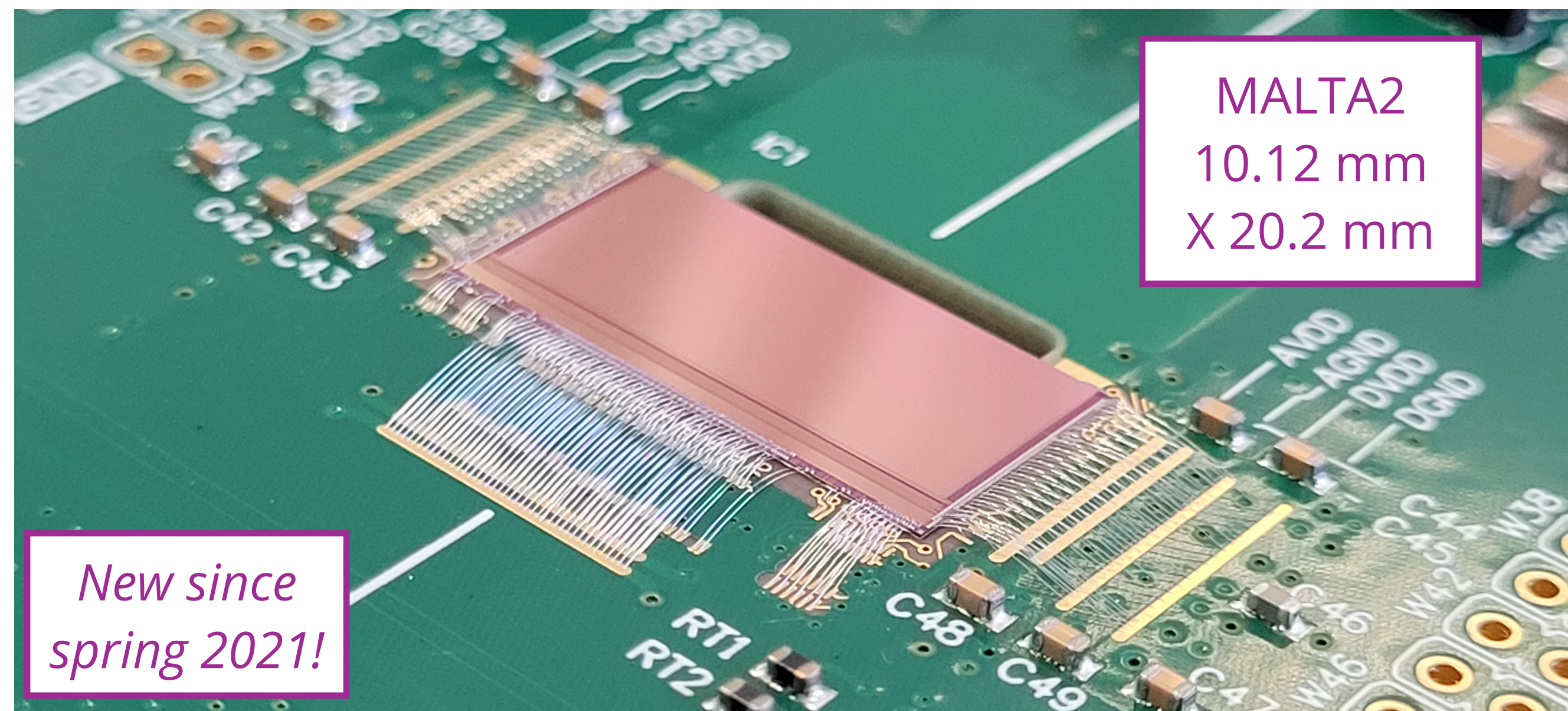
## ASIC+Sensor

## Monolithic Sensors

- Commercial process, no flip-chip bonding
- Lower power needs, less material.
- Radiation tolerance still needs to be proven.

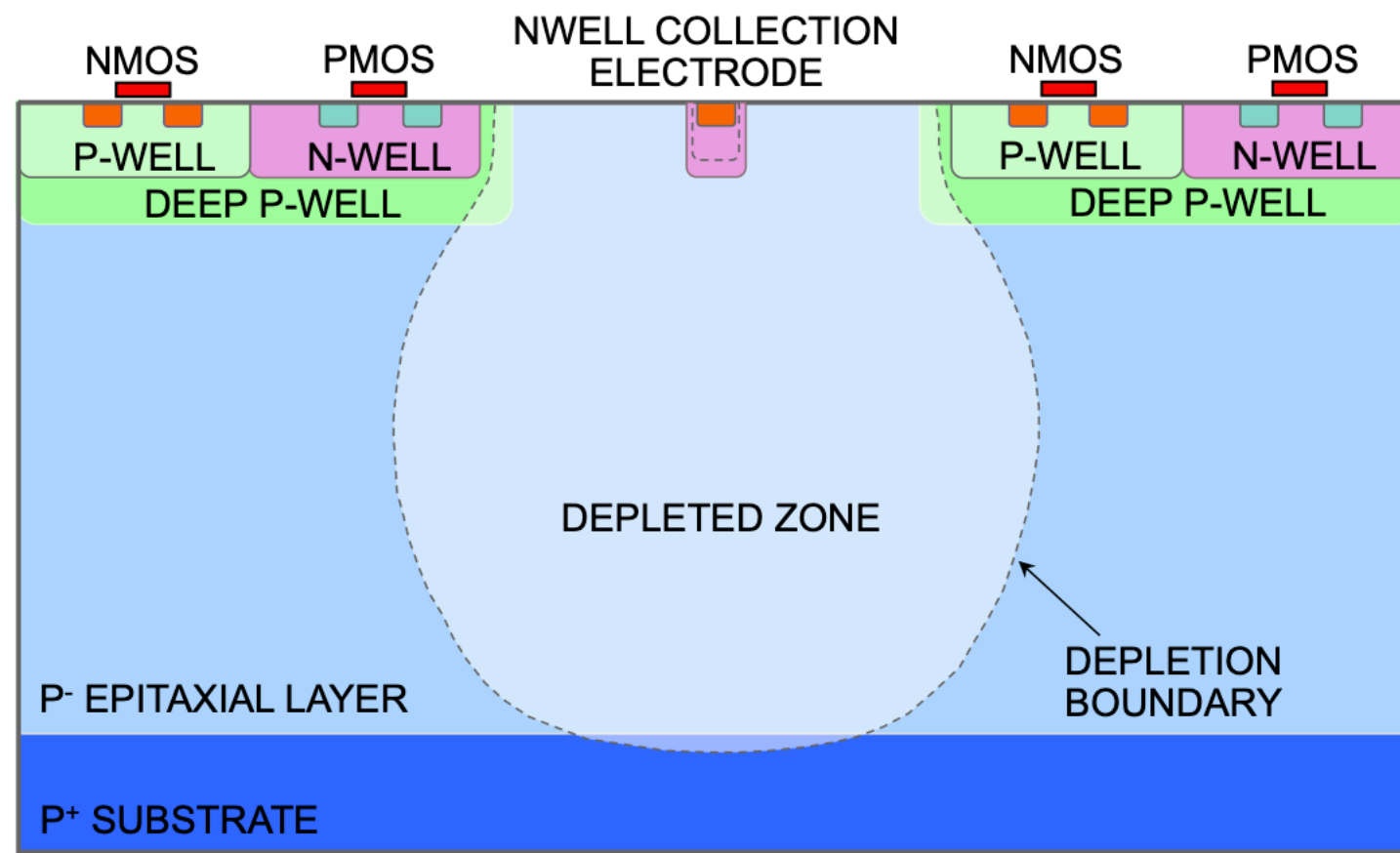
# MALTA & MALTA2

- Full-scale demonstrators produced to target specifications for ATLAS ITk outer layer.
  - Pixel pitch  $36.4\ \mu\text{m} \times 36.4\ \mu\text{m}$ .
  - Small collection electrodes:  **$3\ \mu\text{m}$** , minimal capacitance.
  - Power requirements:  **$1\ \mu\text{W}/\text{pixel}$**  ( $<70\ \text{mW}/\text{cm}^2$ ).
    - No propagation of clock to matrix.
  - Fast, asynchronous read-out.
    - No time-over-threshold info, parallel output signal transmission.
- MALTA2 includes larger transistors, additional cascoded transistor to improve speed of front-end w.r.t. MALTA.
  - **Many different chip flavours** (substrate, process modification, thickness, doping concentrations, etc.)
- Extensive characterization campaign consisting of **lab and testbeam** measurements.
  - **Today, we'll be showing new results demonstrating the radiation tolerance of MALTA2's front-end (TID), and its timing performance.**



# Towerjazz 180 nm Modified Processes

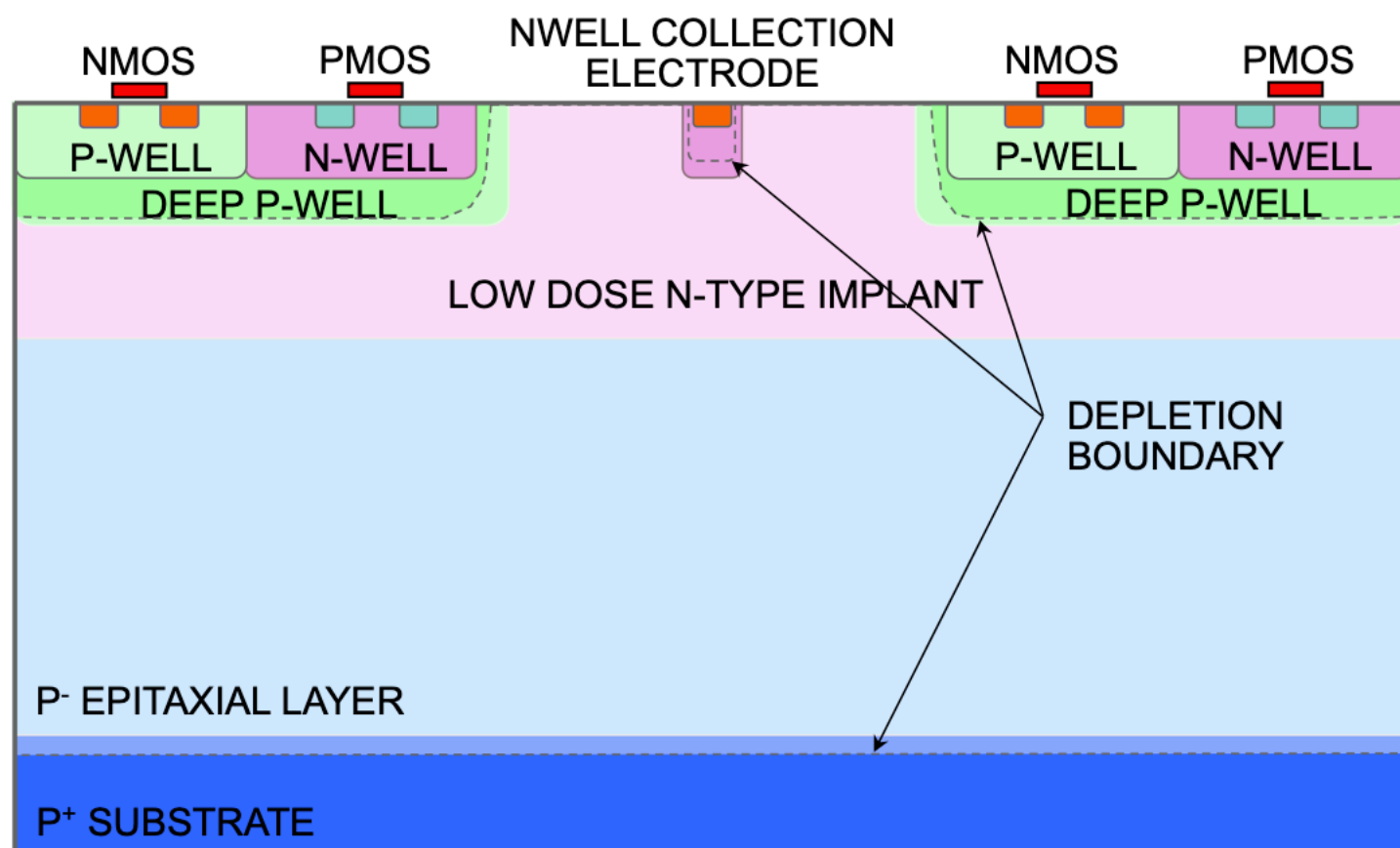
Charge collection time  
~100 ns via diffusion,  
too slow for LHC applications.



Unmodified process

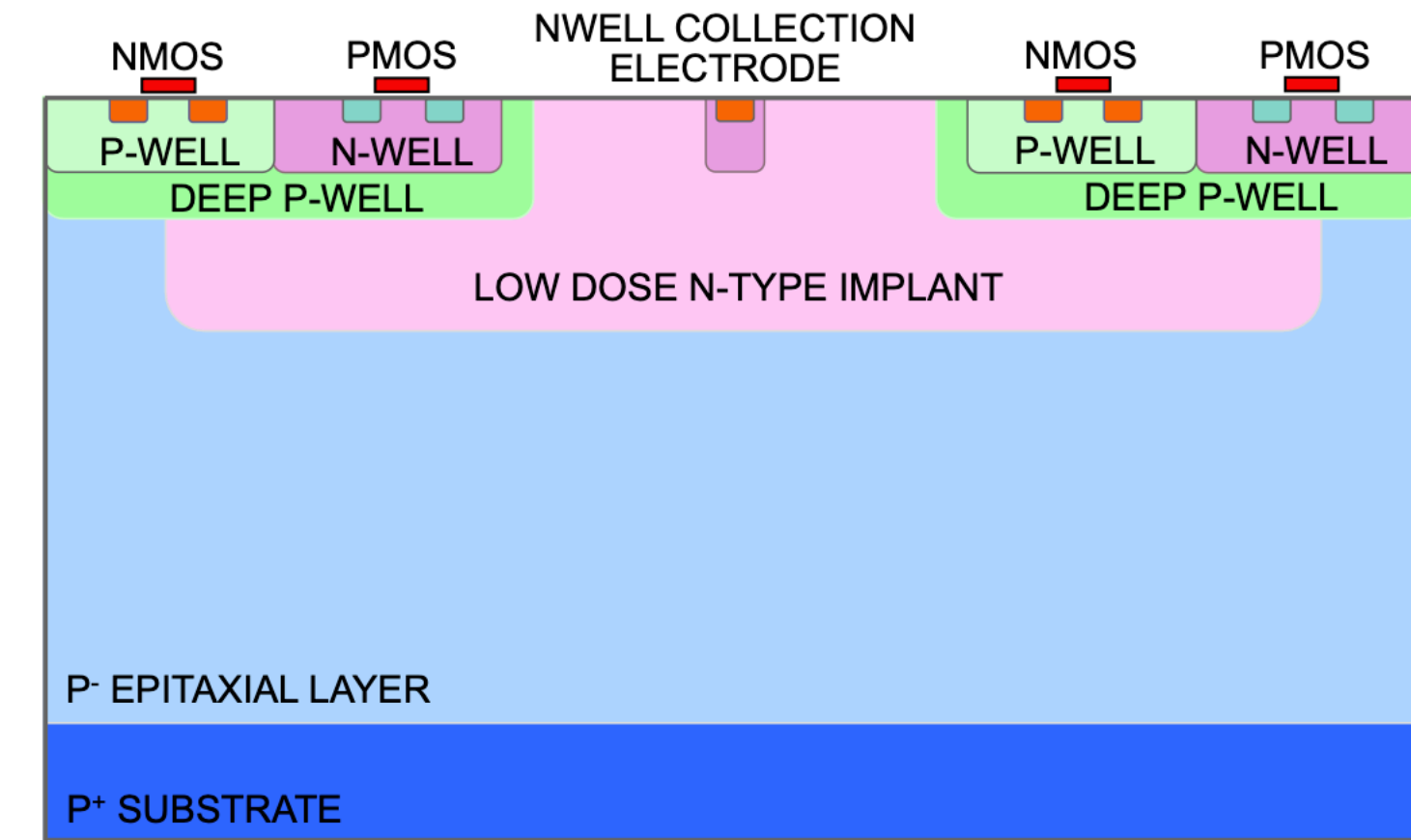
Uniform low-dose n—type  
implant under p-well fully  
depletes pixel area, pushing  
charge-carriers towards  
collection electrode.

Also reduces charge carrier  
capture probability, improving  
sensor tolerance to NIEL.

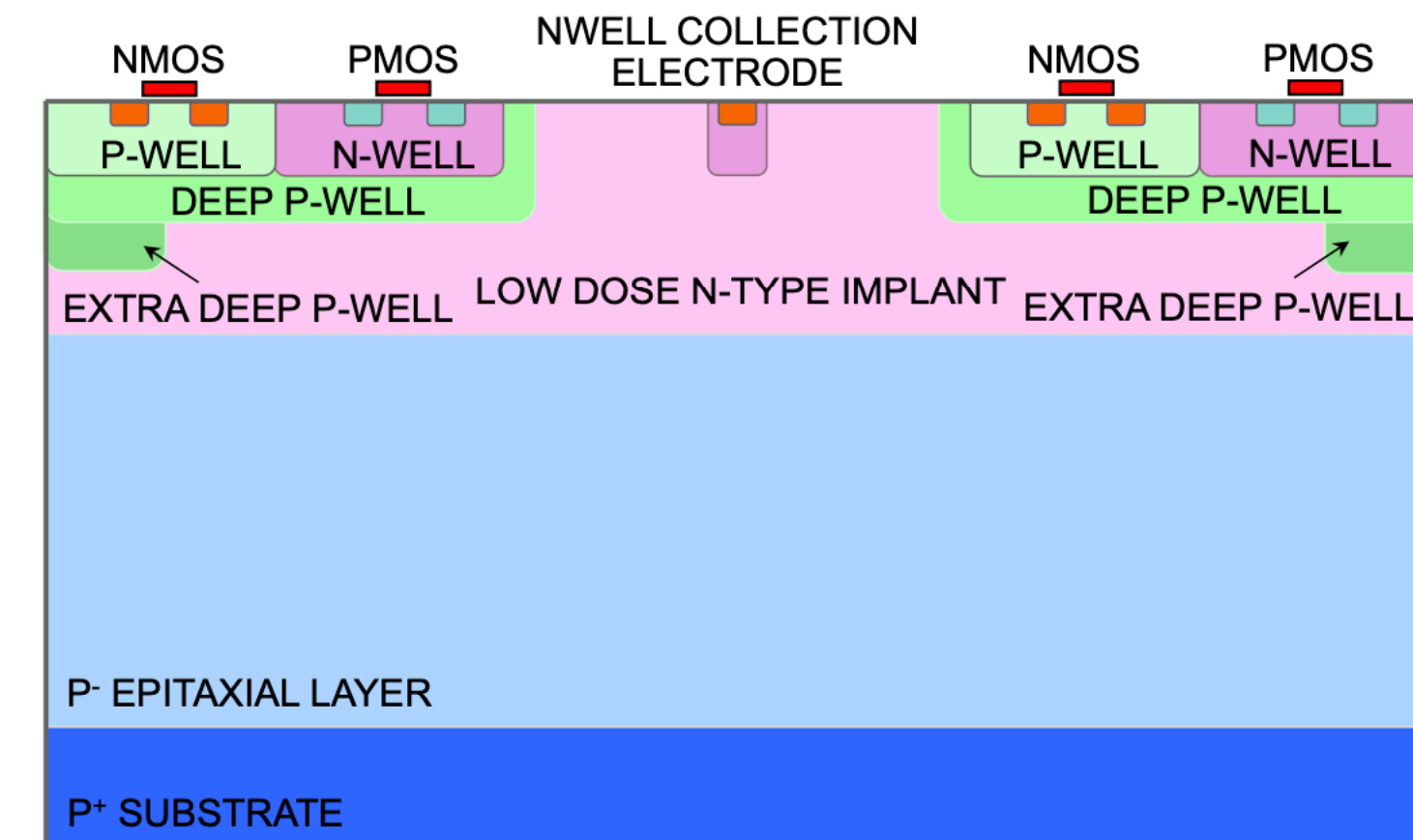


Modified process, low doping

Additional process  
modifications can increase  
E-field in pixel corners,  
further reducing charge  
collection tails.

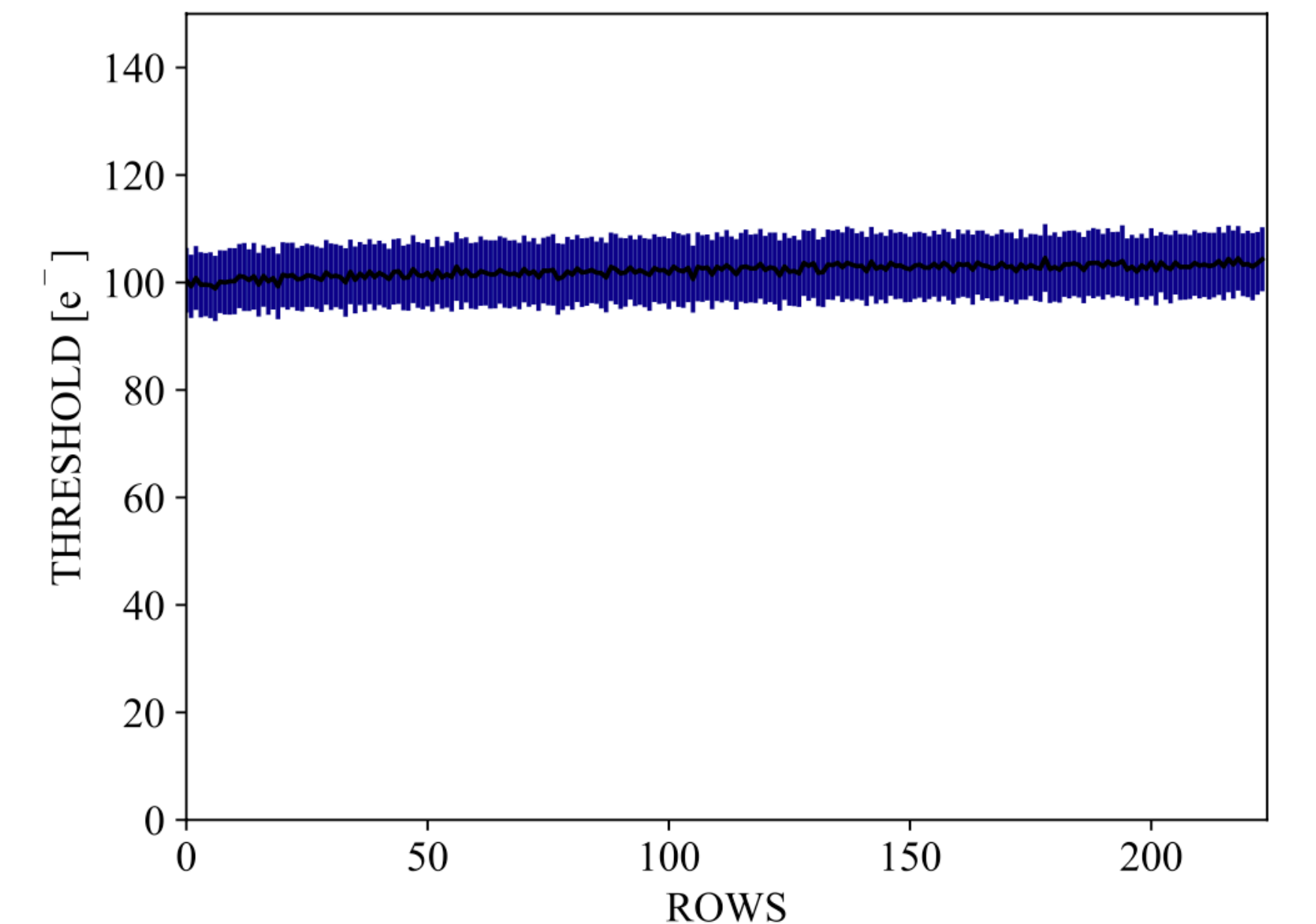
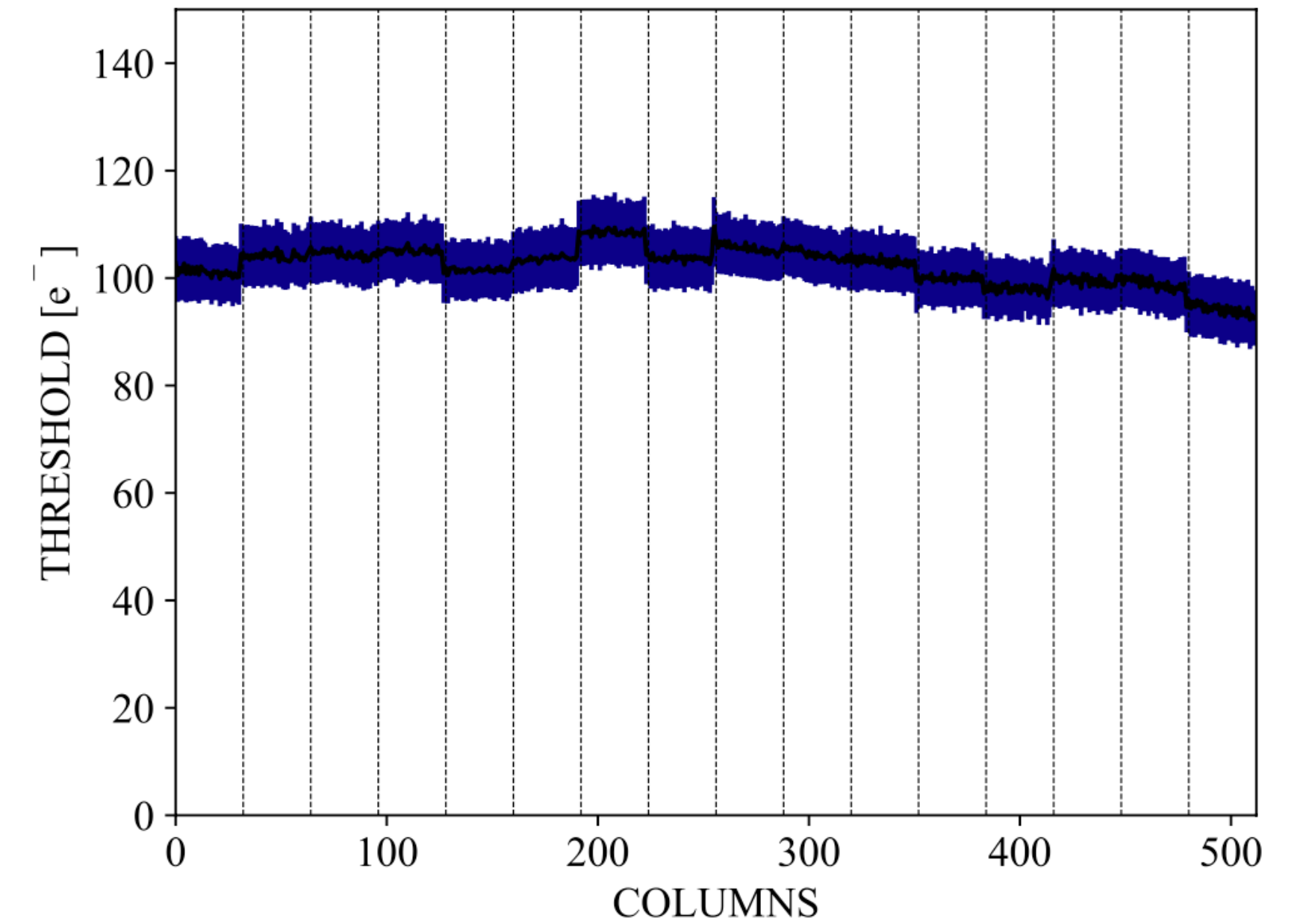
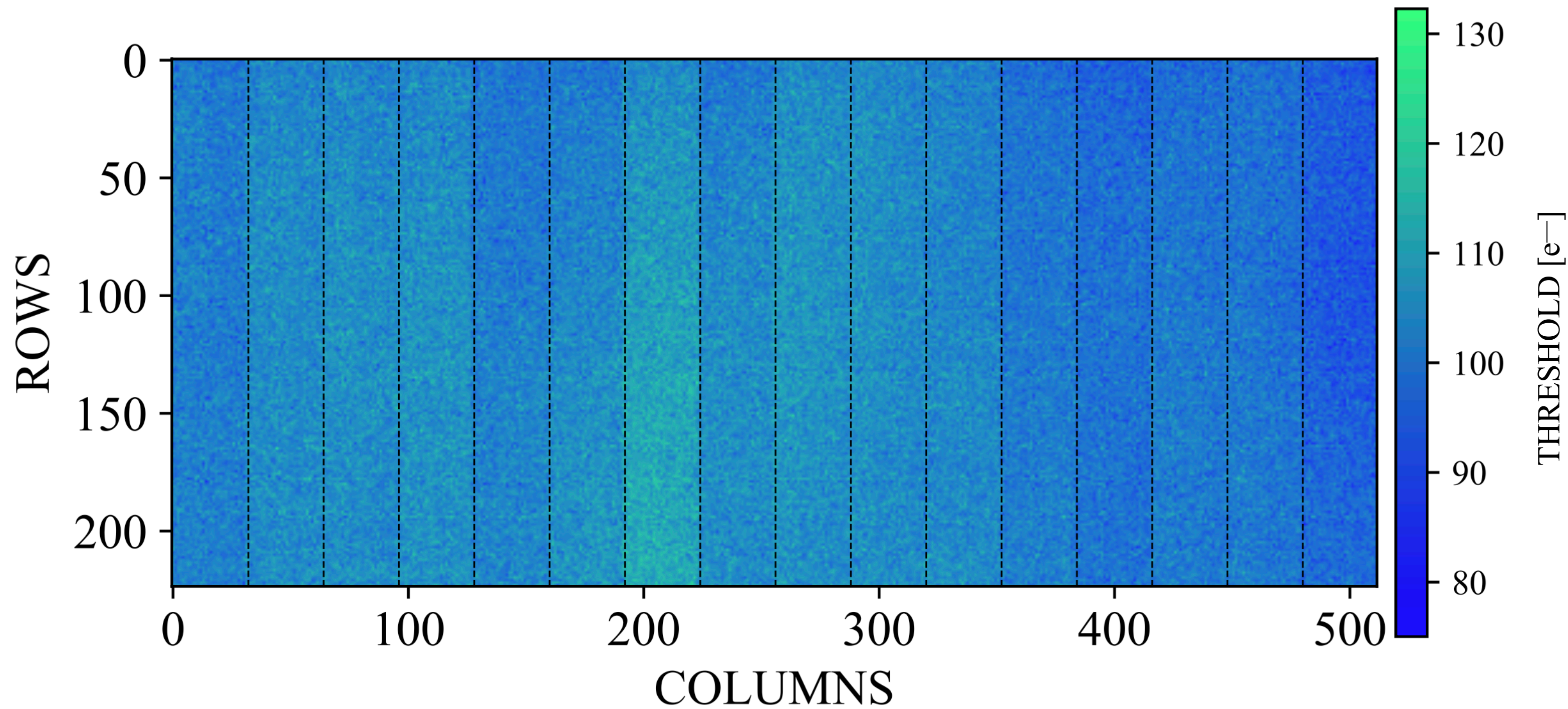


"Gap in the n-layer"



"Extra-deep p-well"

# MALTA2 front-end



Threshold scan performed for entire MALTA2 matrix with nominal front-end settings.

Average threshold is  $\sim 100 e^-$ , with  $\sim 6 e^-$  variation.

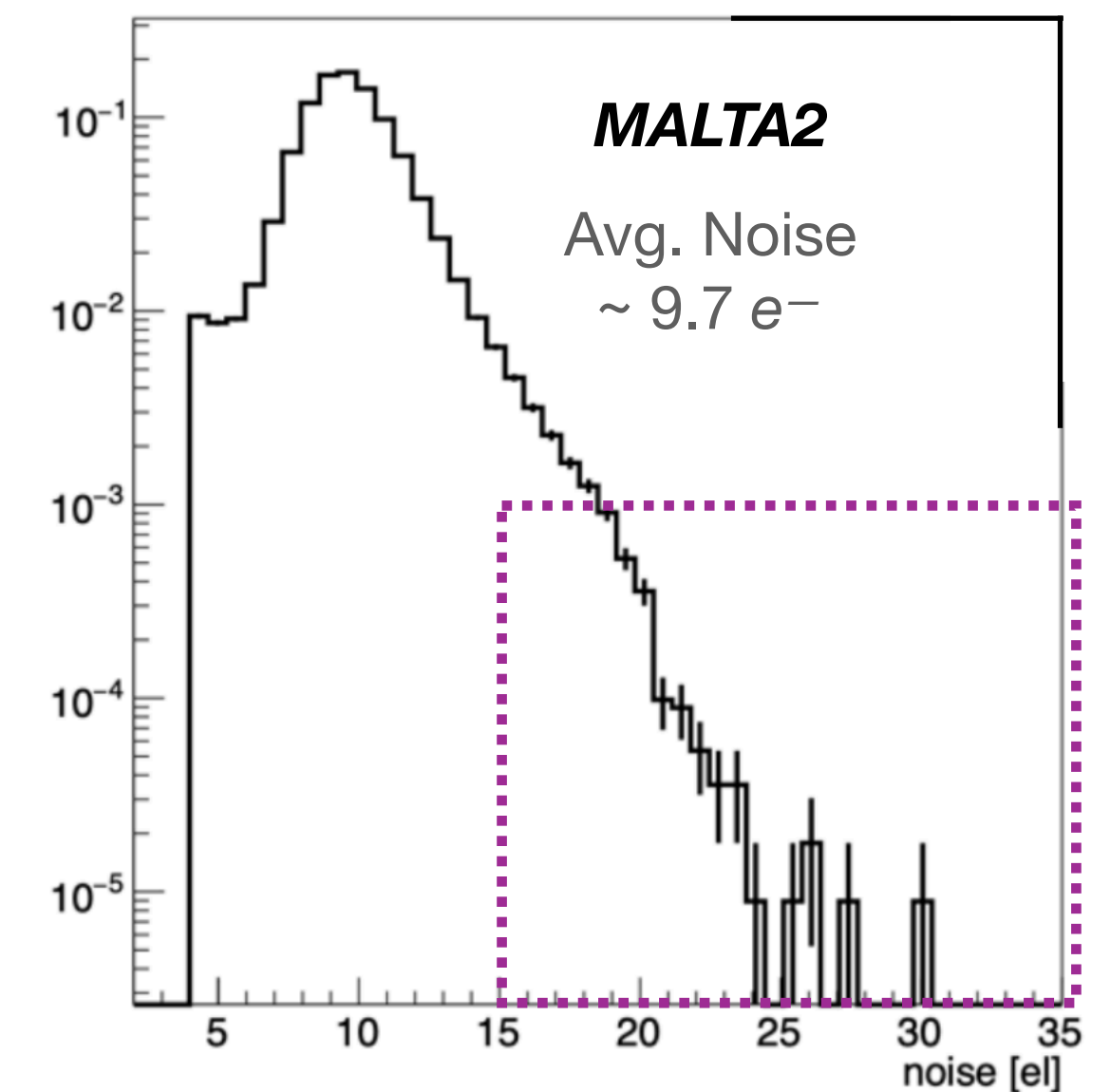
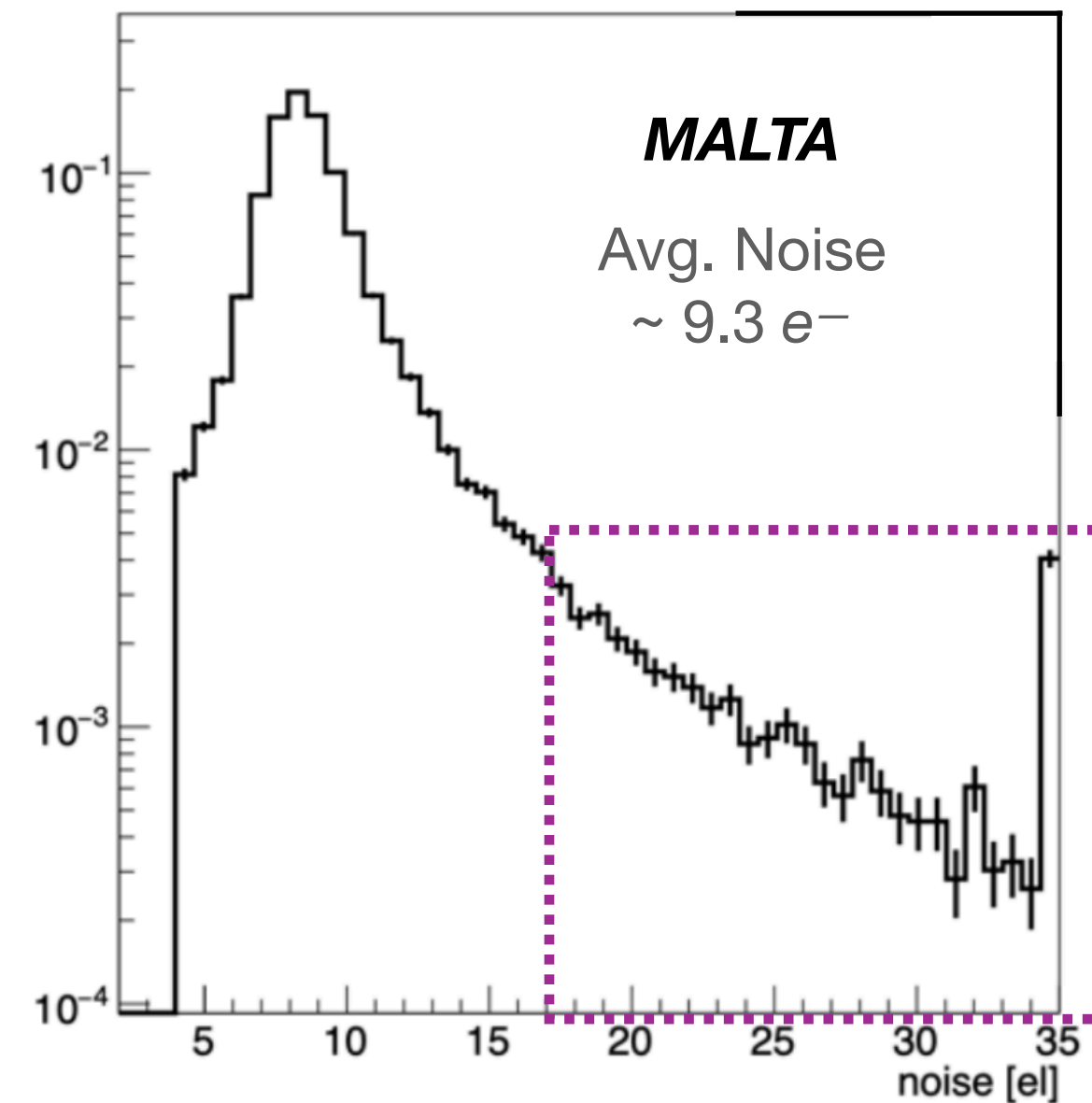
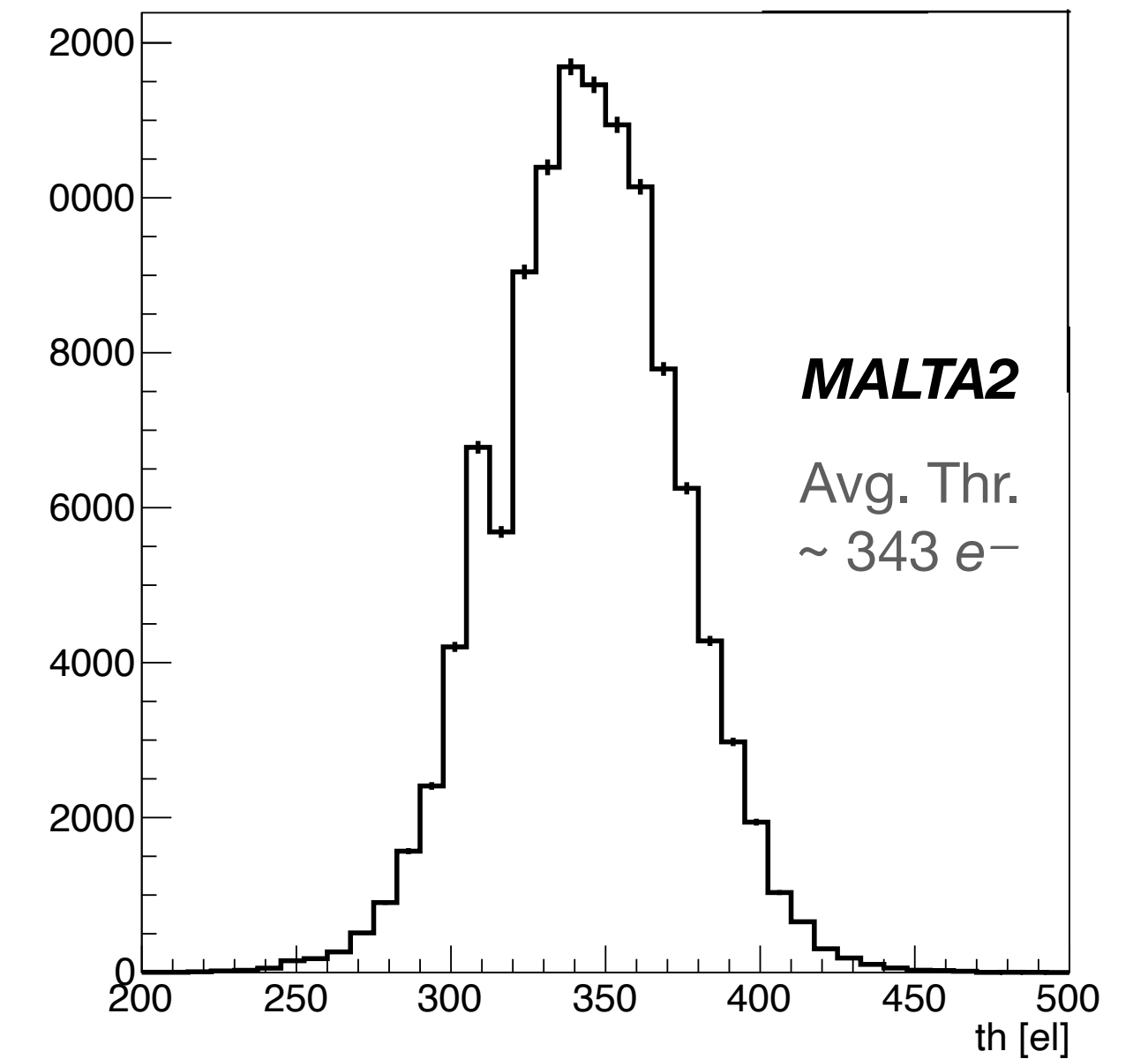
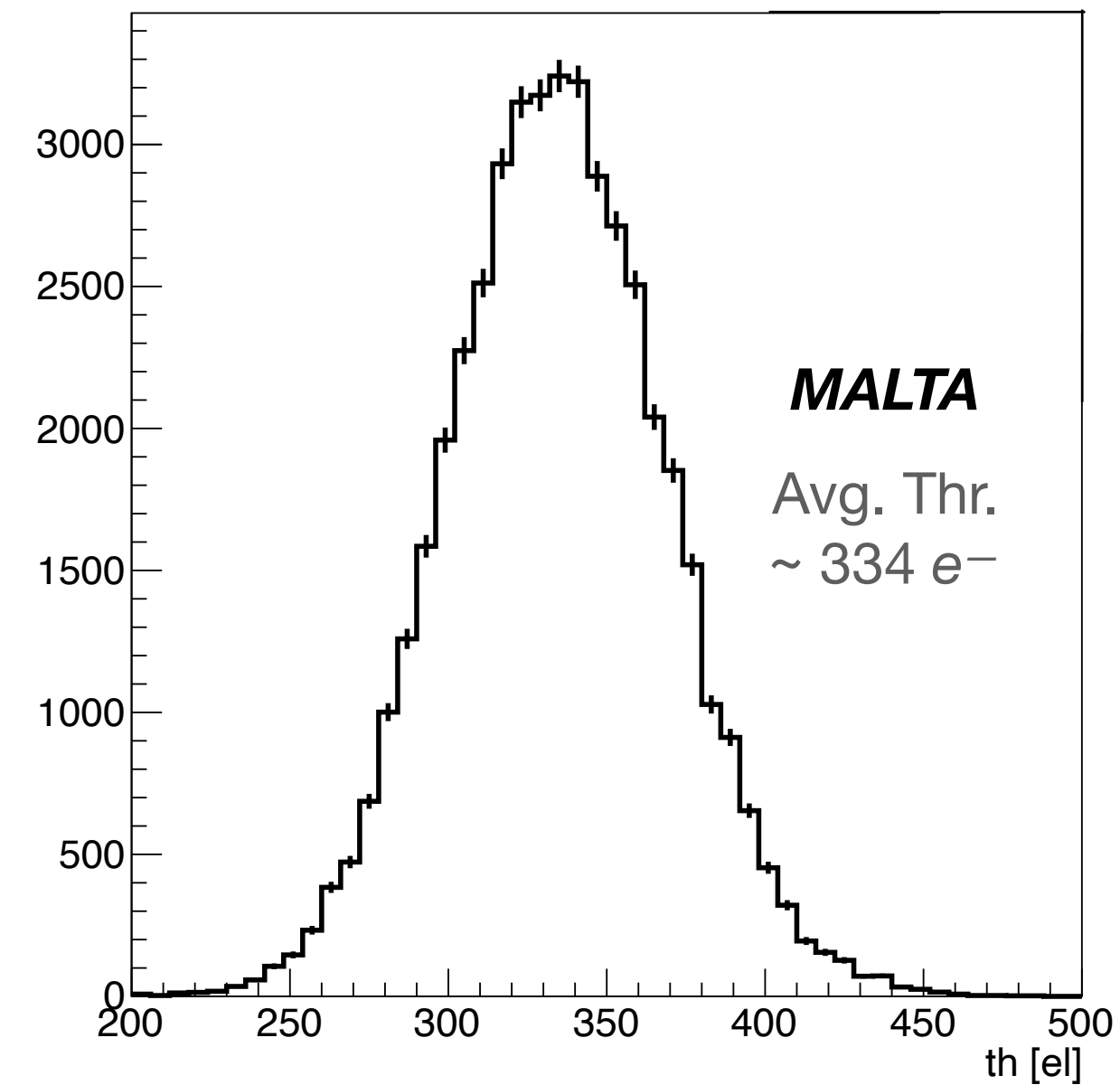
Variation across vertical 32-pixel columns of matrix attributed to front-end biasing scheme, will be refined in future MALTA prototypes.

No systematic trends observed for pixel noise as a function of the matrix.

Threshold variation within a single biasing group is  $\sim 5.1 e^-$ .

# MALTA vs. MALTA2

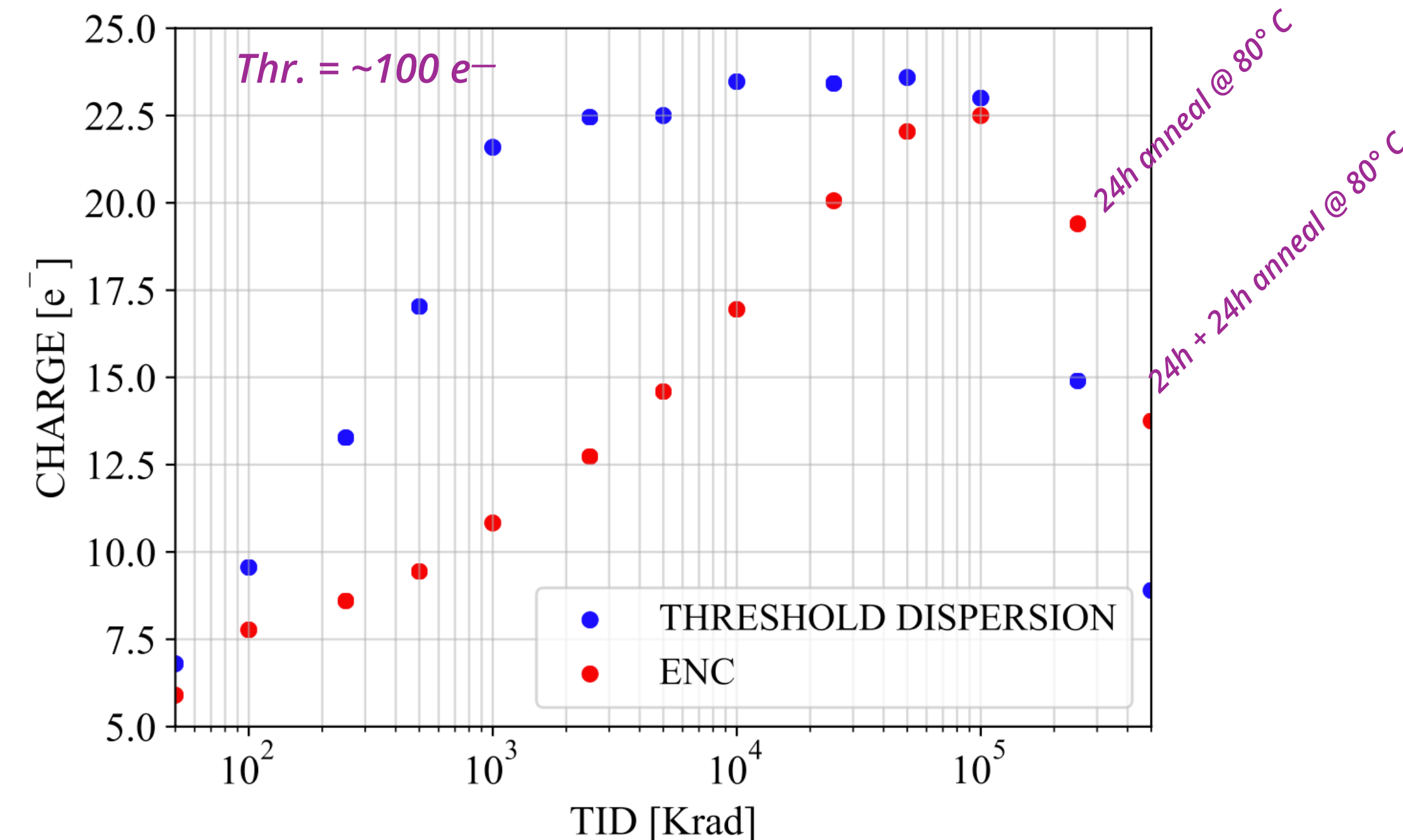
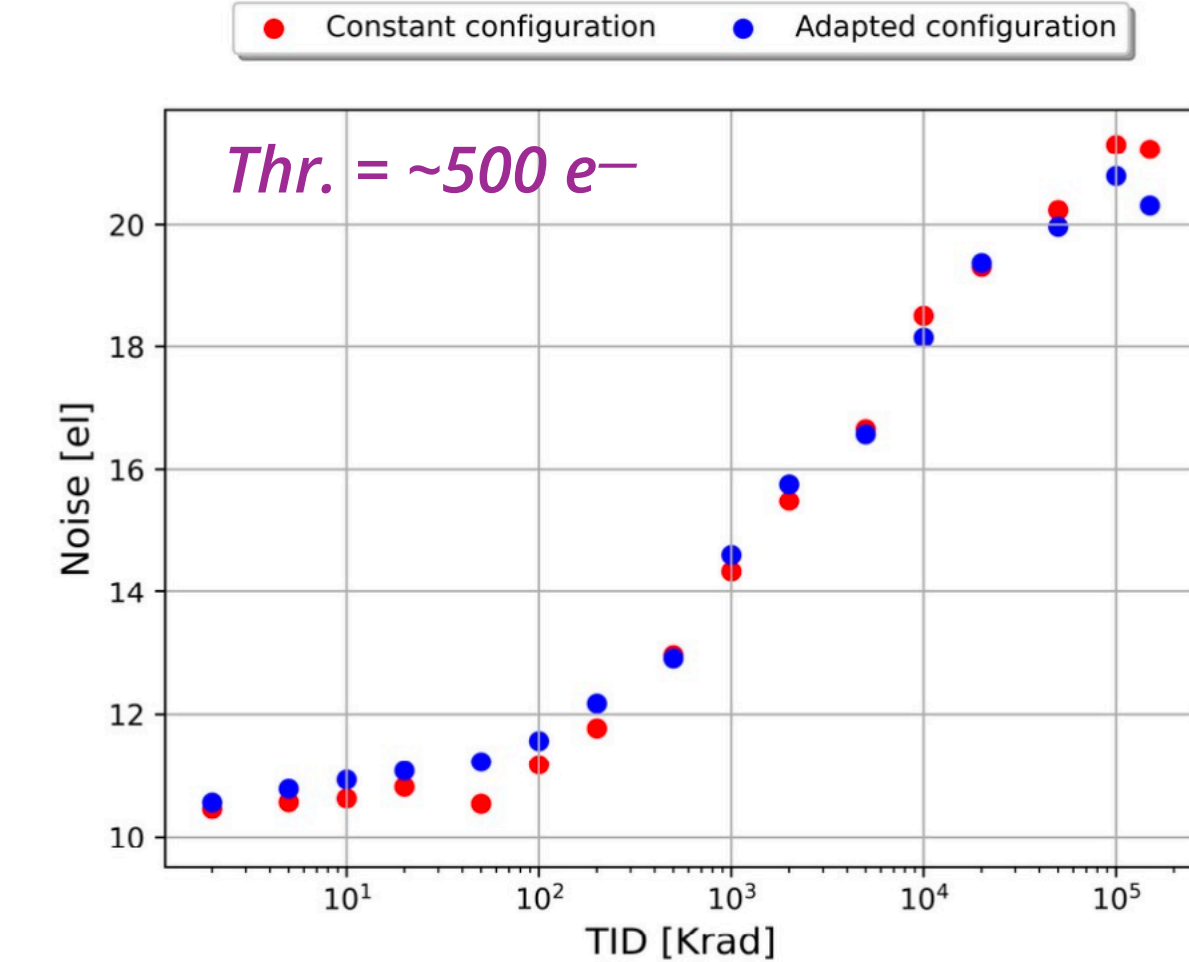
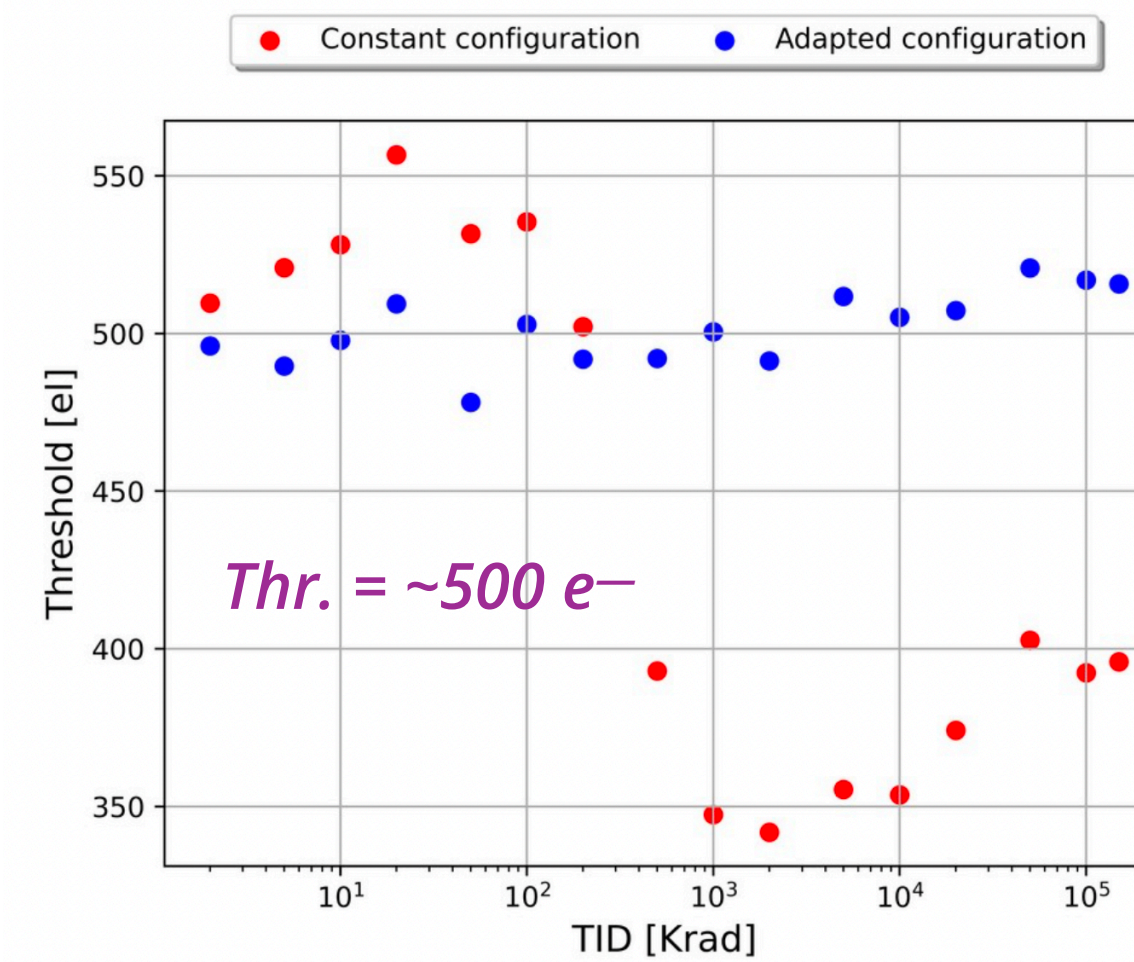
- Comparison of MALTA & MALTA2 at compatible threshold ( $\sim 340 e^-$ ).
  - **Significant reduction of non-Gaussian tails in noise distribution.**
- Attributed to improved MALTA2 front-end.
- Both chips are epi. w/ gap in n-layer
  - High doping of n-layer
  - 300  $\mu m$  thickness
  - Unirradiated



# MALTA2 Front-End : Stability after irradiation

- Two additional studies of front-end **performance at higher TIDs, up to 150 MRad**, by irradiating sensors with X-ray laser.
- Constant thresholds at  $100 e^-$ ,  $500 e^-$  were maintained by **manually re-adjusting front-end settings** between steps of irradiation.
  - **Sensors remained fully functional** throughout irradiation.
  - **Noise found to increase monotonically with TID** in both studies.
  - For study at thr.  $\sim 100 e^-$ , **24h annealing at  $80^\circ C$  was performed after each of the final two steps.**
    - Noise and threshold dispersion performance found to recover after procedure!

## Higher-doped n-layer

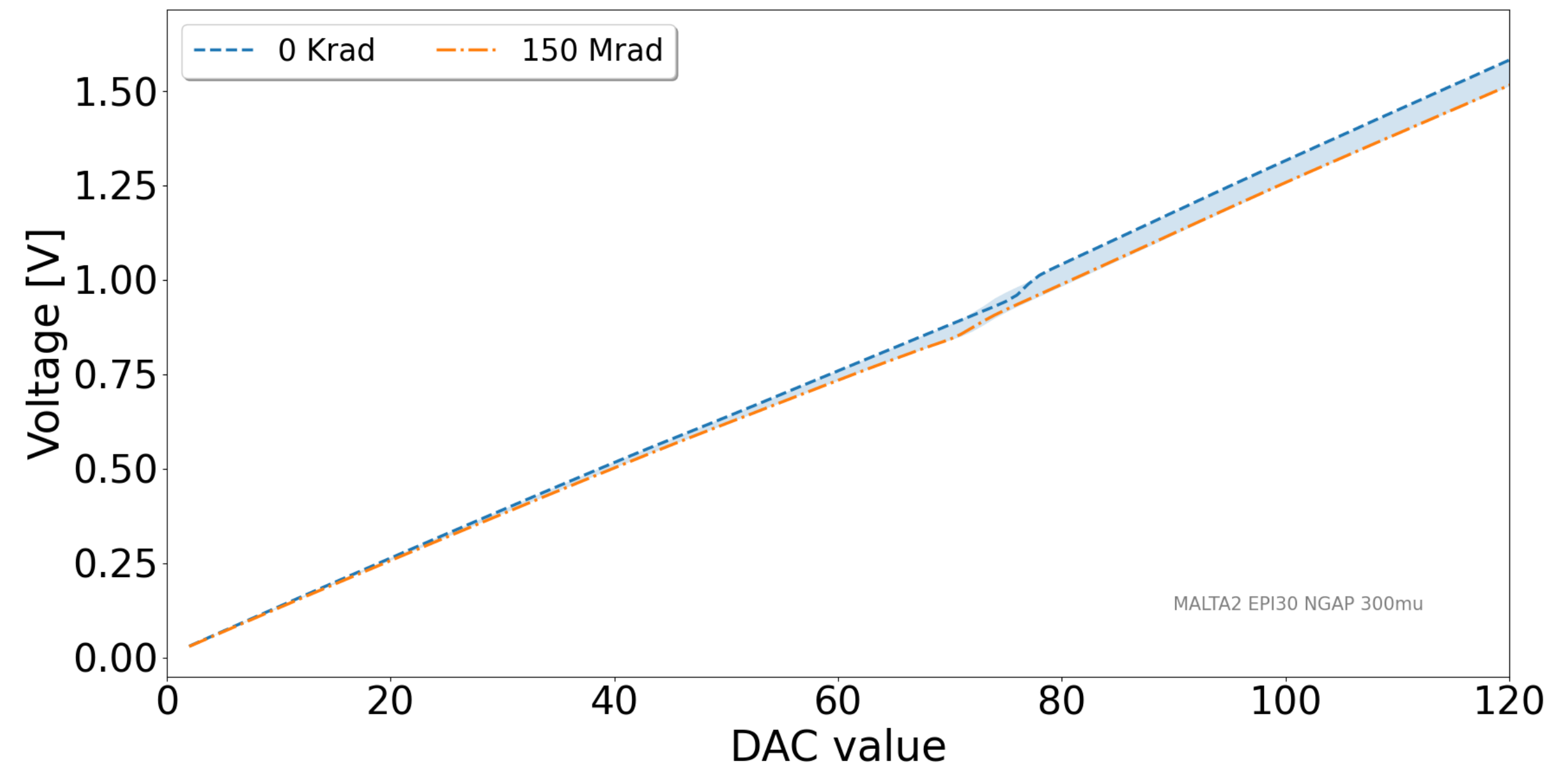


## Lower-doped n-layer



# MALTA2 Front-End : Stability after irradiation

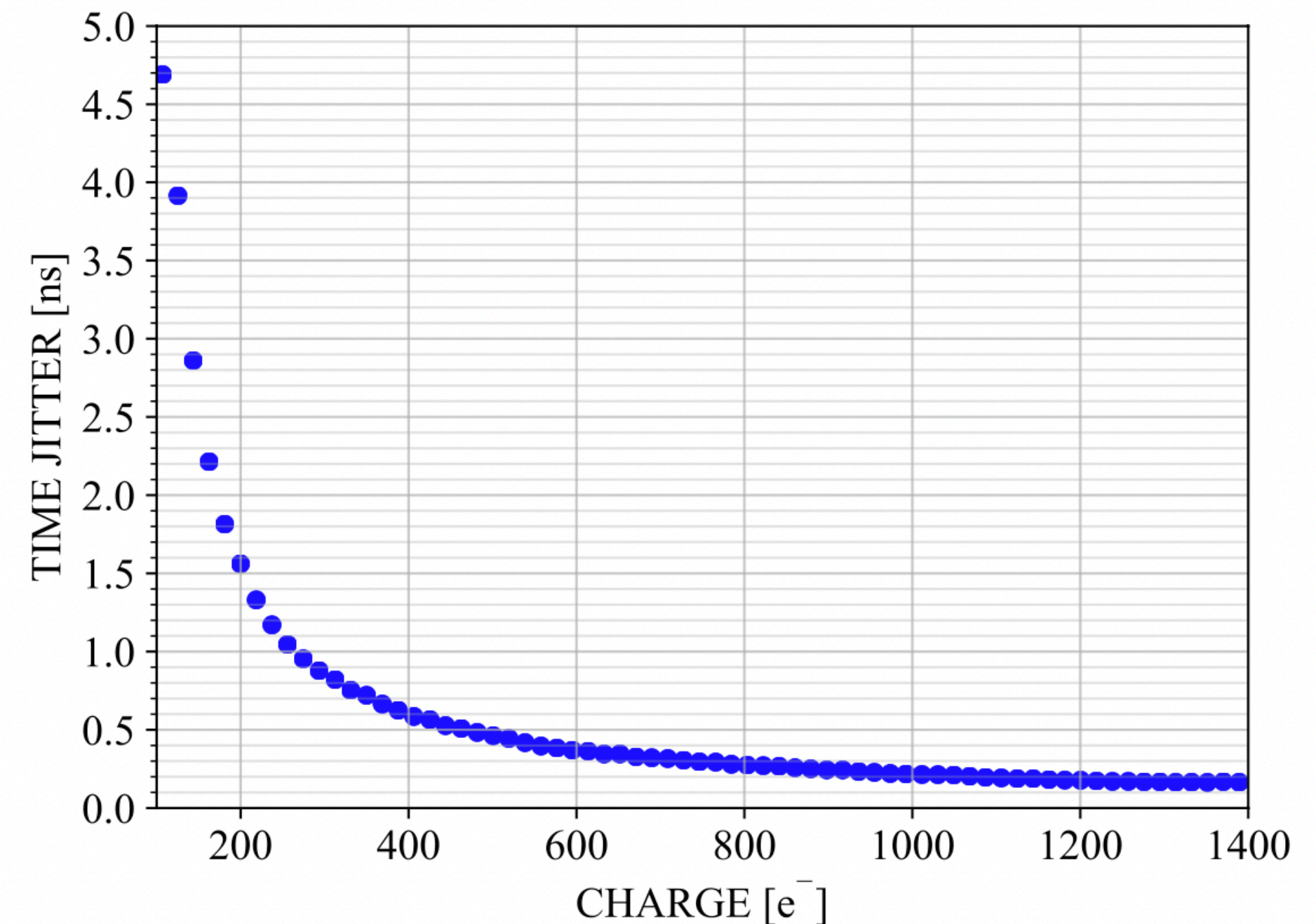
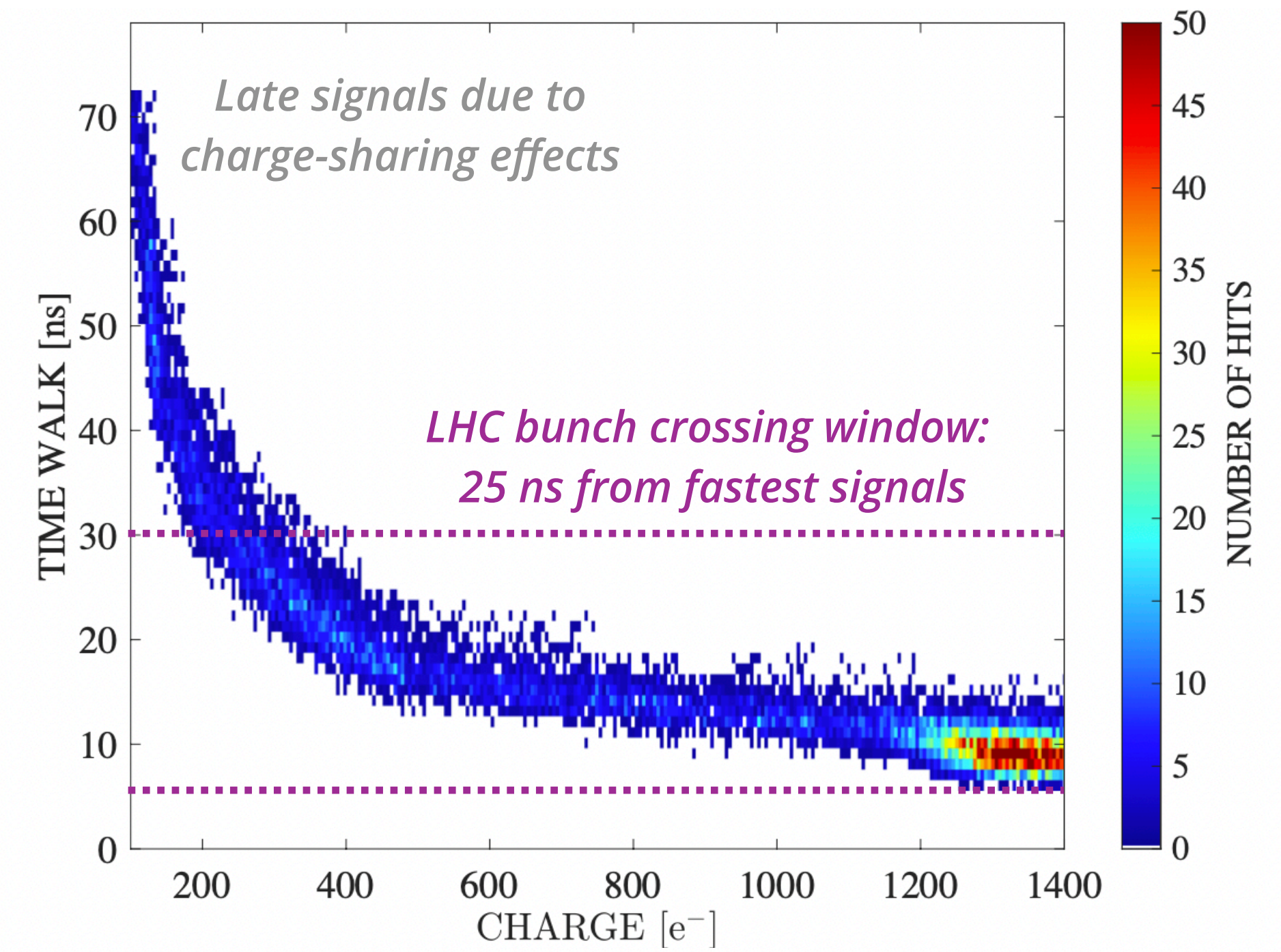
- Two additional studies of front-end **performance at higher TIDs, up to 150 MRad**, by irradiating sensors with X-ray laser.
- Constant thresholds at 100  $e^-$ , 500  $e^-$  were maintained by **manually re-adjusting front-end settings** between steps of irradiation.
  - **Sensors remained fully functional** throughout irradiation.
  - **Noise found to increase monotonically with TID** in both studies.
  - For study at thr.~100  $e^-$ , **24h annealing at 80° C was performed after each of the final two steps.**
    - Noise and threshold dispersion performance found to recover after procedure!
  - Linearity of front-end response (digital-to-analogue converters) vs. TID also verified.
    - Slight non-linearity related to the DAC under study, has no impact on front-end operation.



*Blue envelope represents spread of scans at intermediate irradiation steps*

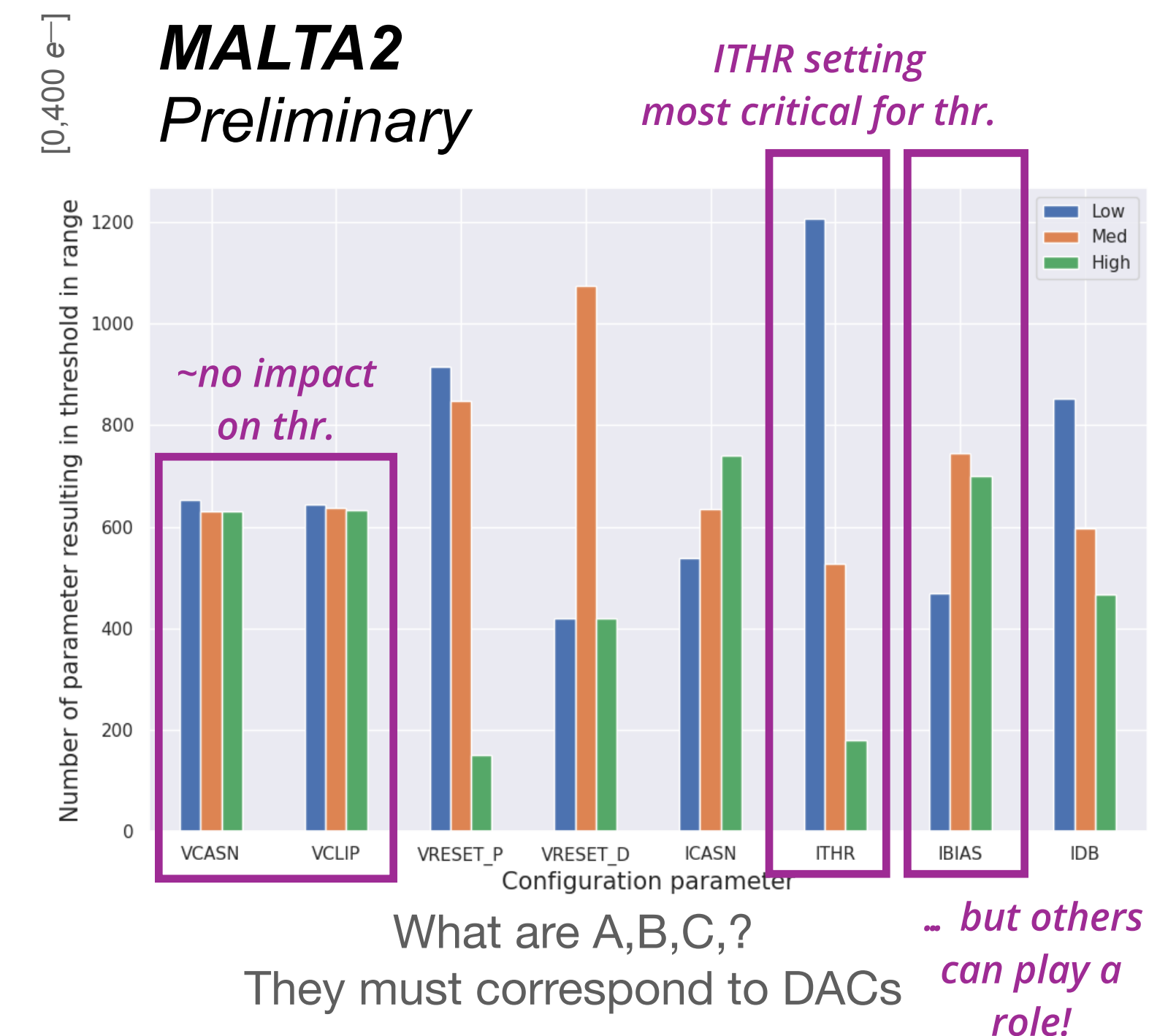
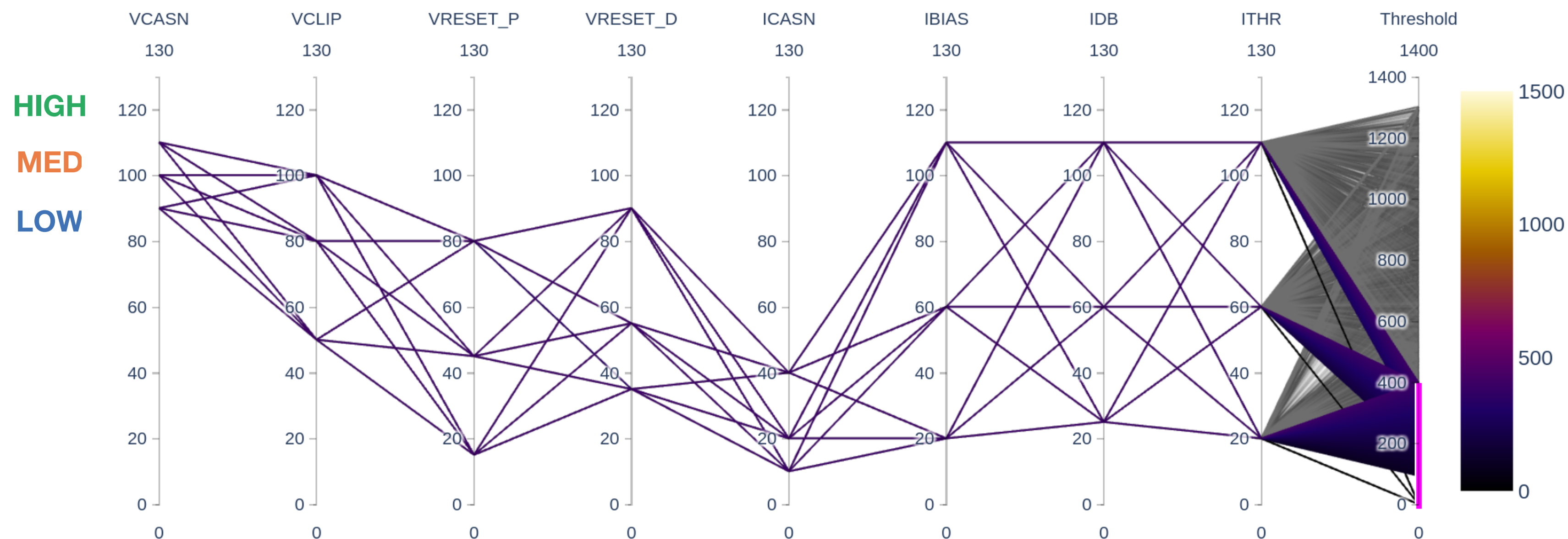
# MALTA2 Front-End : Timing

- Time-walk of front-end measured using special pixels with analogue output monitoring.
  - Time for amplifier output to reach discriminator threshold, depends on charge deposition.
  - Sensor exposed to  **$^{90}\text{Sr}$  source in lab**
    - MIP-like signals, avg. deposition  $\sim 1800 e^-$ .
      - 90% of hits arrive within 25 ns window.
      - For largest deposited charges, time-walk  $\sim 10$  ns.
      - Contributions with small charge deposition attributed to charge-sharing effects (expect small signals from pixel corners to arrive later).
- Can also measure time jitter of front-end by injecting charge in pixel matrix and triggering on signal using CERN-developed PicoTDC ASIC.
  - Time jitter dominated by front-end, which varies from 4.7 ns to 0.17 ns as injected charge increases.



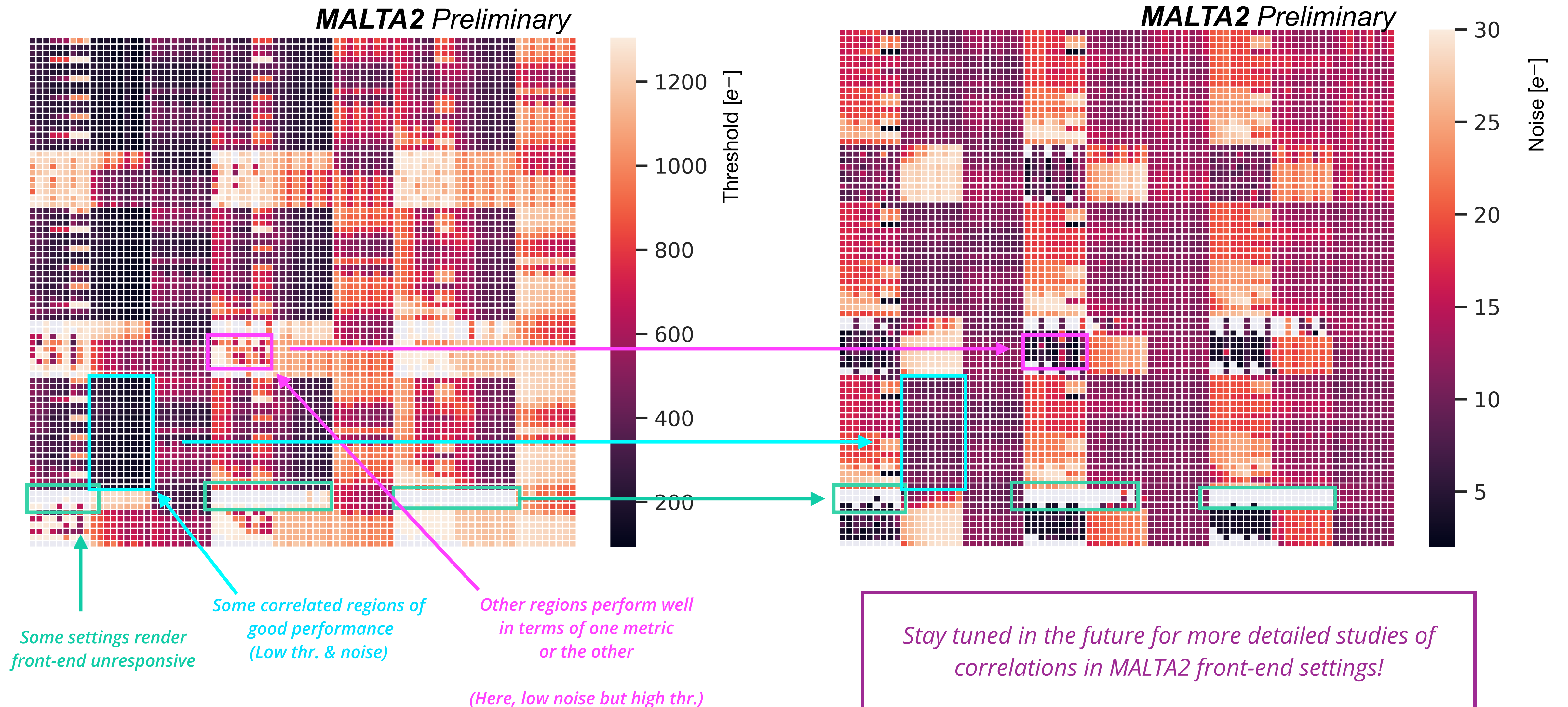
# MALTA2 Front-End : DAC correlations

## MALTA2 Preliminary



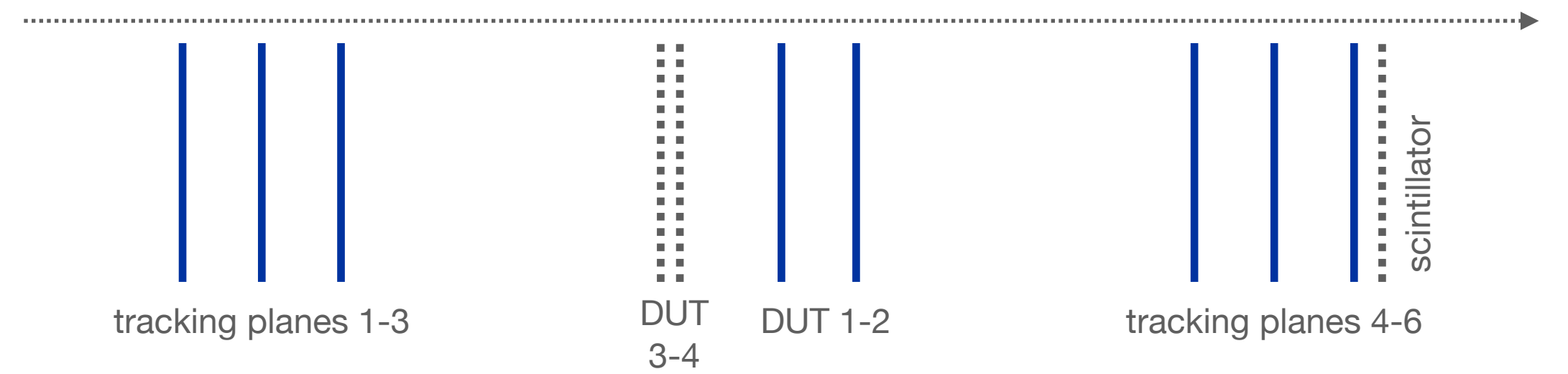
- More detailed studies of the front-end behaviour are underway — in this study, many combinations of front-end settings are evaluated in terms of the resultant **threshold** (pictured), **noise** & **number of inactive pixels**.
- DACs are designed to be linearly independent — but in practice, some nonlinear codependencies exist.  
*How many different configurations yield comparable front-end performance? Does this picture change with TID?*
- Pushing some settings to the margins of design range in order to probe a large parameter space.

# MALTA2 Front-End : DAC correlations

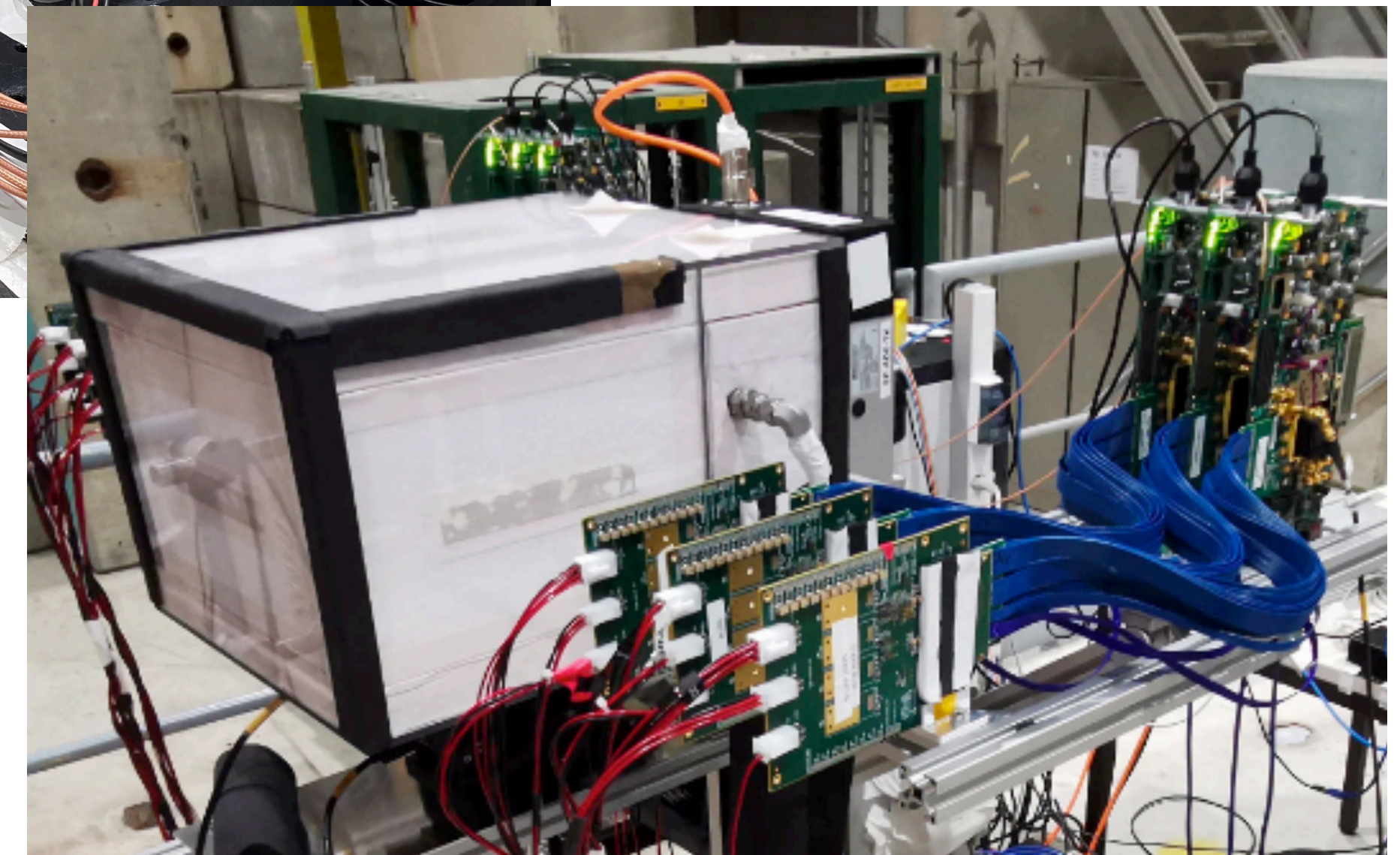
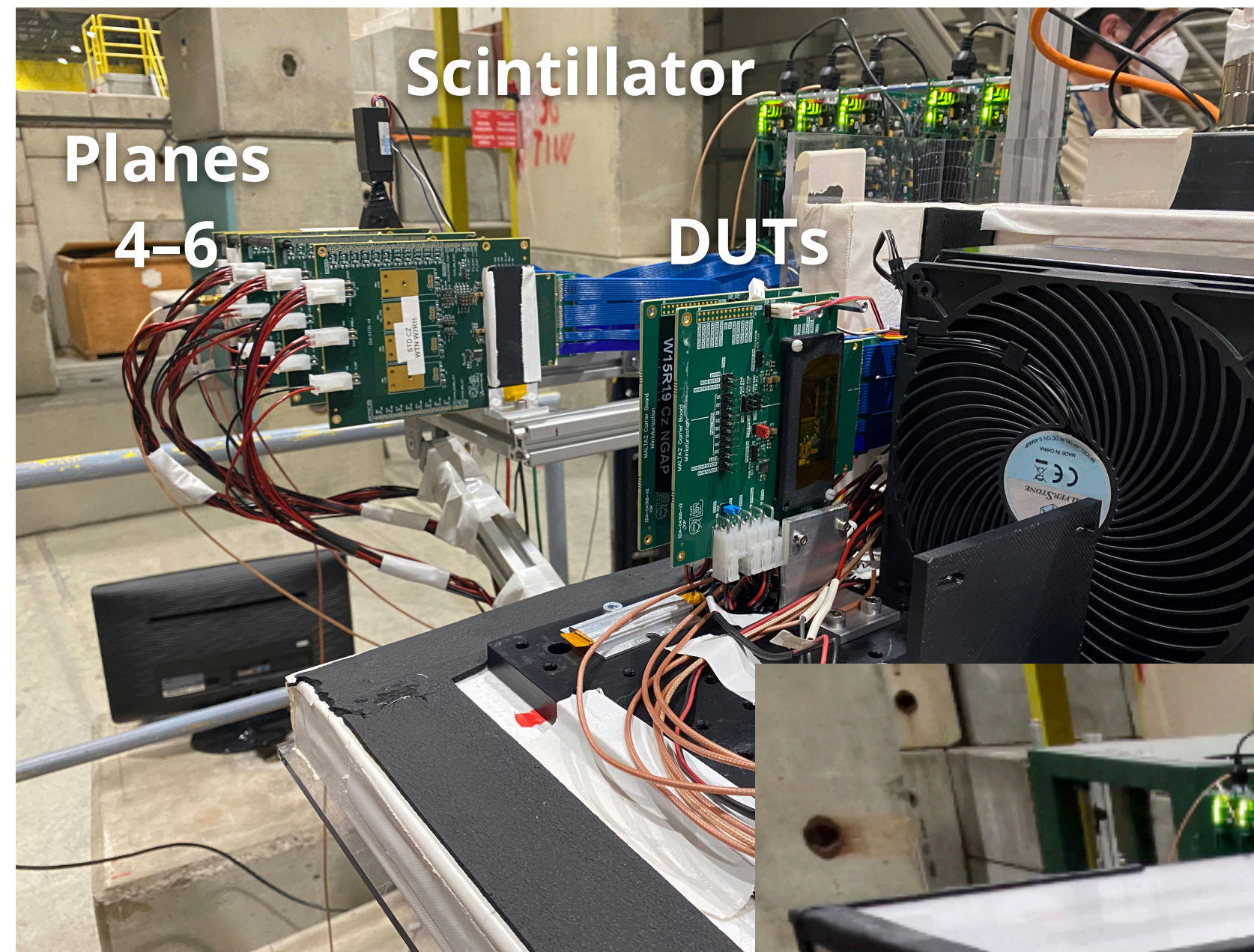


# MALTA Telescope @ SPS

SPS H6 Beamline



- Operating an eight-plane telescope in **CERN's SPS H6 beamline**.
  - 180 GeV proton beam.
  - Continuous data-taking from summer 2021 until end-of-year.
- **Six tracking / triggering planes** (MALTA, 2xCz, 4xEpi), and **up to two MALTA2 Devices Under Test (DUTs)**.
  - Use of MALTA with high-resistivity **Czochralski (Cz)** substrate for tracking planes **produces increased cluster size**, improves spatial resolution of telescope.
- Campaign to demonstrate **MALTA2 performance** in terms of **radiation tolerance** and **timing performance**.

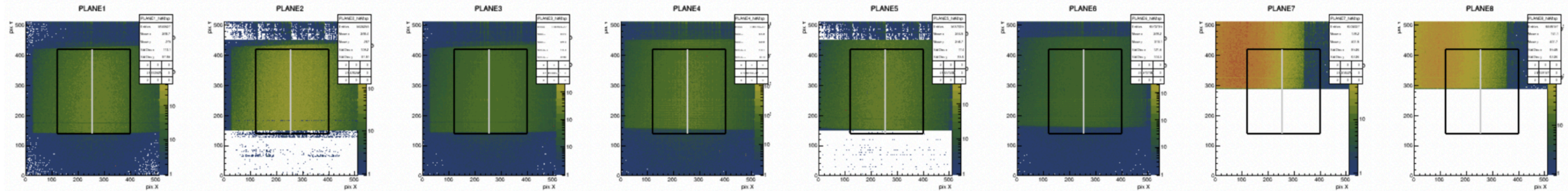


# SPS Testbeam Monitoring Plots

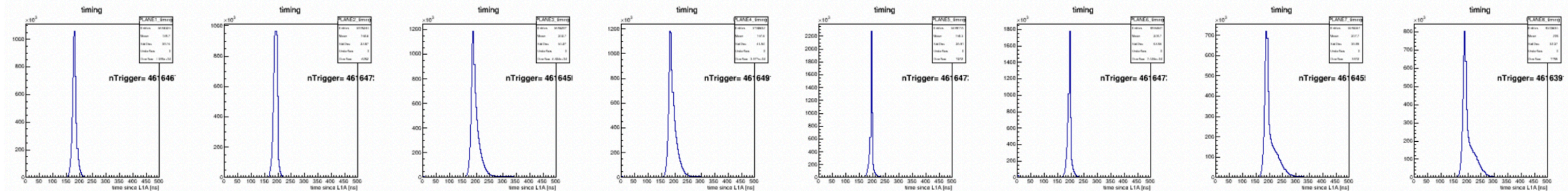
DUT1

DUT2

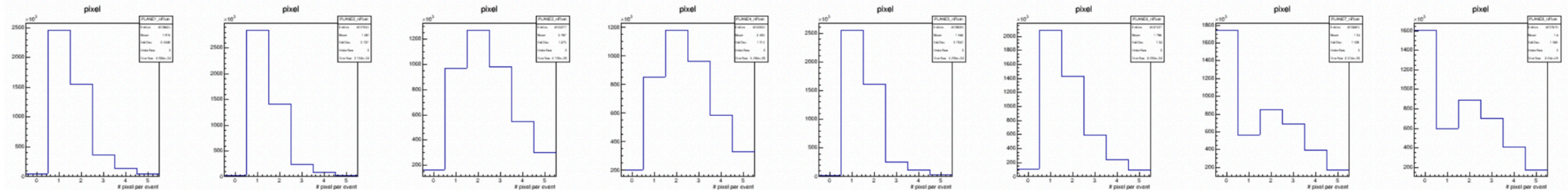
Hitmap



Time since L1A

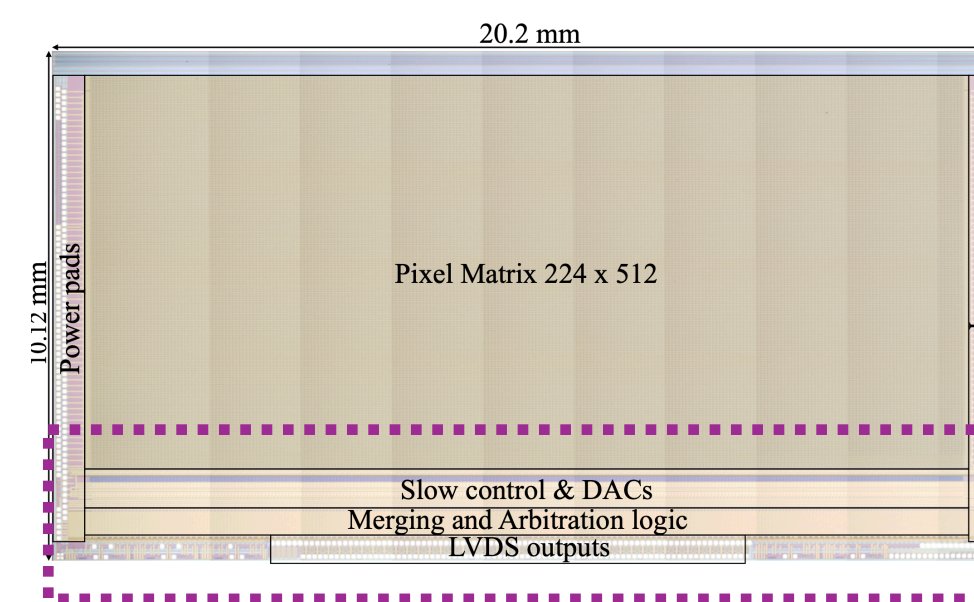


#pixel /event

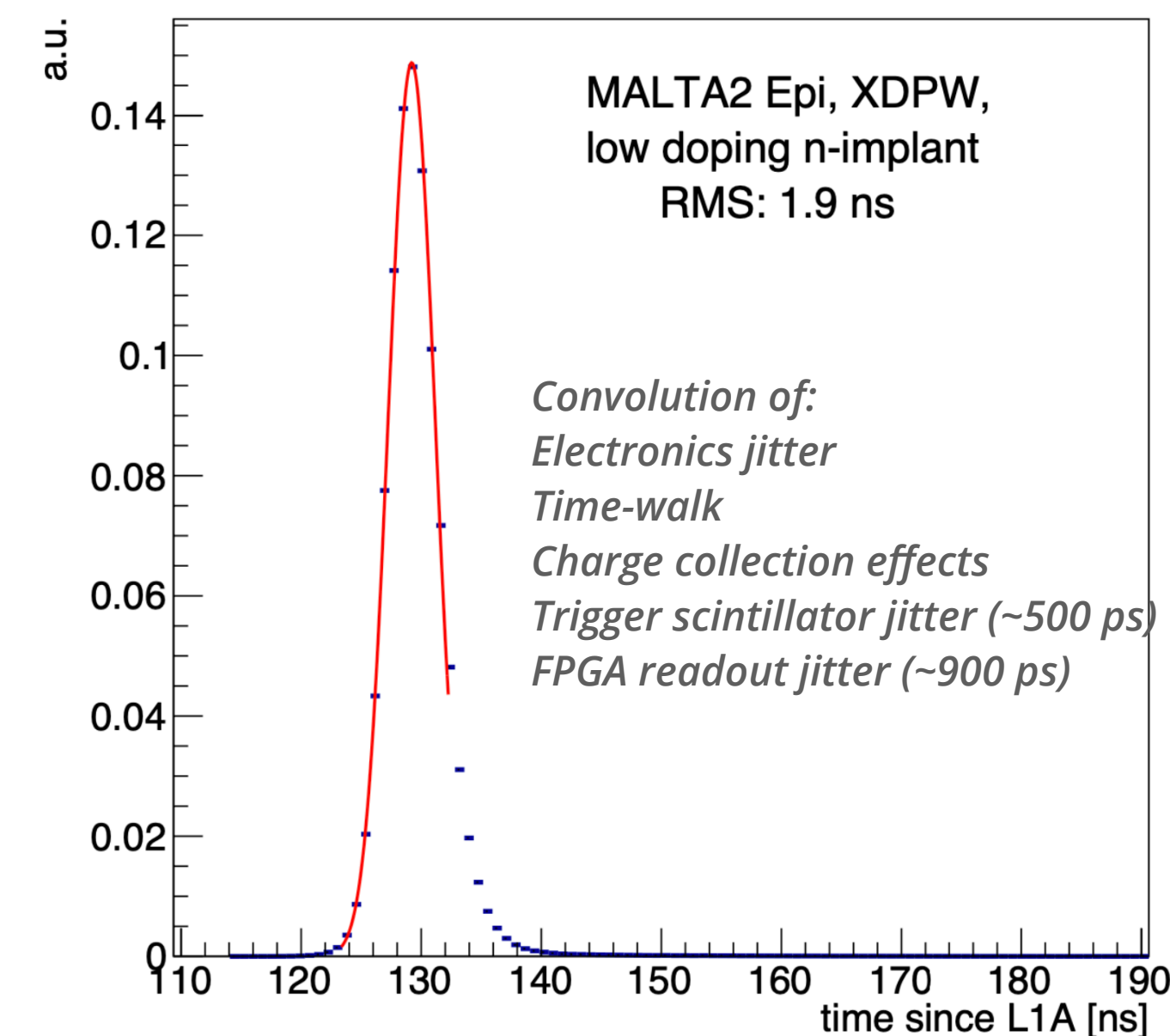


- Realtime monitoring with hitmap, time distribution and number of hits per-event.
- Low noise / occupancy of MALTA allows for fast track reconstruction (~1.2 hits/plane/event).

# MALTA2 Timing



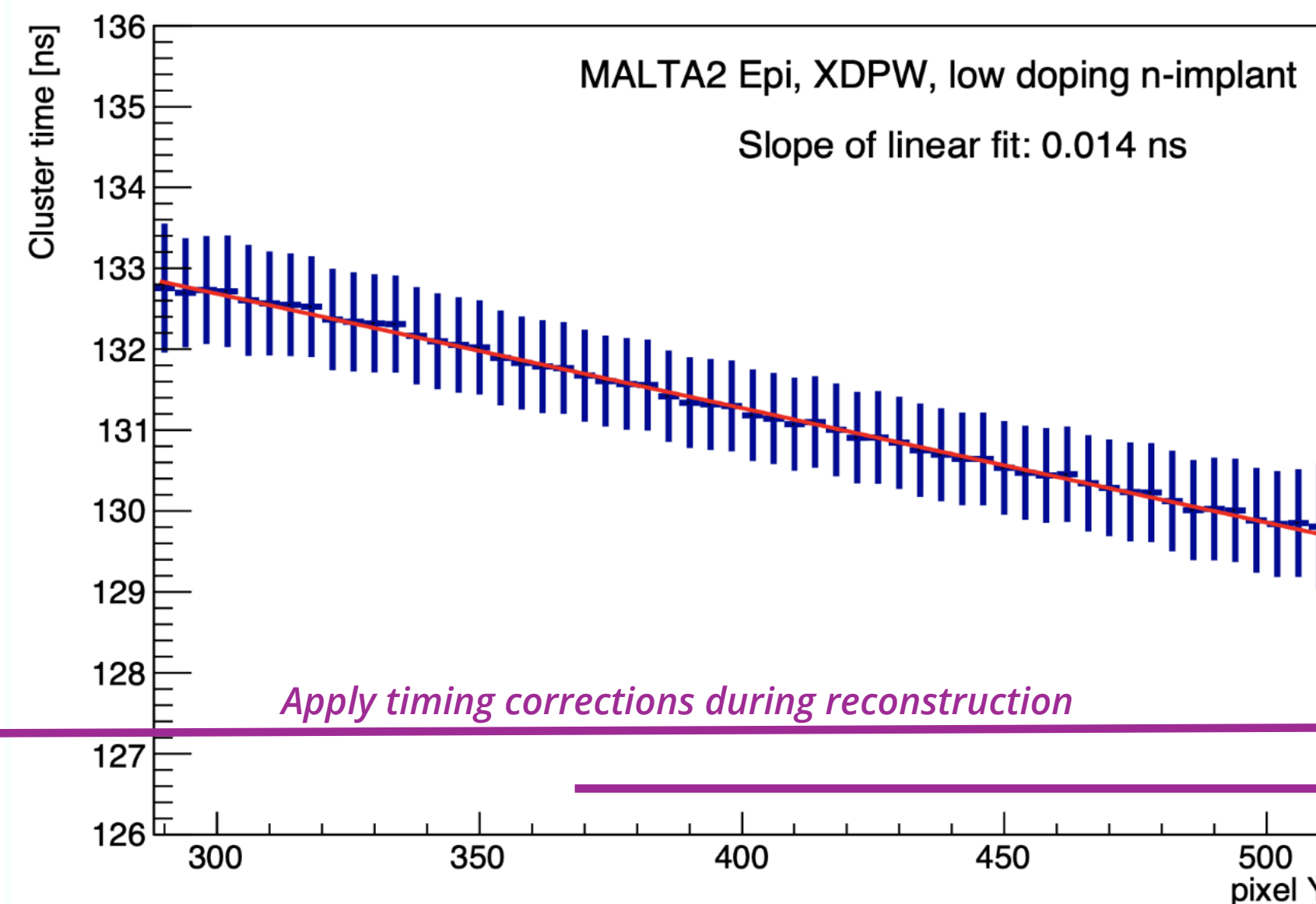
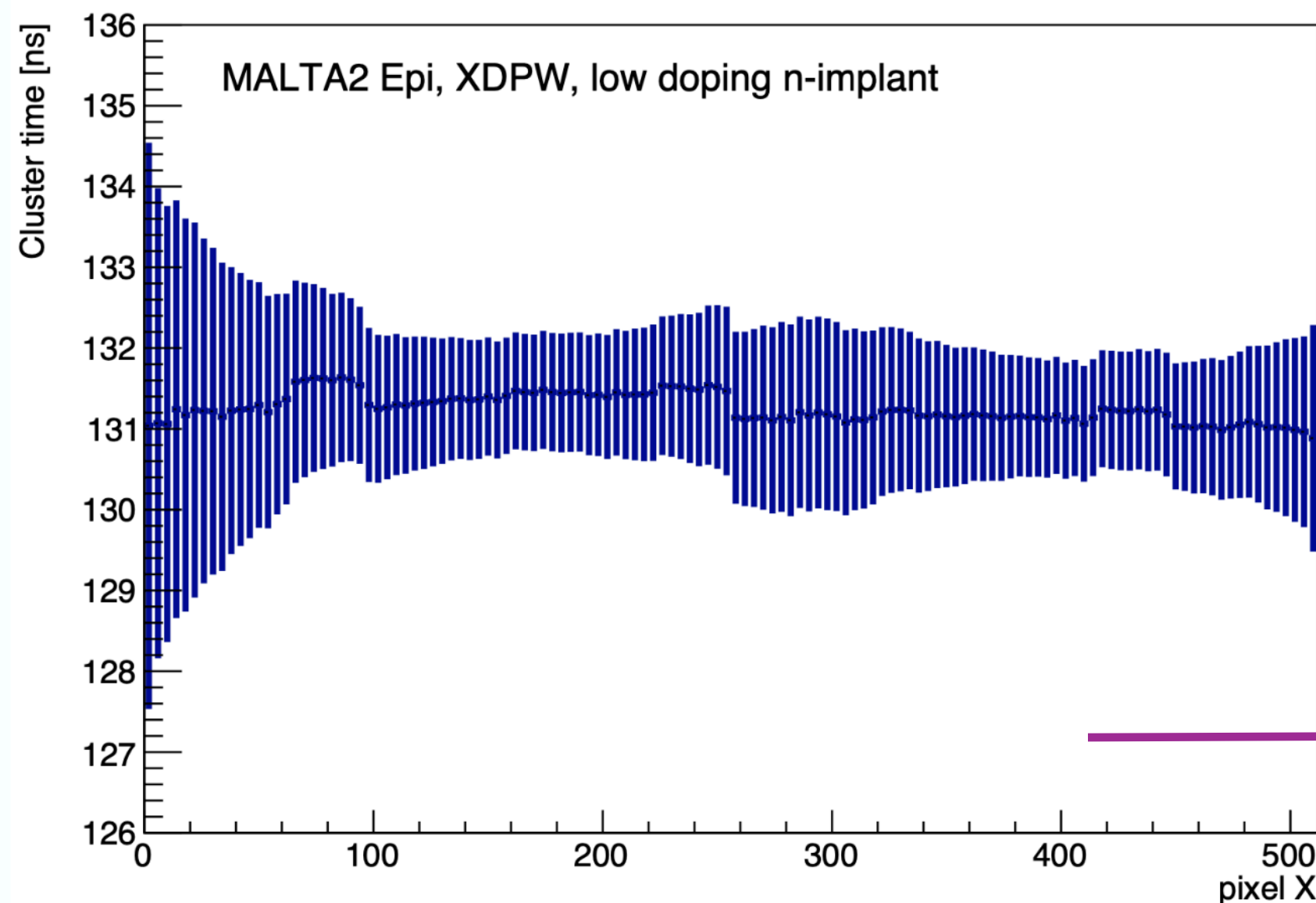
Corrected time of arrival for clusters matched to a track.



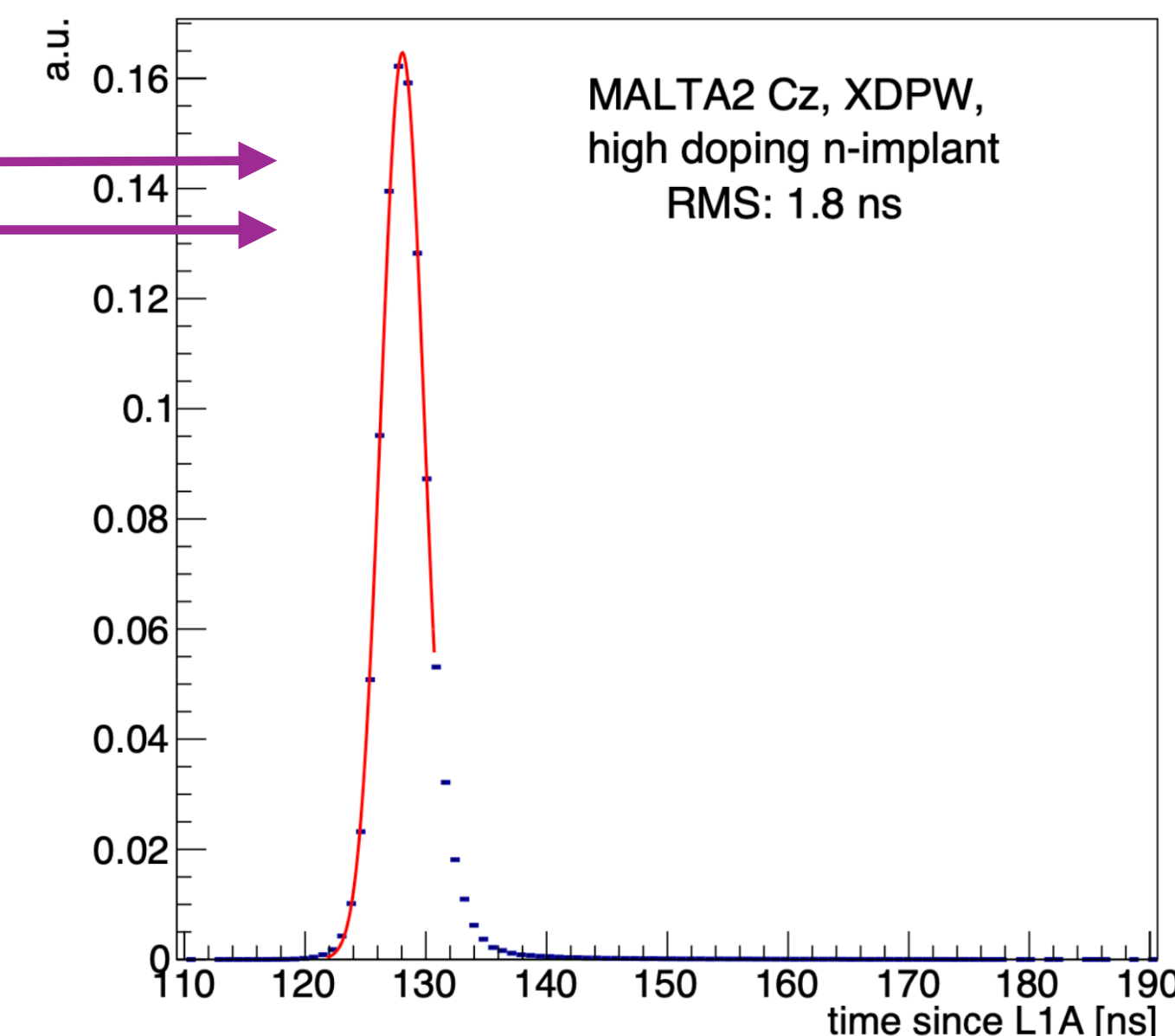
Bias groups visible

Far side of sensor

Read-out

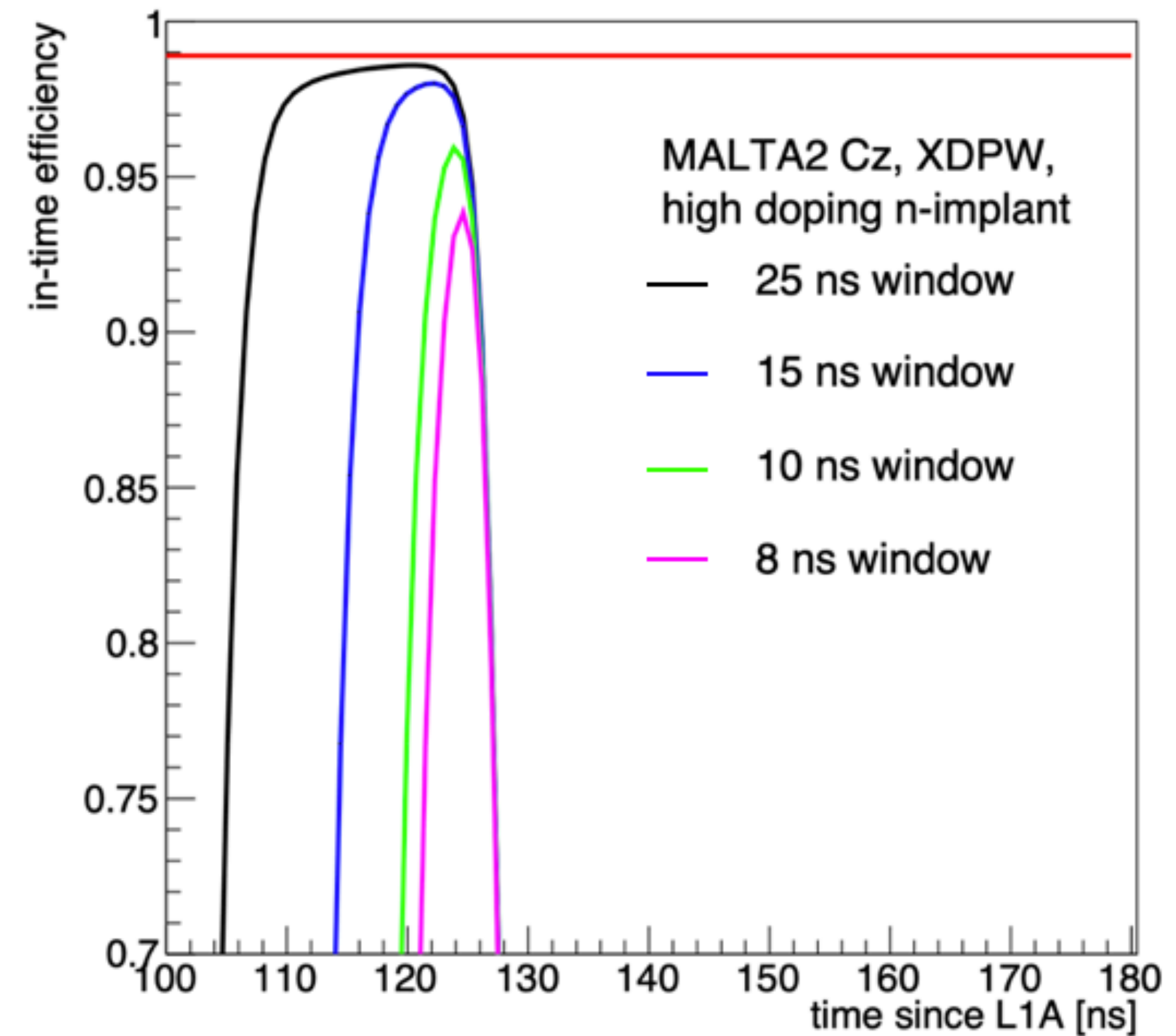
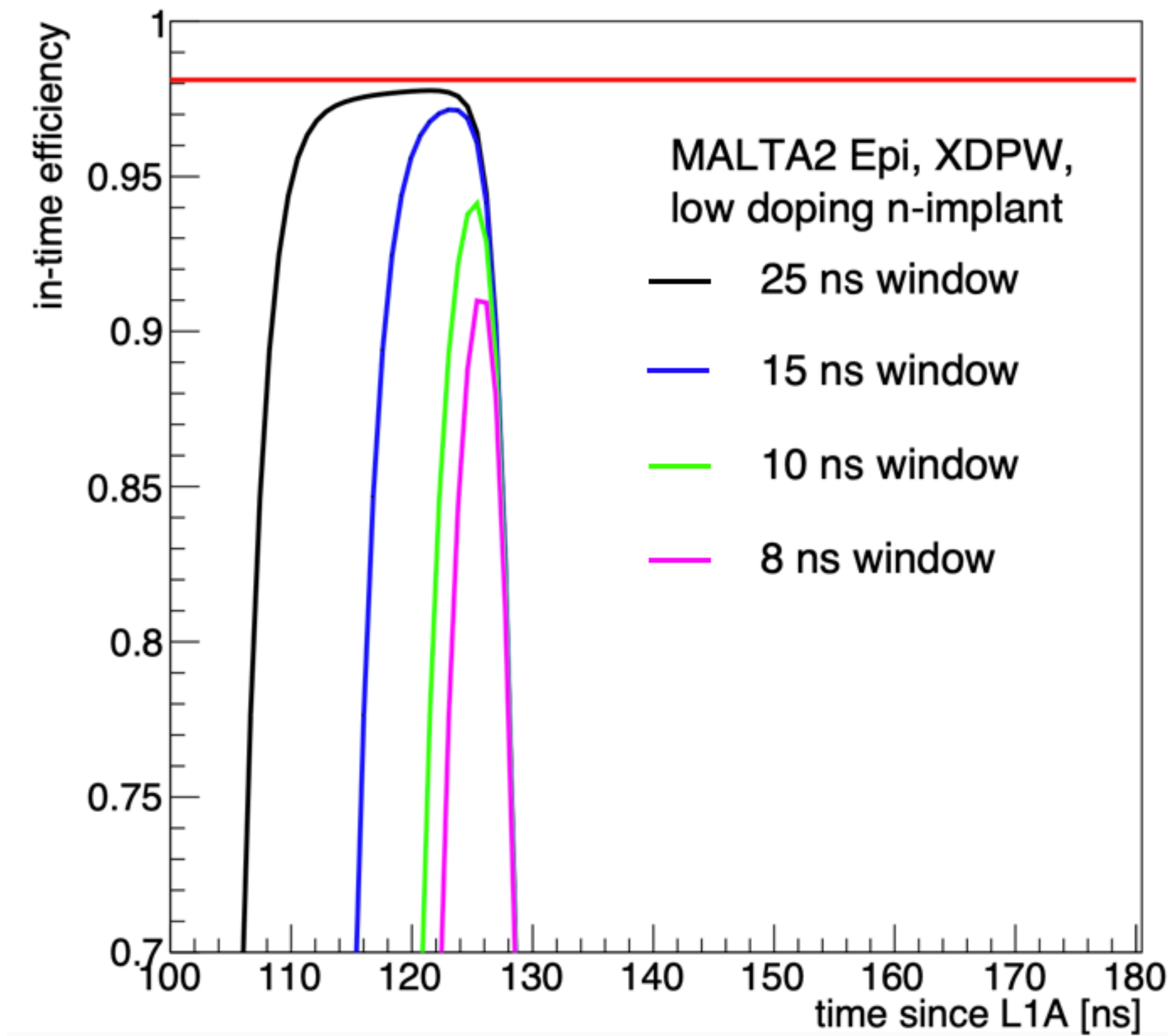


Apply timing corrections during reconstruction



- **Time of arrival of the fastest hit in a cluster**, as a function of the matrix X/Y coordinate.
  - There is some propagation time of signals from top-to-bottom of columns, different bias groups also exhibit slightly different arrival times.
  - After correcting for the arrival-time offset, we find that the average time between triggering and receiving a signal is  $\sim 1.8\text{--}1.9$  ns, for **MALTA2** with **extra-deep p-well (XDPW)**, with both high-resistivity **epitaxially grown** and **Czochralski (Cz)** substrates, and **different n-implant doping** concentrations.
- *n.b.* — only the difference between min & max cluster time values is relevant.  
Pipeline results in arrival of signal after  $\sim 130$  ns.

# MALTA2 Timing, *suite*.



*>98% of MALTA2 signals arrive within LHC 25 ns bunch spacing window!*

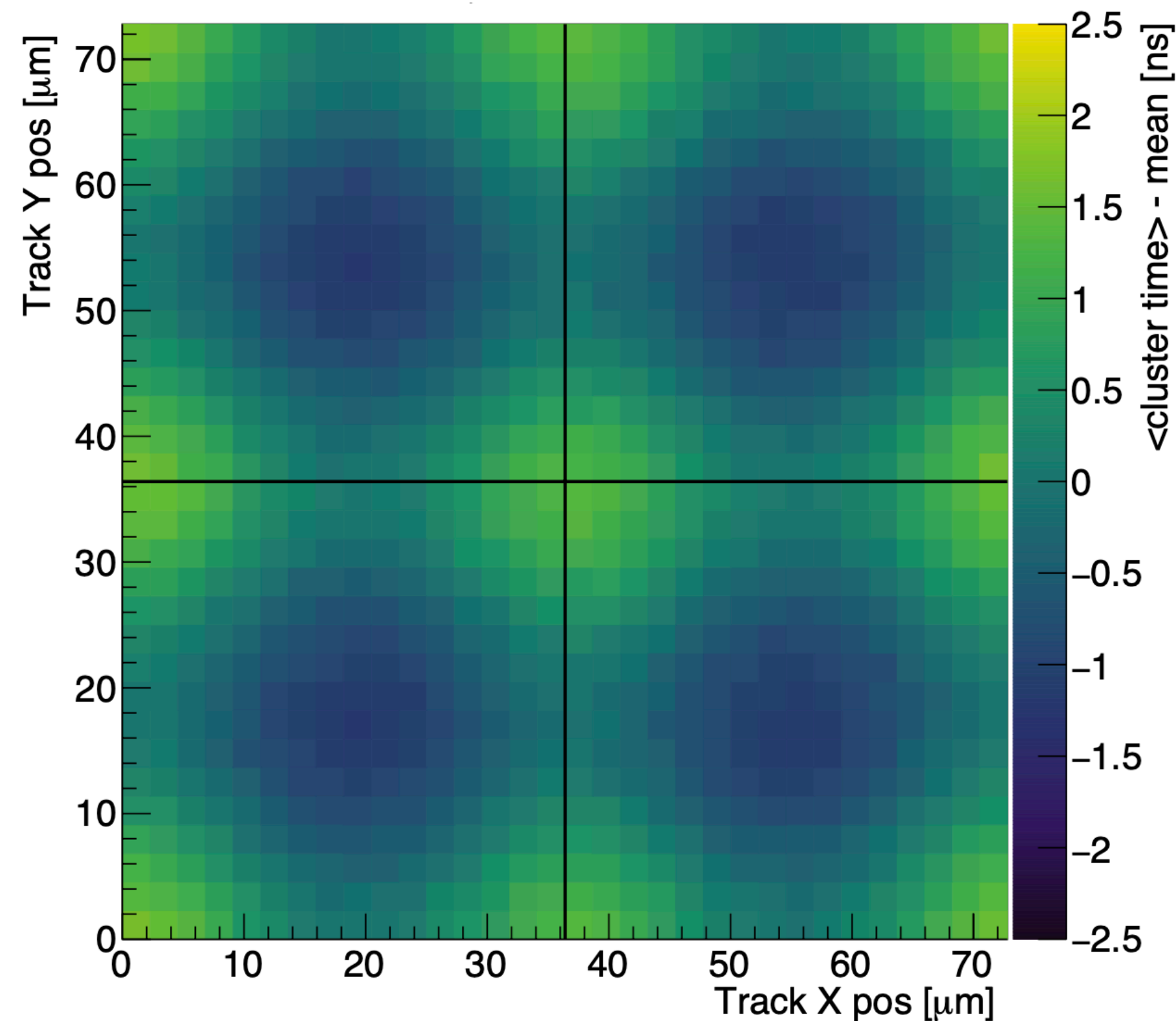
*Able to achieve >90% in-time efficiency for smaller windows (based on currently-discussed **ILC**, **FCC-ee** specifications).*



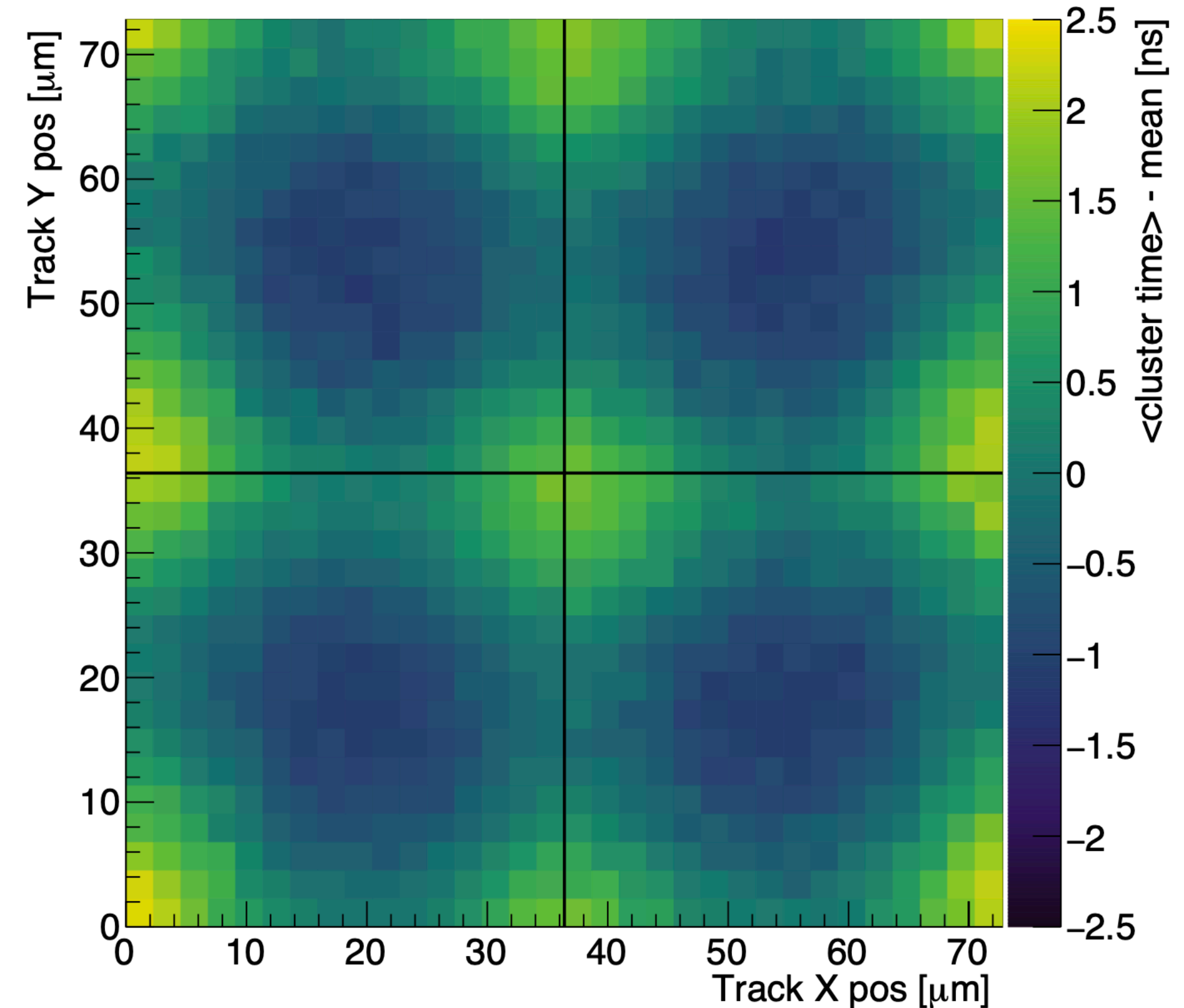
# MALTA2 Timing, *suite*.

(Thr. = 170  $e^-$ , substrate bias voltage -6 V.)

MALTA2 Epi. XDPW 100  $\mu\text{m}$ , low doping of n-implant



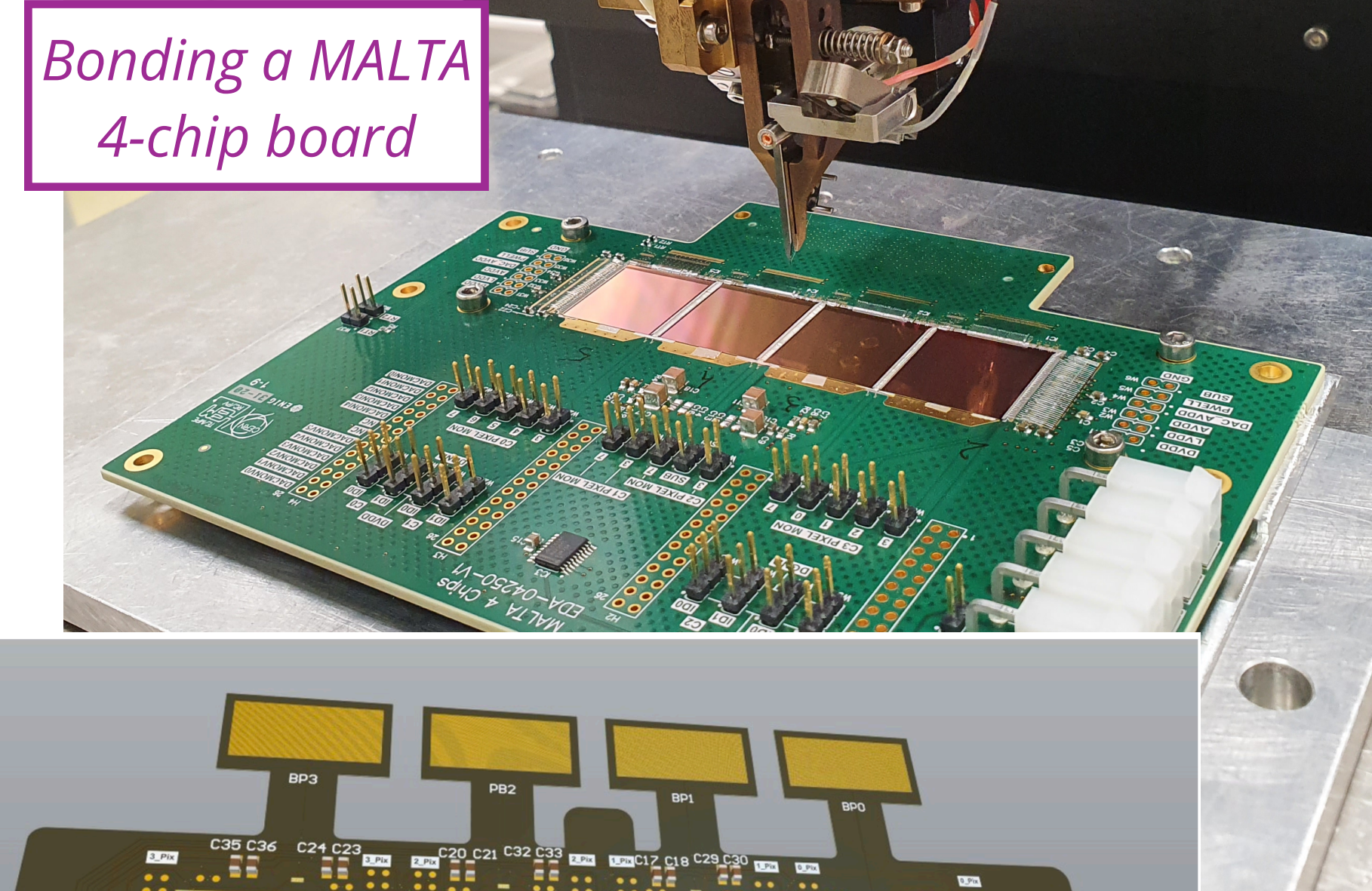
MALTA2 Cz. XDPW 100  $\mu\text{m}$ , low doping of n-implant



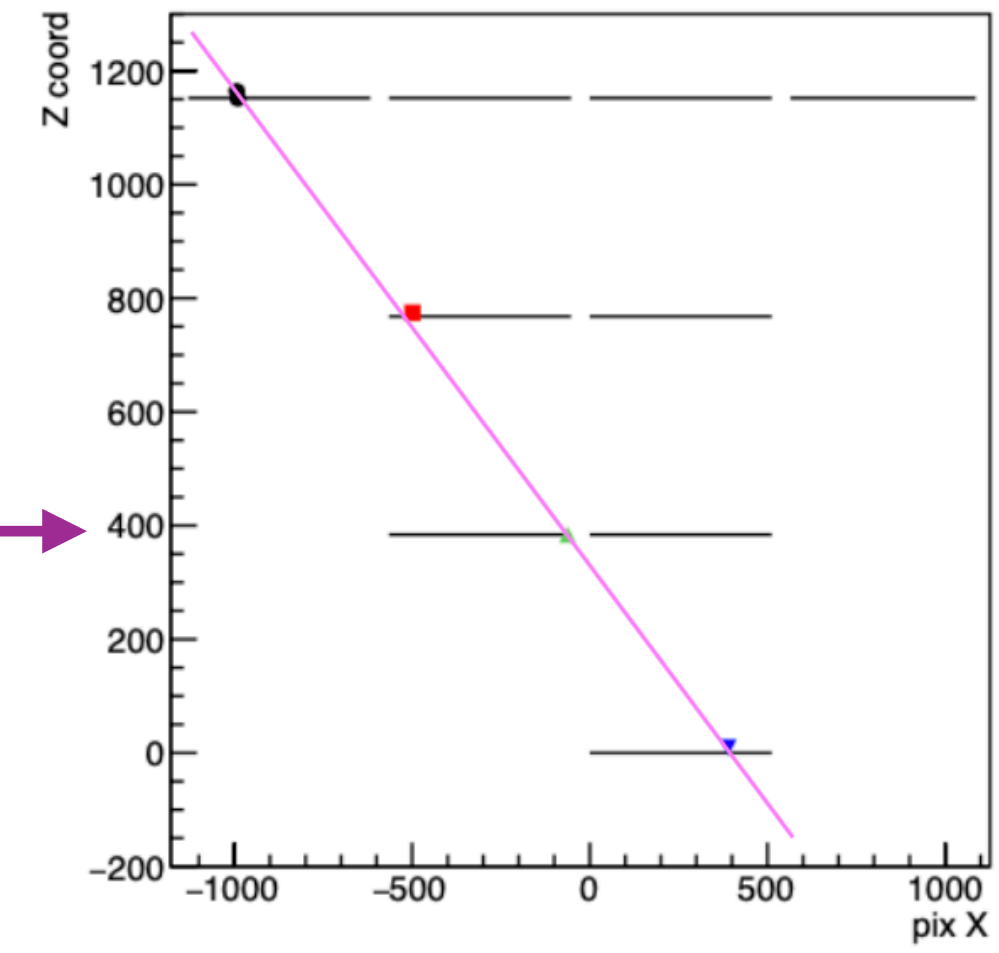
Study of in-pixel timing projected over 2x2 pixel matrix indicates that **late-arriving signals originate from pixel corners**: in these cases, charge-sharing effects result in a **lower charge deposition per-pixel** and **increased time-walk**.

*More detailed simulations of charge collection times are currently being pursued.*

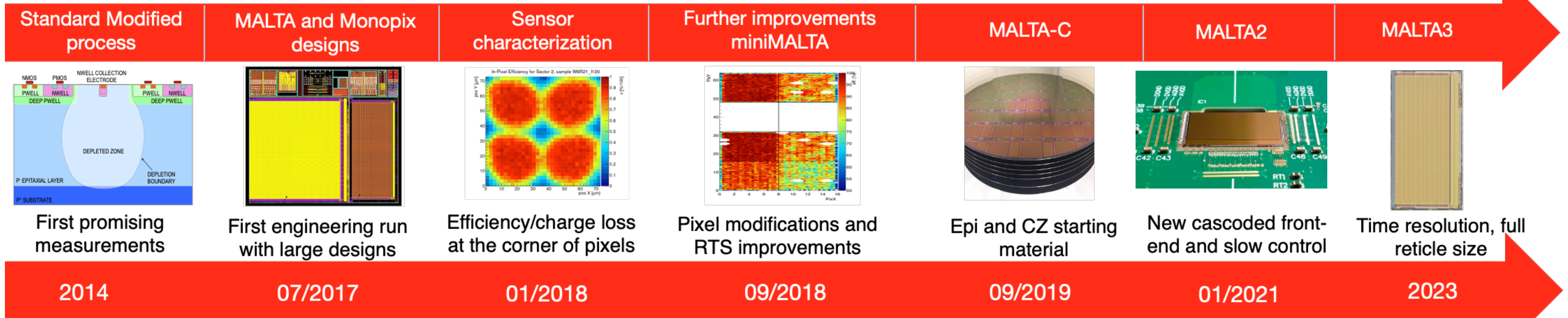
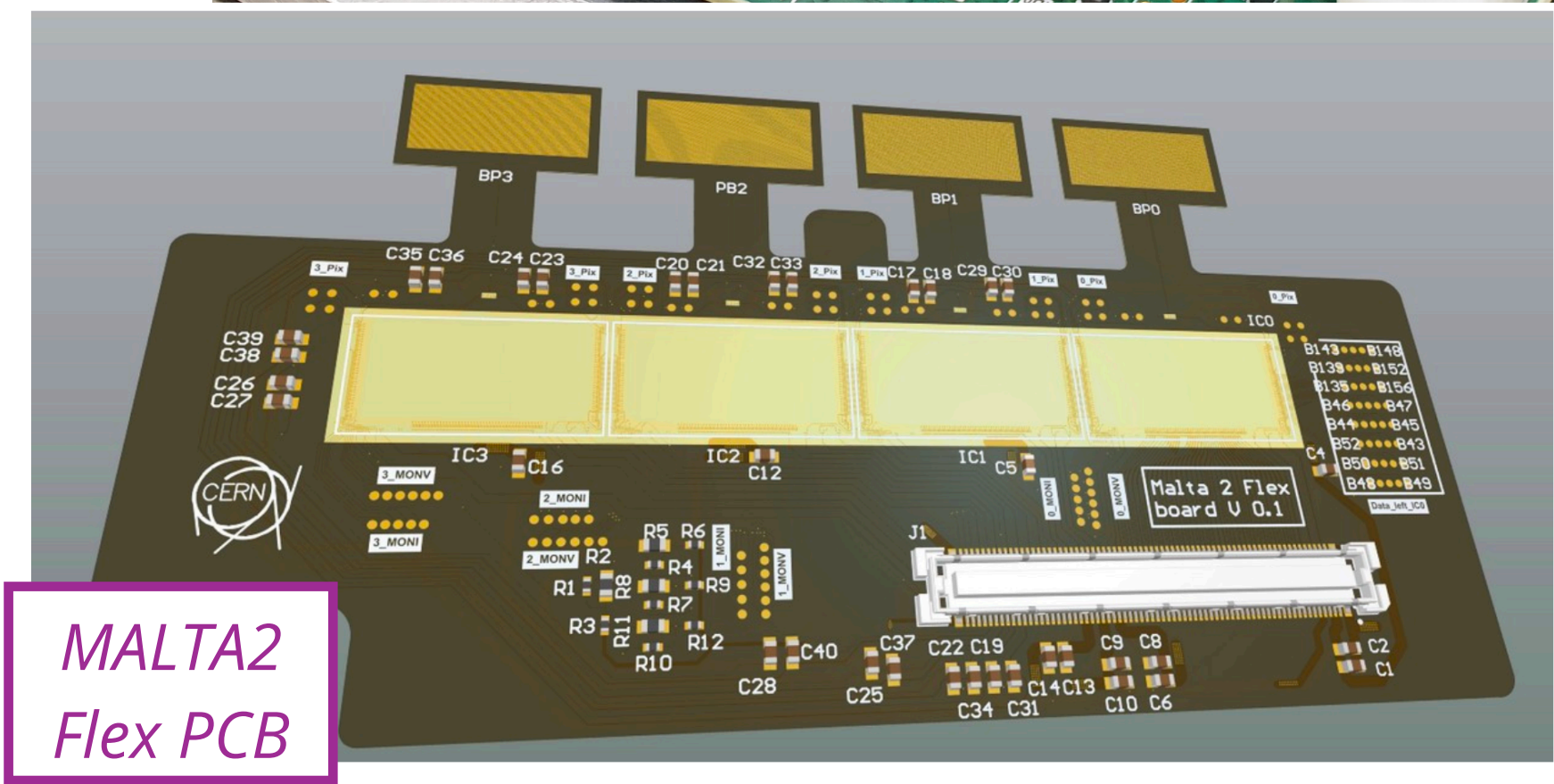
# Four-chip board and flex



- Process of building multi-chip modules is ongoing for MALTA 1 & 2.
- **4-chip MALTA board functionality recently demonstrated.**
  - Quad-chip plane already installed in MALTA “mini-telescope” for cosmic data-taking!
- **4-chip MALTA2 flex PCB** in planning stages.
- *Serialization improvements planned for next versions of MALTA prototypes.*



- P0: Quad Chip
- P1: Dual Chip
- P2: Dual Chip
- P3: Single chip



# Concluding remarks

- Detailed studies of the MALTA2 sensor performance continue.
  - Characterization of MALTA2 performance after irradiation.
    - Device is fully-functional after irradiation.
  - Measurements of MALTA2 timing performance.
- Planning more testbeam measurements throughout this year at the CERN SPS!
- Stay tuned for more from MALTA in the near-future!

For more on *MALTA*:

<https://ade-pixel-group.web.cern.ch/Welcome/>

<https://twiki.cern.ch/twiki/bin/viewauth/Atlas/MaltaApprovedPlots>

<https://ade-pixel-group.web.cern.ch/TowerJazz/>

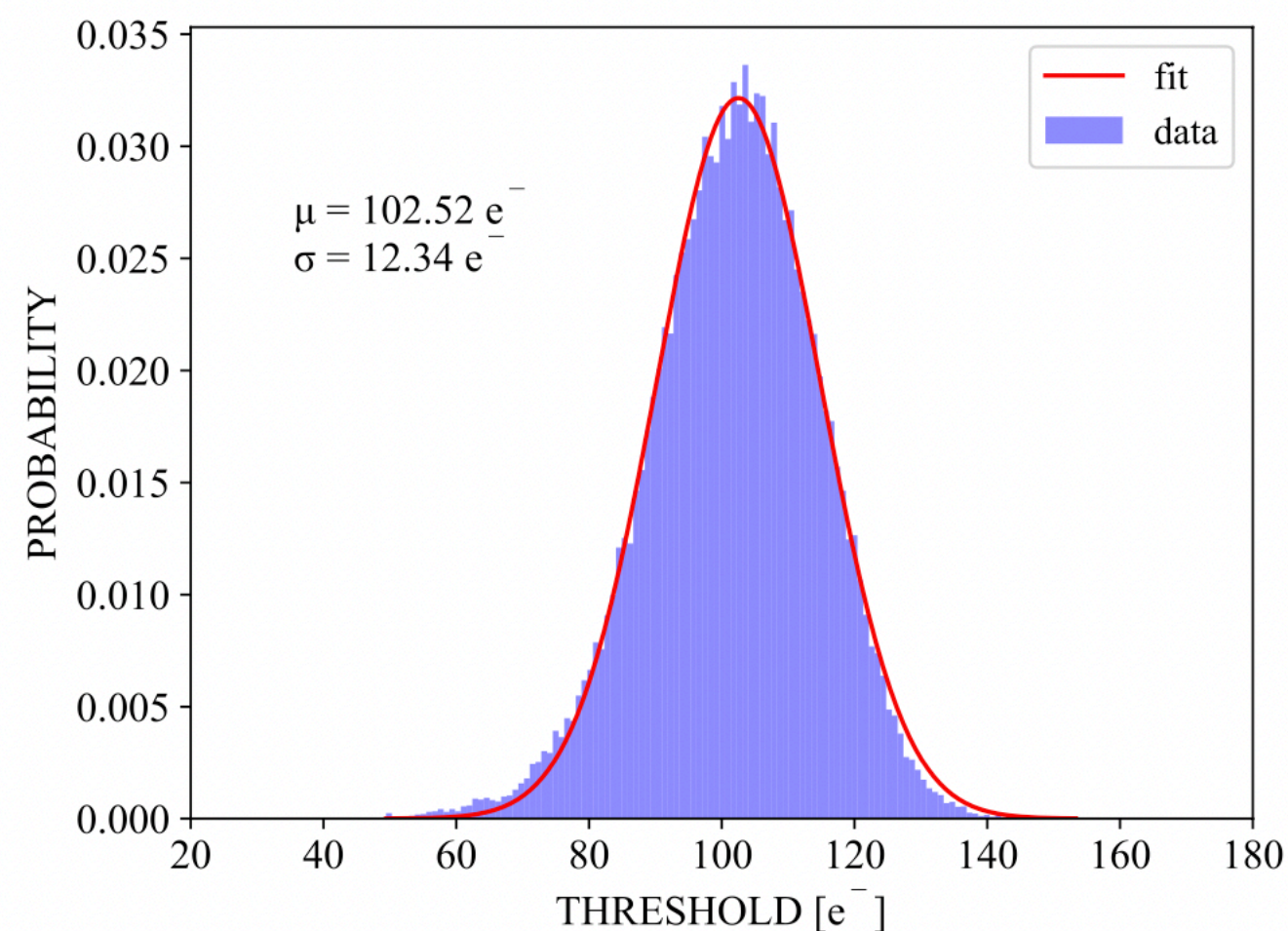
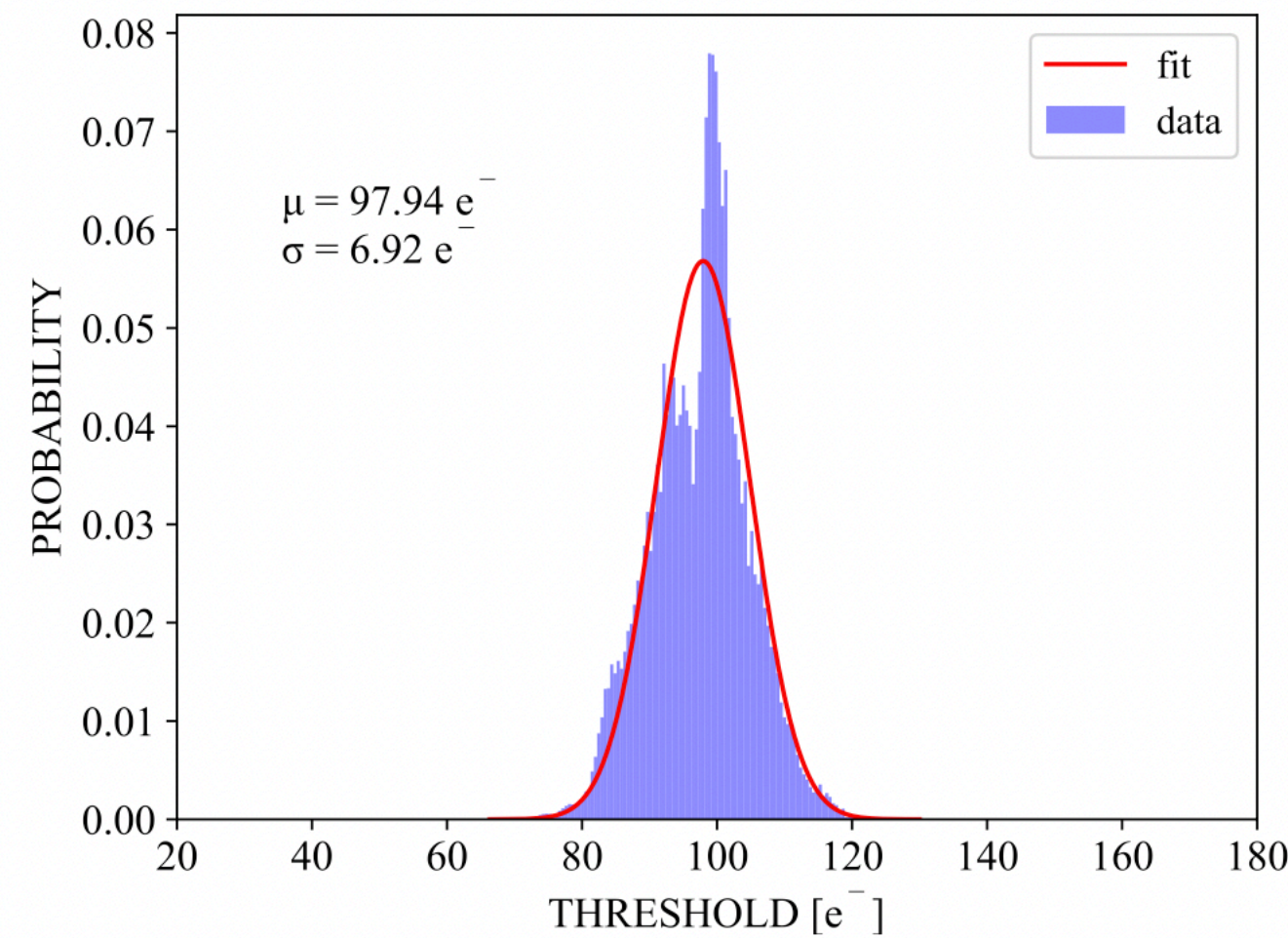
<https://ade-pixel-group.web.cern.ch/Publications/>



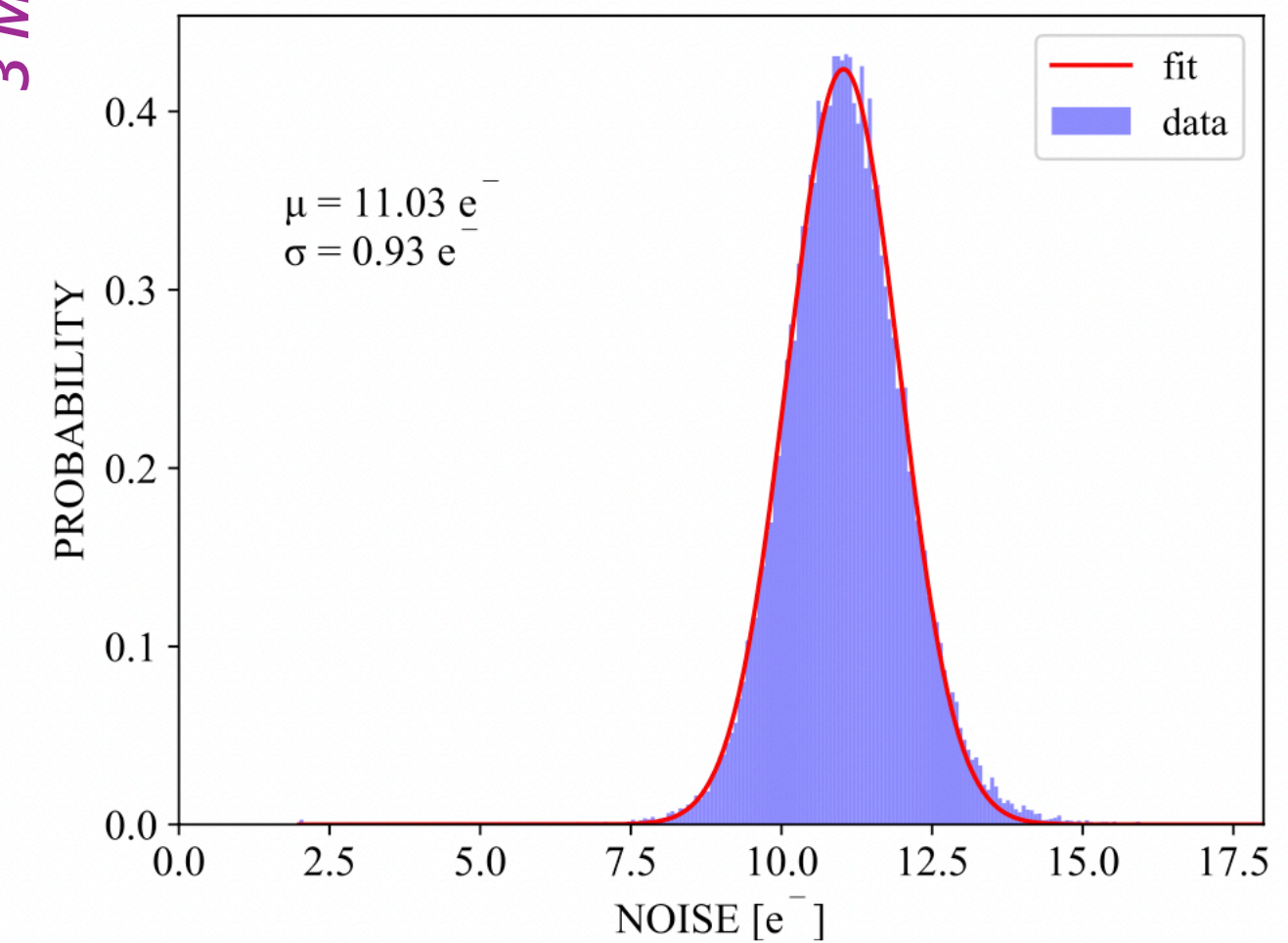
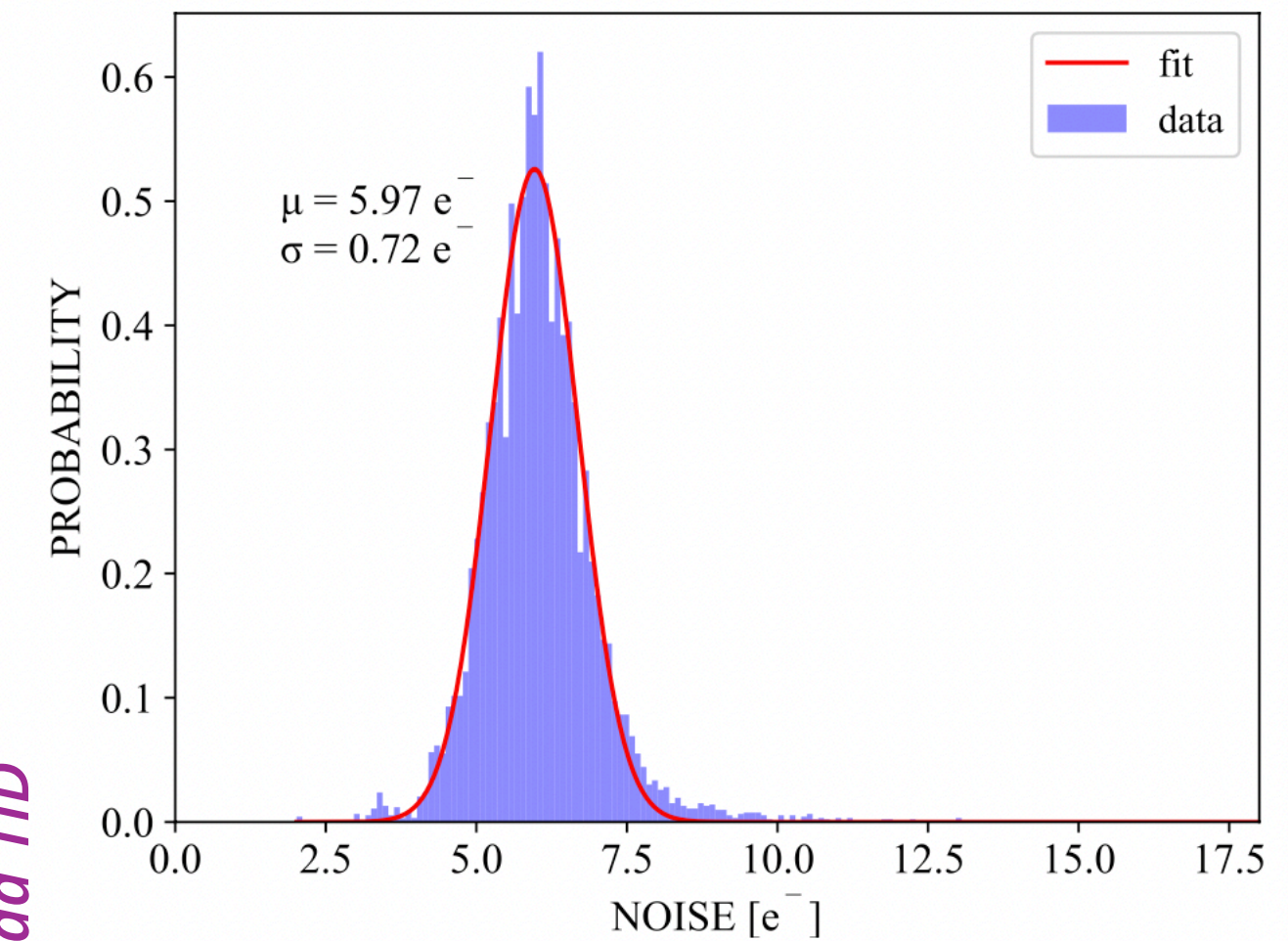
**Auxiliary material.**

# MALTA2 Front-End : Irradiation

- MALTA2 sensors irradiated at TRIGA reactor in Ljubljana.
  - Up to  $3E+15$  1 MeV  $n_{eq}/cm^2$
  - Background TID of 1 Mrad per  $1E+15$  1 MeV  $n_{eq}/cm^2$
- **Sensors are fully functional following irradiation.**
- **Threshold dispersion and noise increase.**
  - For a  $100 e^-$  threshold, pixel-to-pixel variation in threshold increases from  $\sim 7 e^-$  to  $\sim 12.5 e^-$ .

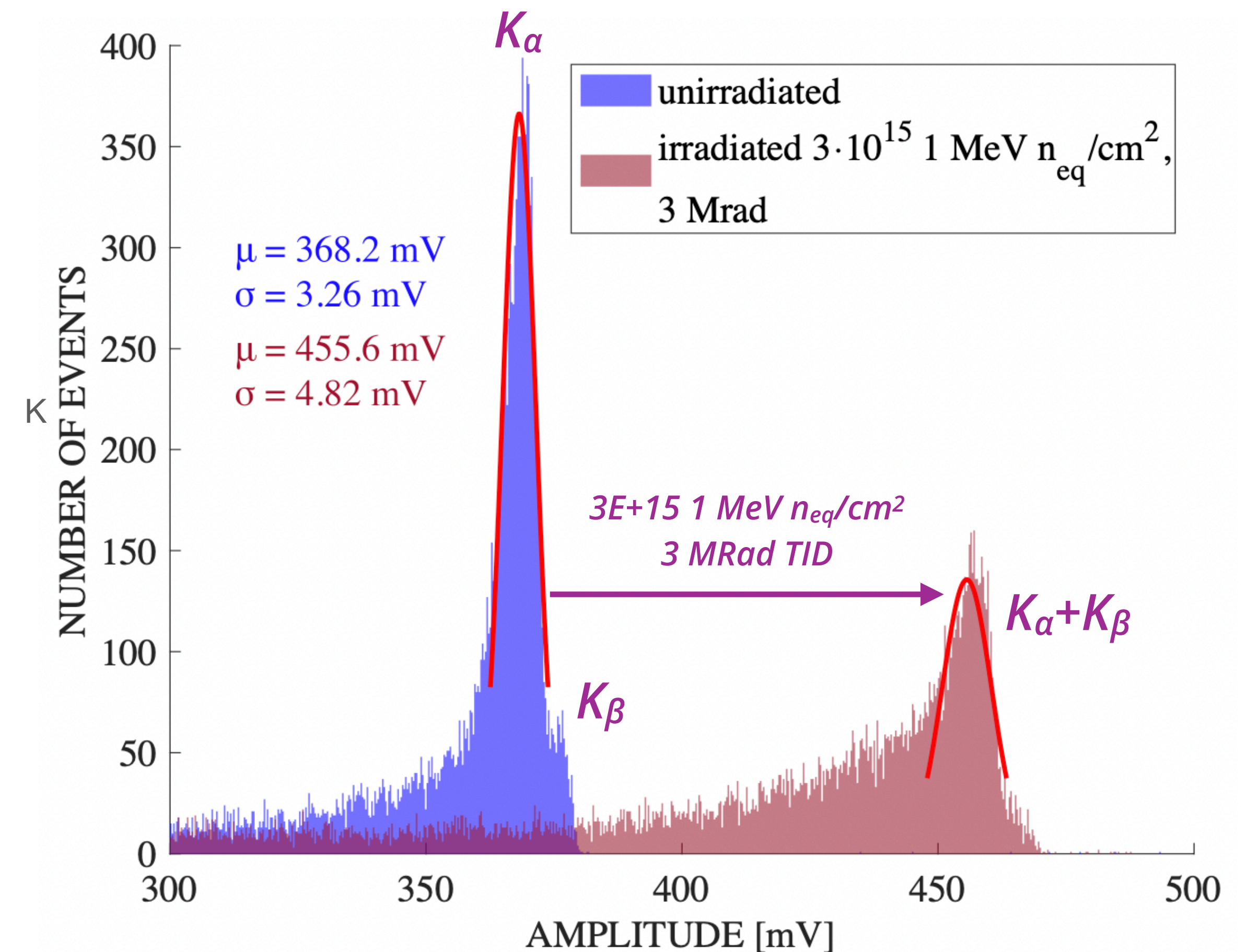


Maintain ~fixed threshold!  
 $3E+15$  1 MeV  $n_{eq}/cm^2$   
3 MRad TID



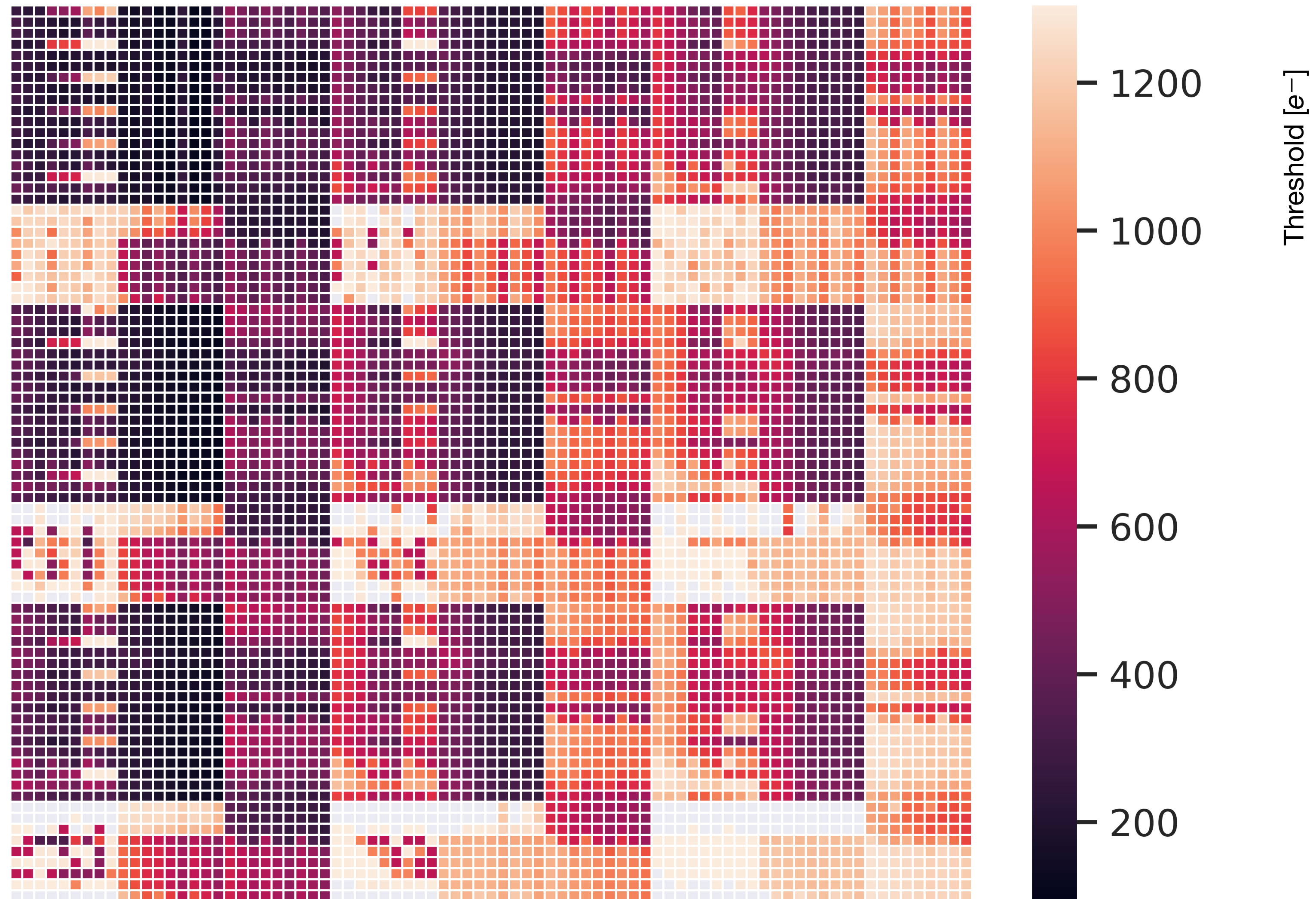
# MALTA2 Front-End : Irradiation, suite.

- MALTA2 sensors irradiated at TRIGA reactor in Lubljana.
  - Up to  $3E+15$  1 MeV  $n_{eq}/cm^2$
  - Background TID of 1 Mrad per  $1E+15$  1 MeV  $n_{eq}/cm^2$
- Effect of irradiation on sensor energy resolution studied using  $^{55}Fe$  source.
  - $K\alpha$  peak amplitude increases  $\sim 23.7\%$  after irradiation.
    - $K\beta$  peak no longer distinct!
  - Noise increase from  $\sim 6.8 e^- \rightarrow \sim 11.7 e^-$
  - Behaviour expected from previous MALTA studies, likely related to NIEL decreasing effective doping of n — layer (lower capacitance  $\rightarrow$  higher amplitude).

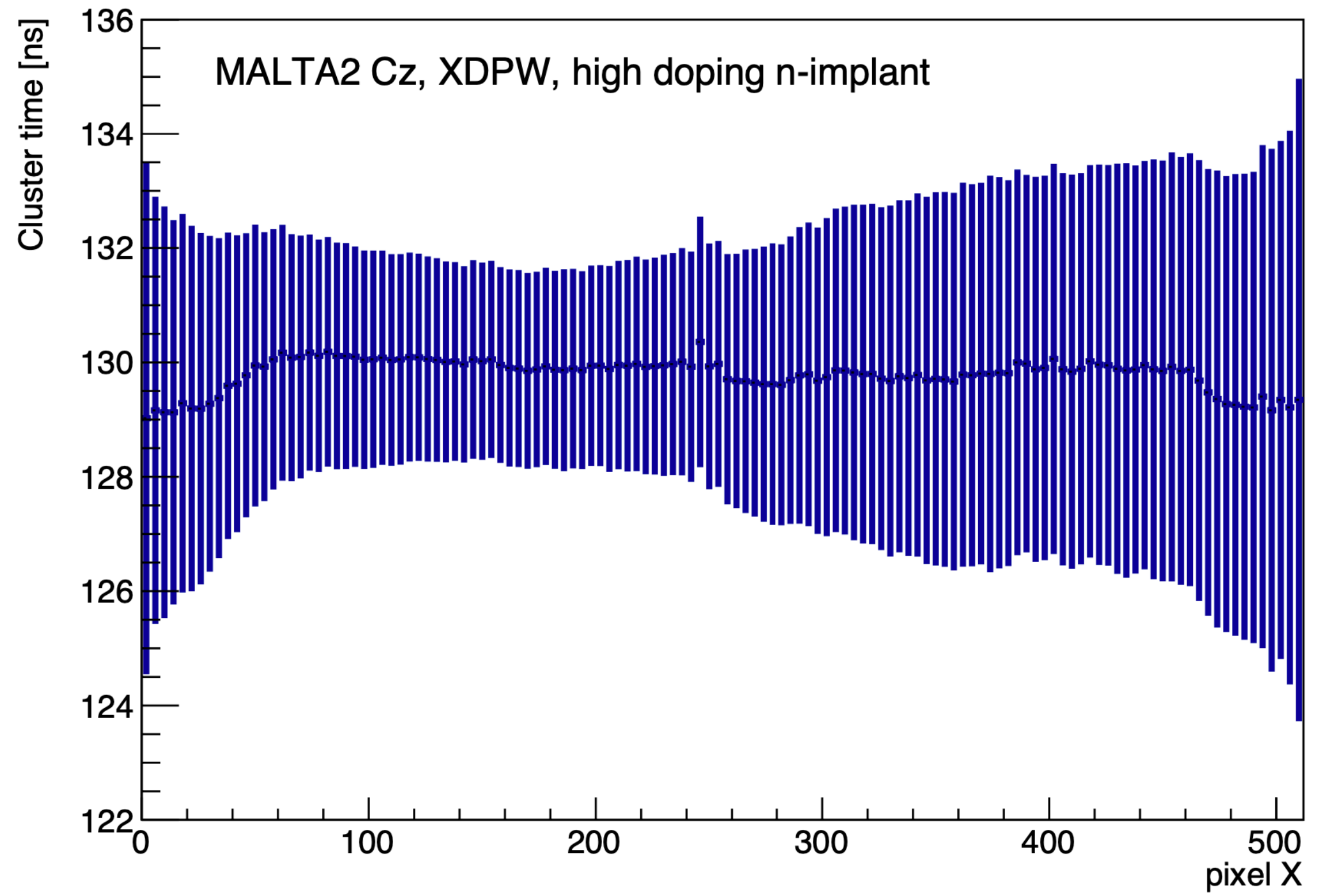
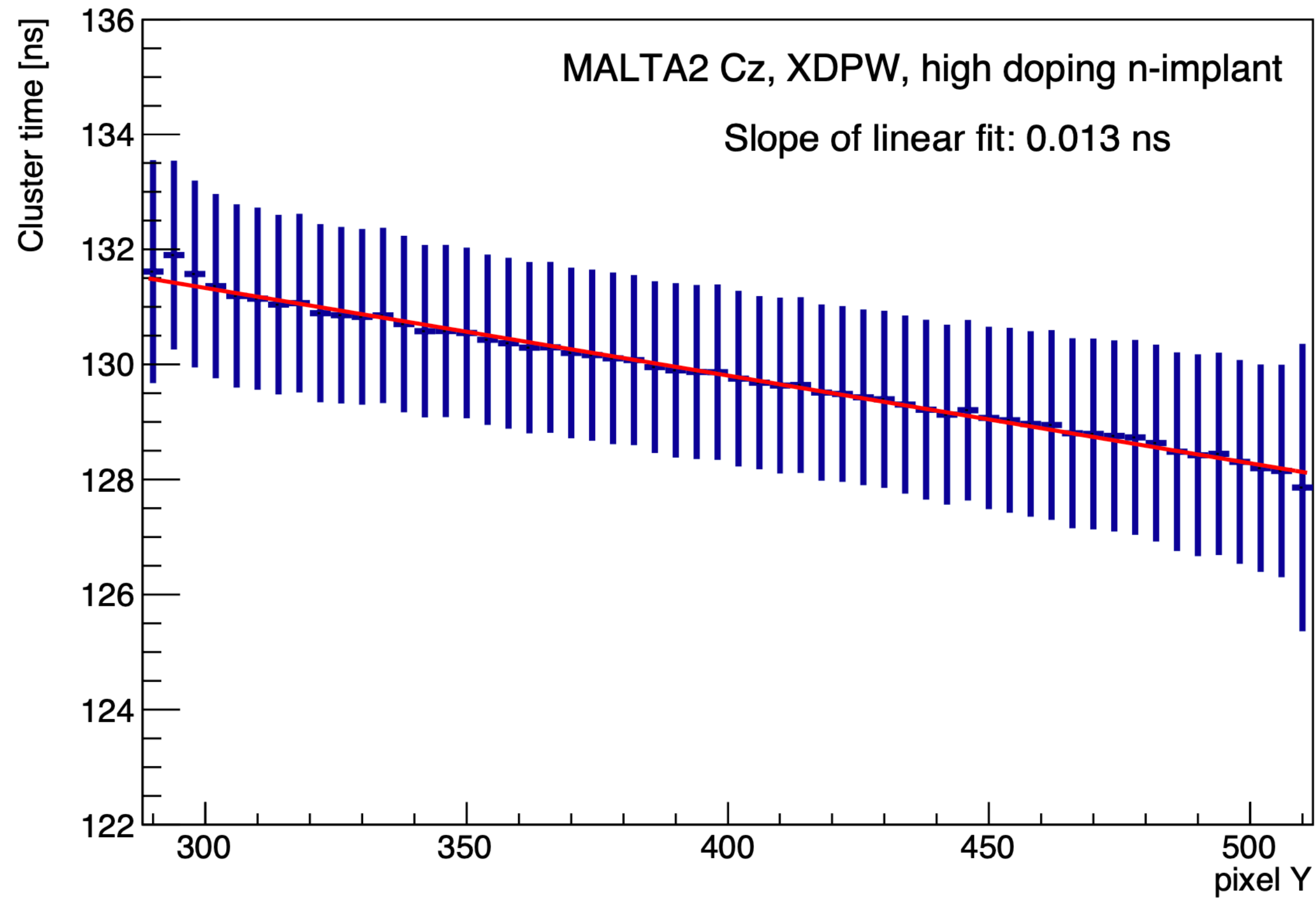


# MALTA2 Front-End : DAC Interdependencies (no annotations)

*MALTA2 Preliminary*





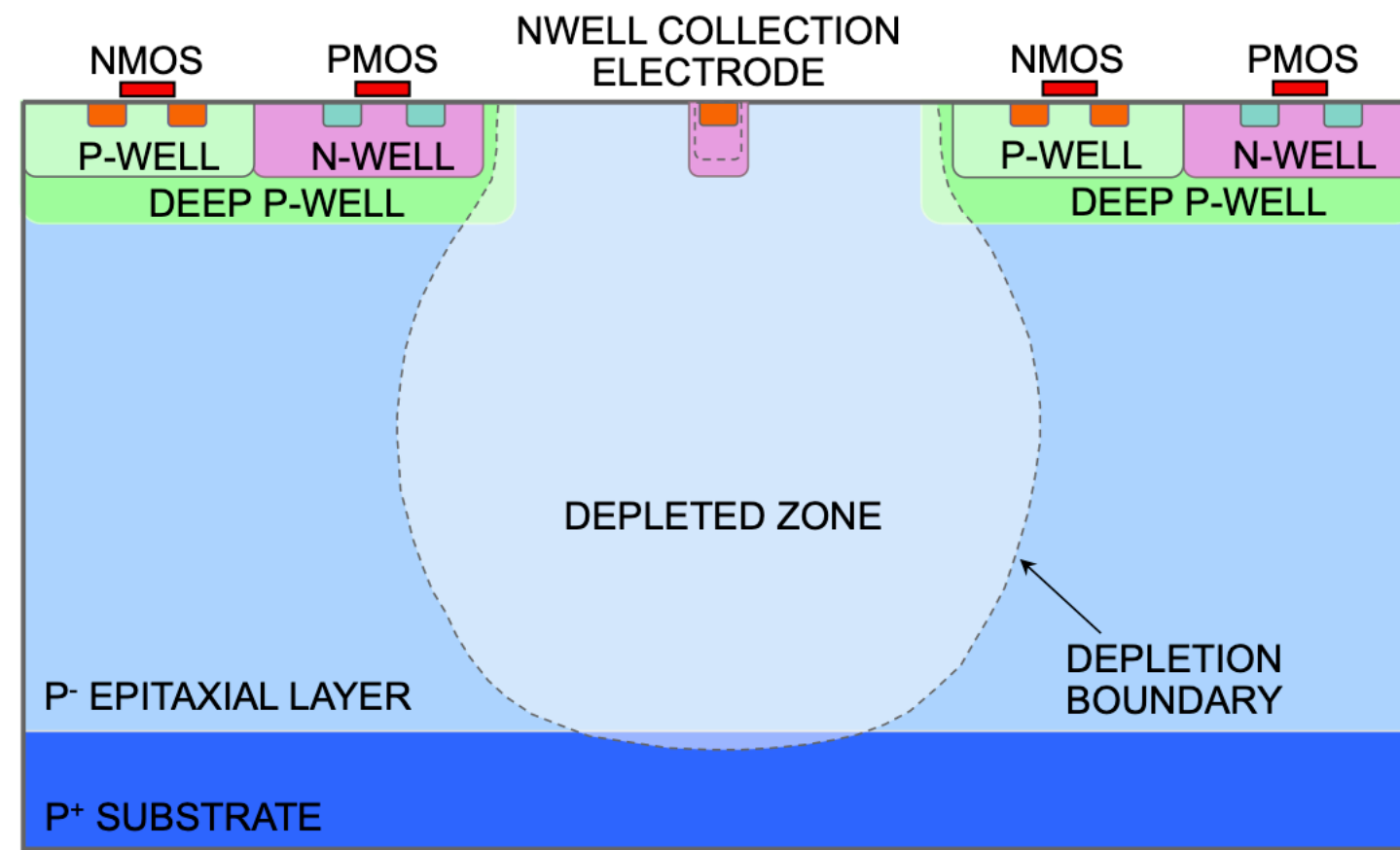


# Towerjazz 180 nm Modified Processes

Charge collection time  
~100 ns via diffusion,  
too slow for LHC applications.



Not in today's talk!

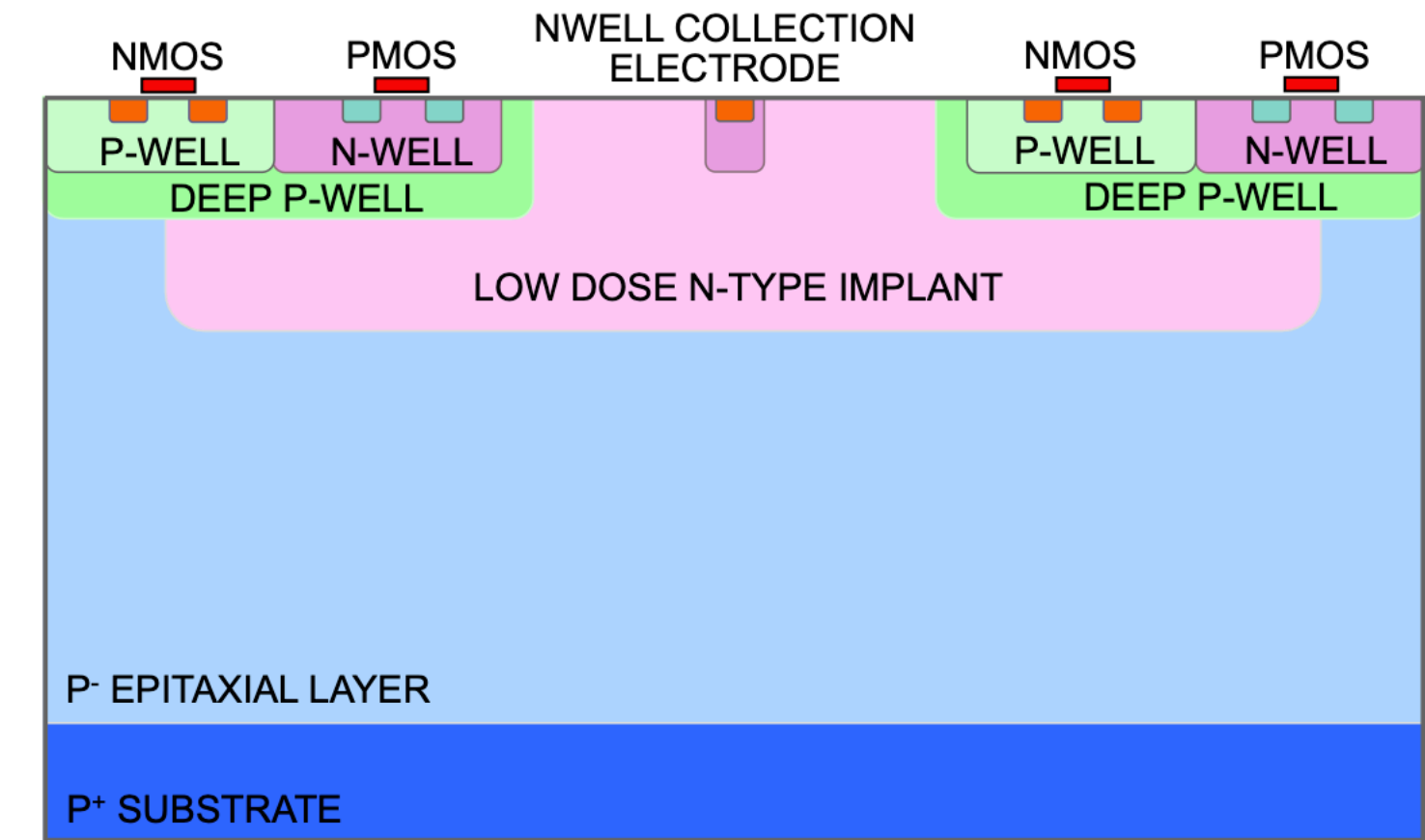


Unmodified process



In today's talk!

Additional process modifications can increase E-field in pixel corners, further reducing charge collection tails.



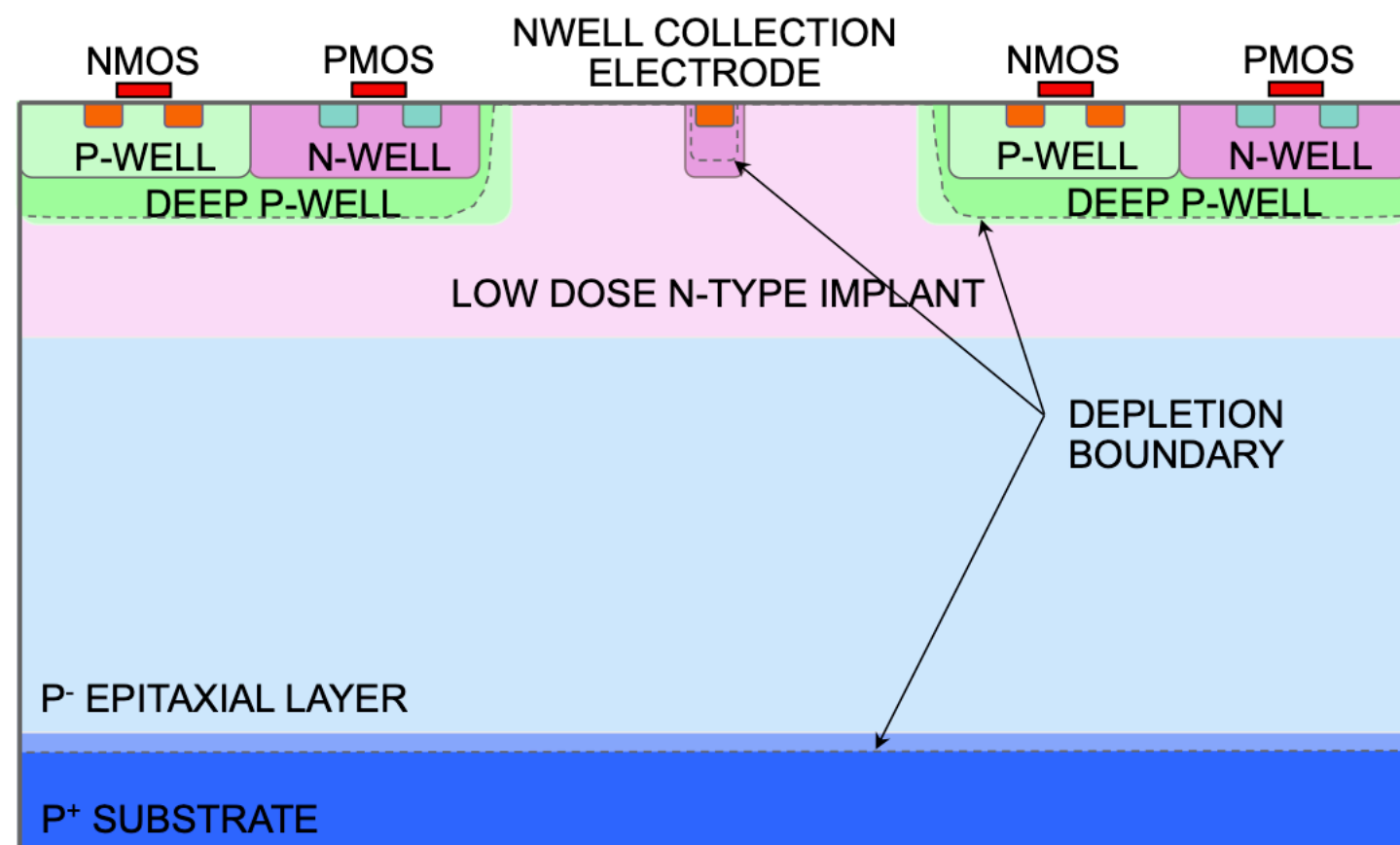
Gap in the n-layer

Uniform low-dose n— layer under p-well fully depletes pixel area, pushing charge-carriers towards collection electrode.

Also reduces charge carrier capture probability, improving sensor tolerance to NIEL.



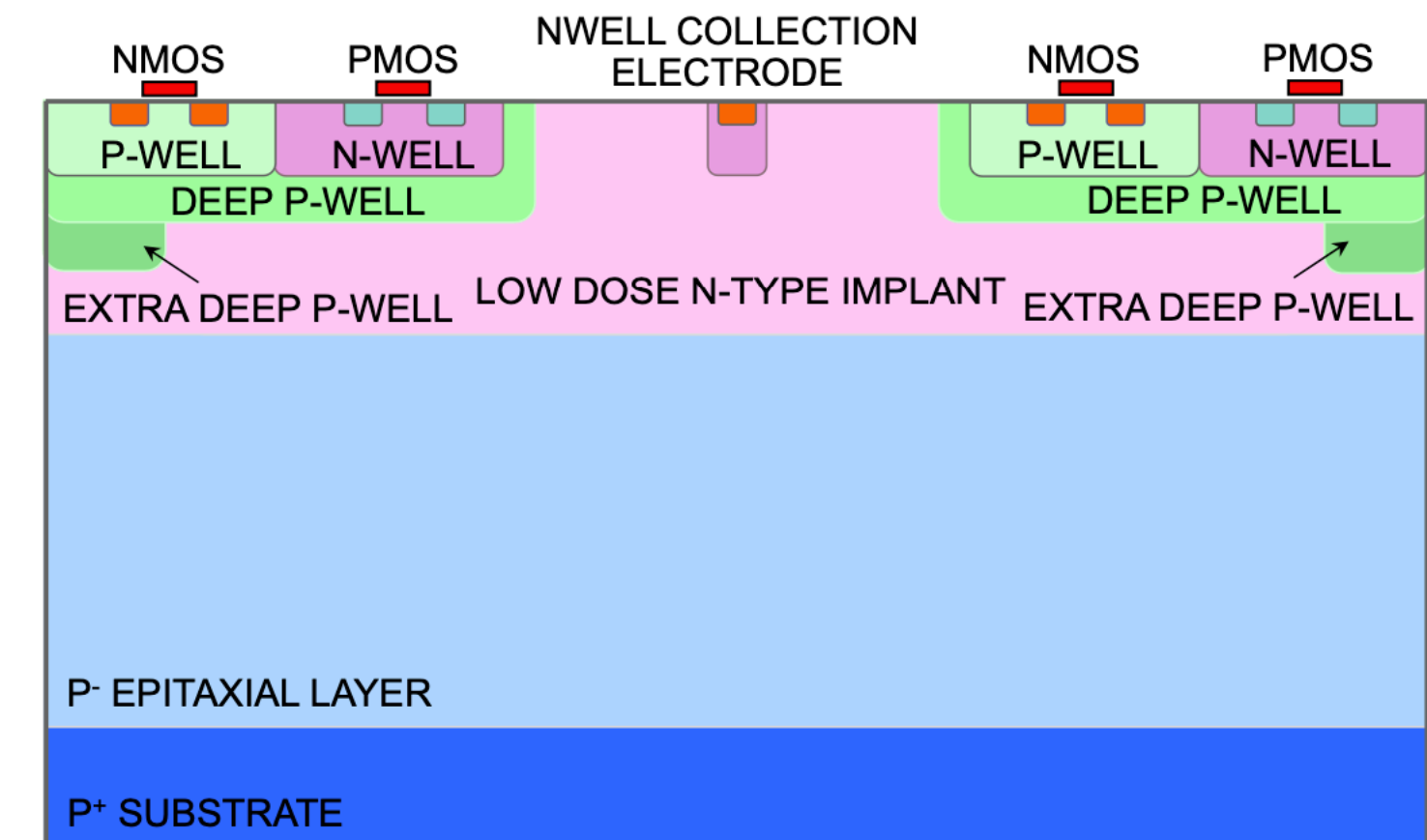
In today's talk!



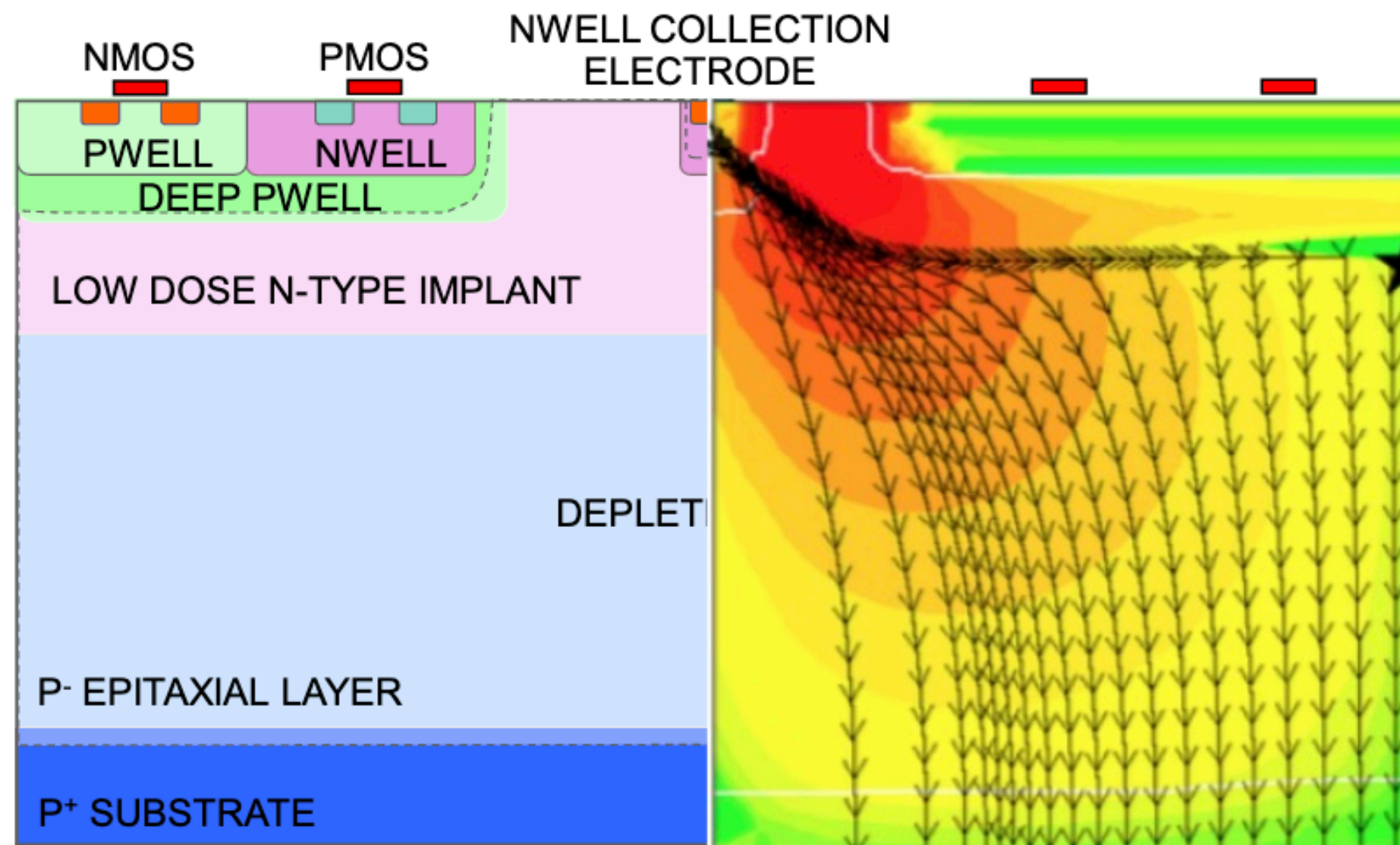
Modified process, low doping



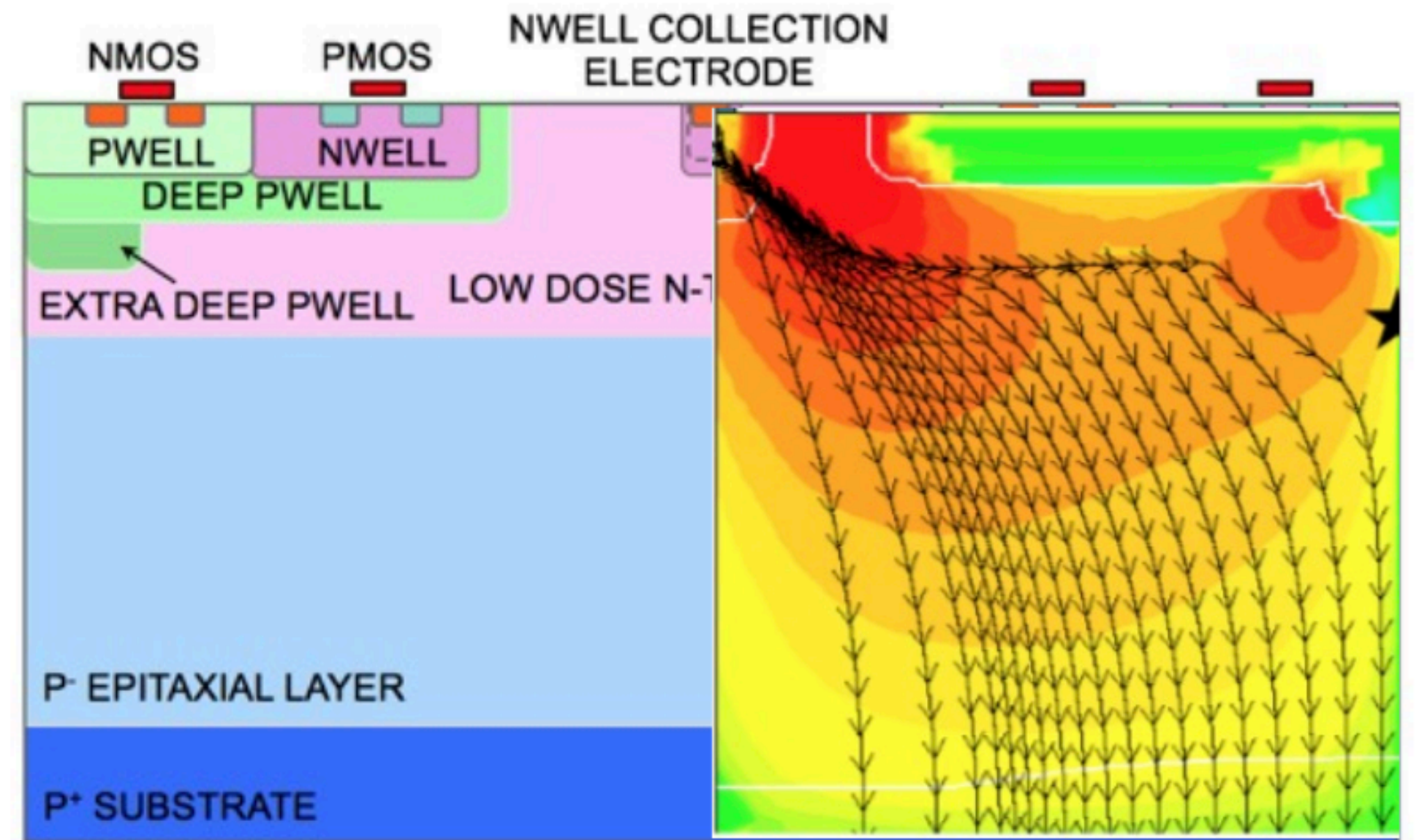
Not in today's talk!



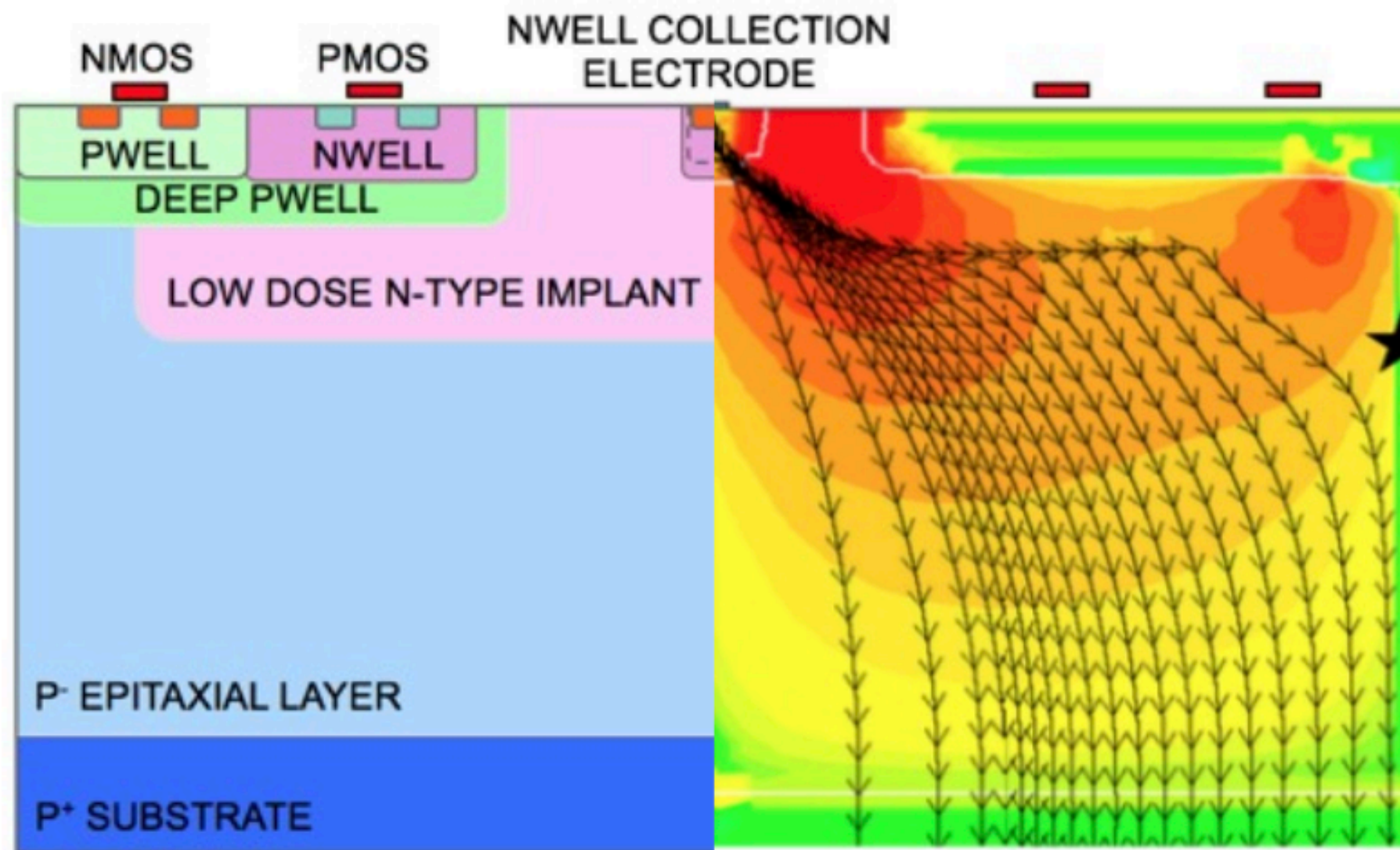
Extra-deep p-well



**Standard modified process**



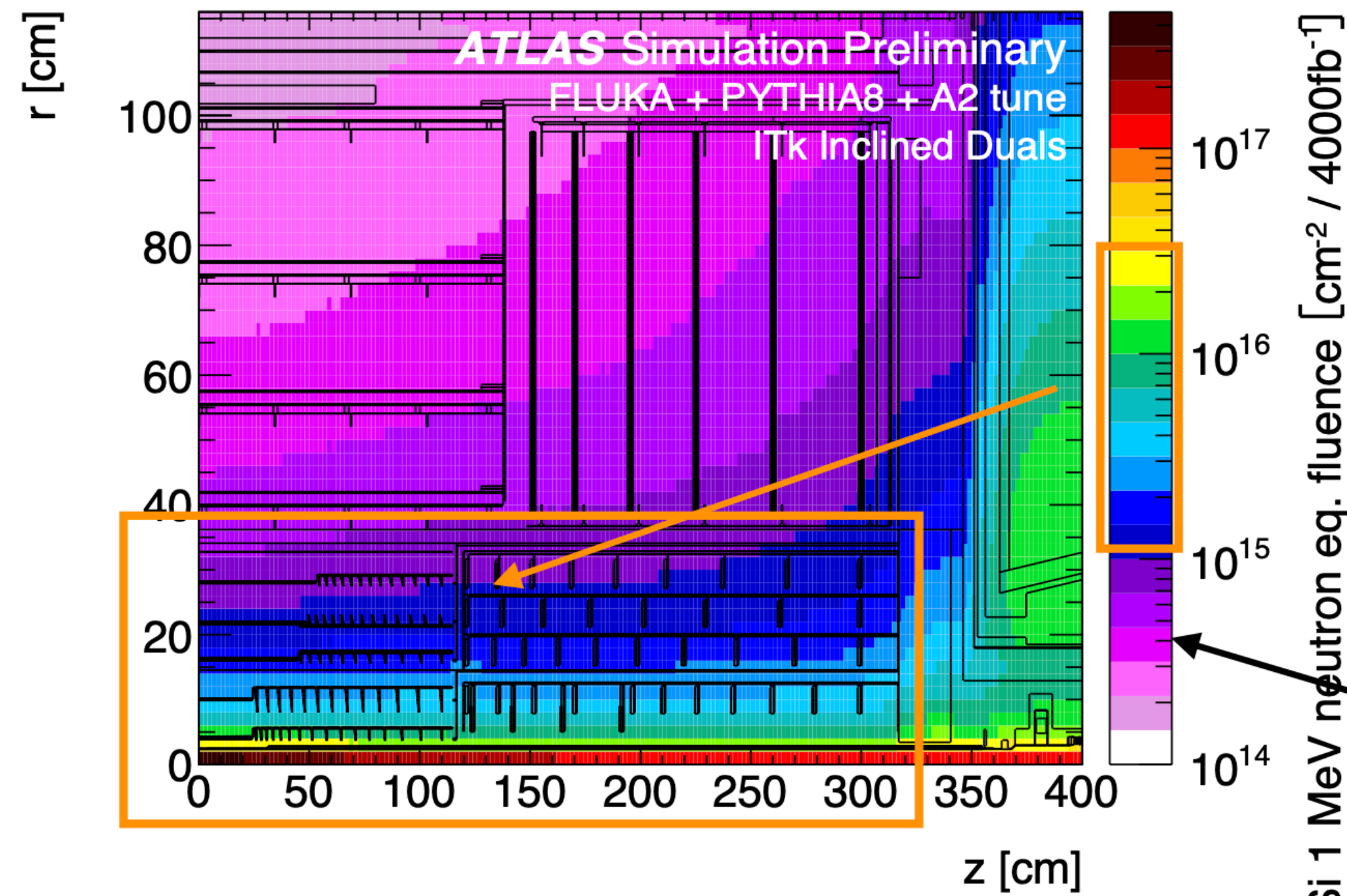
**Extra deep p-well (EDPW)**



**Gap in the n- layer (NGAP)**

## (one of) the next challenges for pixel detectors

- ◆ Large hit rate: 200 MHz/cm<sup>2</sup>
- ◆ Resist to very large radiation dose:
  - ◆ HL-LHC pixel detector:
    - ◆  $2 \cdot 10^{16} - 10^{15} n_{eq}/cm^2$  NIEL
- ◆ 'As thin as possible'



Si 1 MeV neutron eq. fluence [cm<sup>2</sup> / 4000fb<sup>-1</sup>]

Innermost ATLAS Pixel detector now at the end of Run2

- ◆ ATLAS Itk:
  - ◆ 5 pixel layers from 3 to 30 cm IP